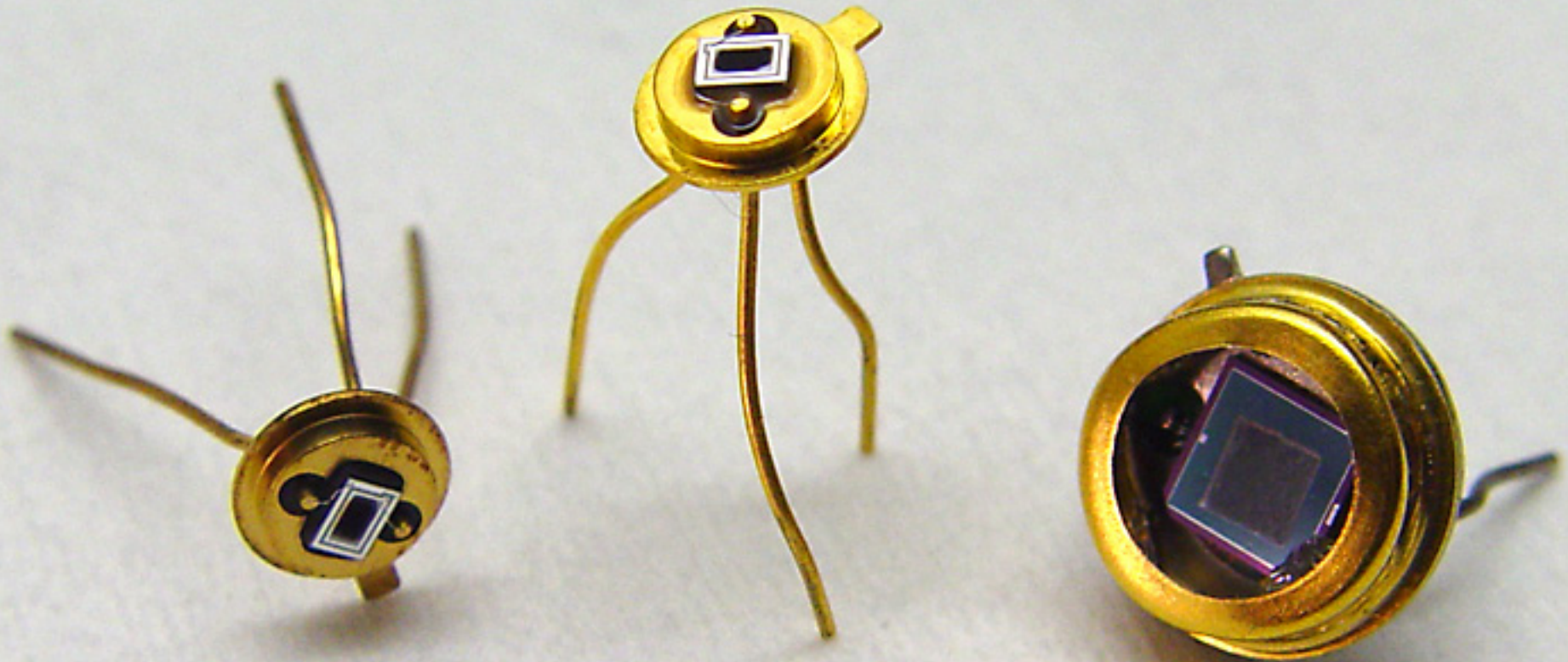


Serendipity, science, and engineering



Faculty Seminar, REU Program
Harvard University
Cambridge, MA, 15 July 2010

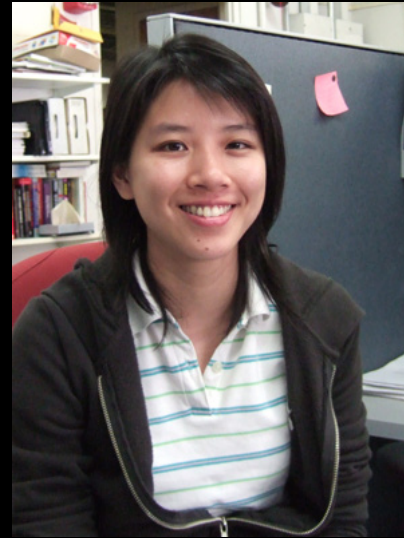




Mark Winkler



Renee Sher



Yu-Ting Lin



Eric Mazur

and also....

**Eric Diebold
Haifei Albert Zhang
Dr. Brian Tull
Dr. Jim Carey
Prof. Tsing-Hua Her
Dr. Shrenik Deliwala
Dr. Richard Finlay
Dr. Michael Sheehy
Dr. Claudia Wu
Dr. Rebecca Younkin
Prof. Catherine Crouch
Prof. Mengyan Shen
Prof. Li Zhao**

**Dr. John Chervinsky
Dr. Joshua Levinson**

**Prof. Michael Aziz
Prof. Cynthia Friend
Prof. Howard Stone**

**Prof. Tonio Buonassisi (MIT)
Prof. Silvija Gradecak (MIT)
Dr. Bonna Newman (MIT)
Joe Sullivan (MIT)**

Prof. Augustinus Asenbaum (Vienna)

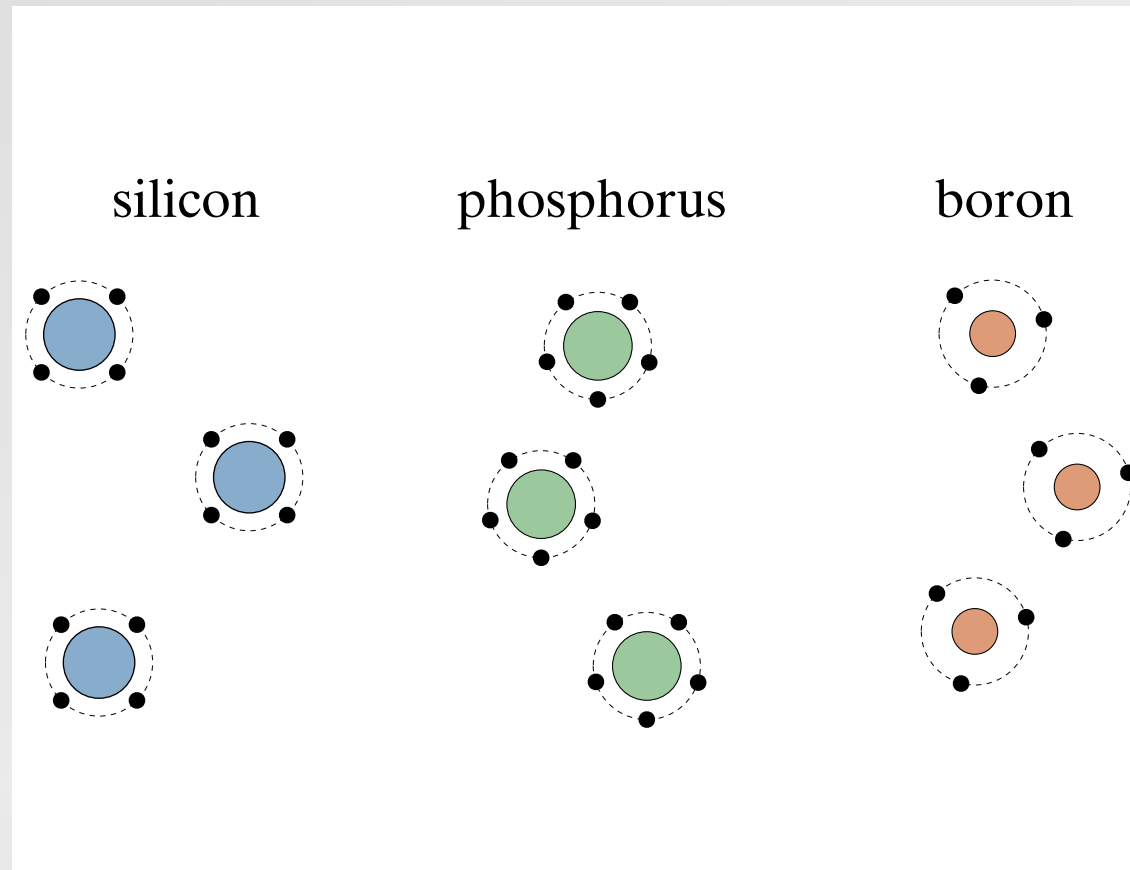
**Dr. François Génin (LLNL)
Mark Wall (LLNL)**

**Dr. Richard Farrell (RMD)
Dr. Arie Karger (RMD)
Dr. Richard Meyers (RMD)**

Dr. Pat Maloney (NVSED)

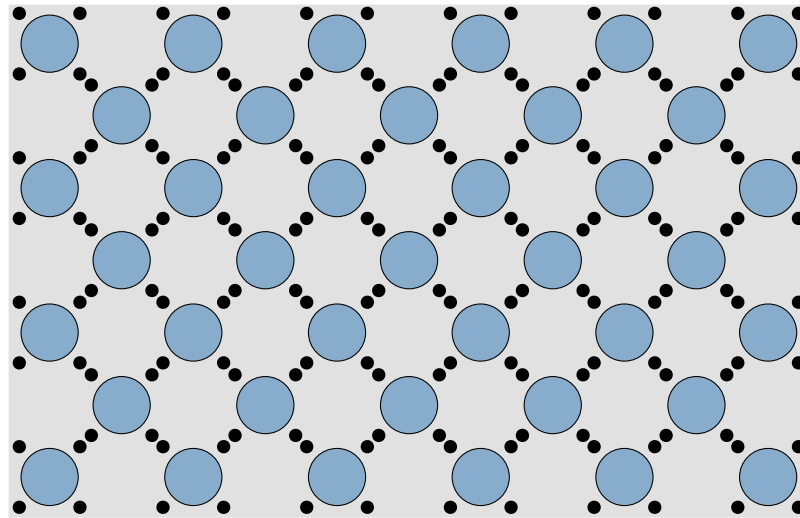
Dr. Jeffrey Warrander (ARDEC)

Introduction



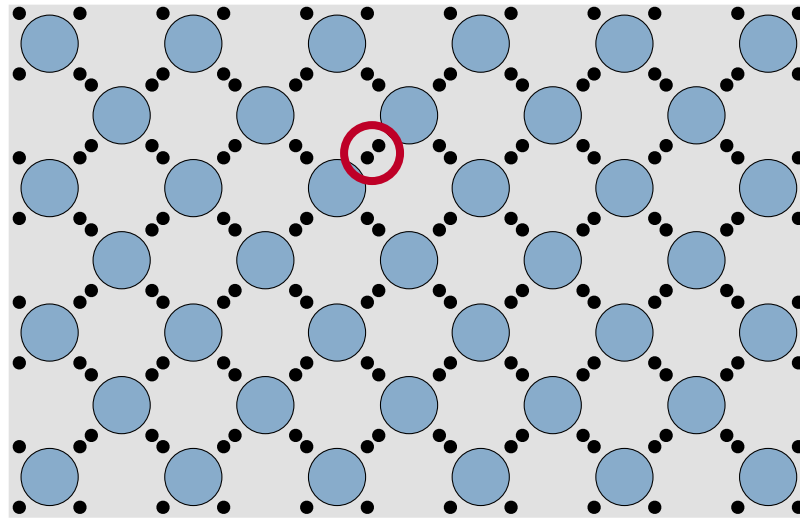
outer ("valence") electrons determine electronic properties

Introduction



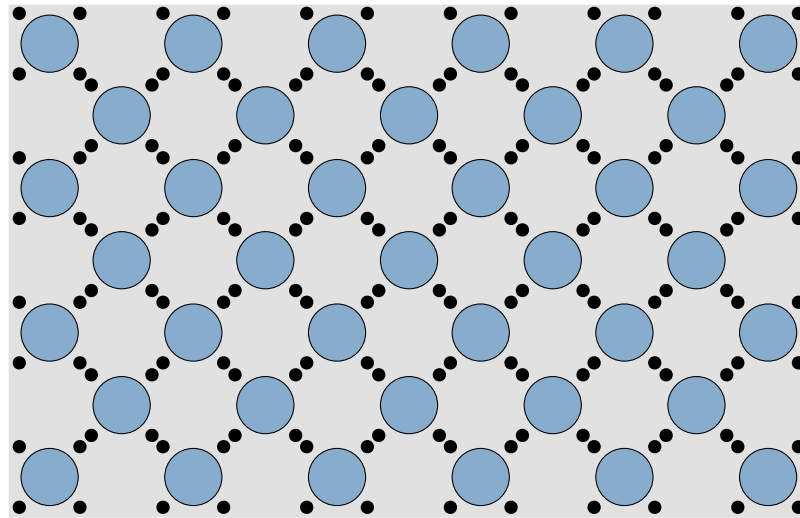
pure ("intrinsic") silicon

Introduction



electrons in covalent bond are immobile

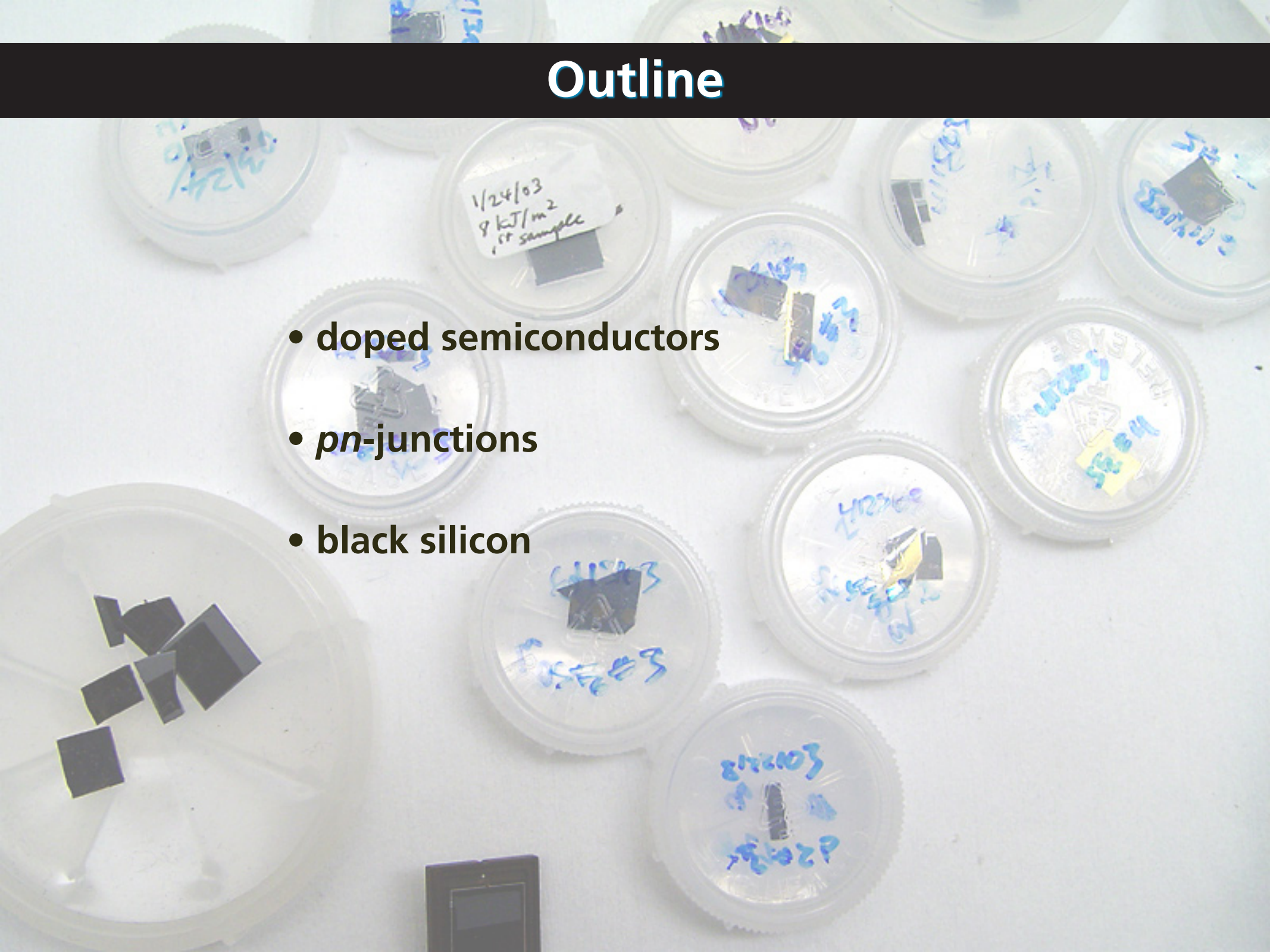
Introduction



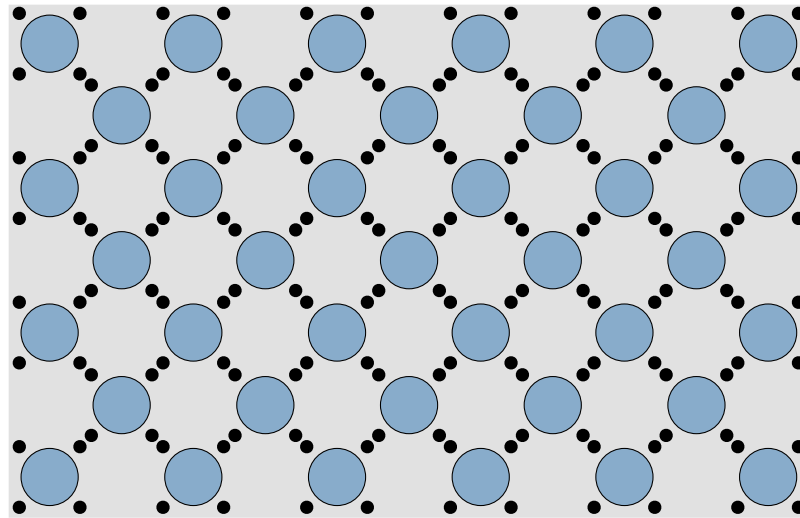
all electrons bound, so no conduction

Outline

- doped semiconductors
- *pn*-junctions
- black silicon

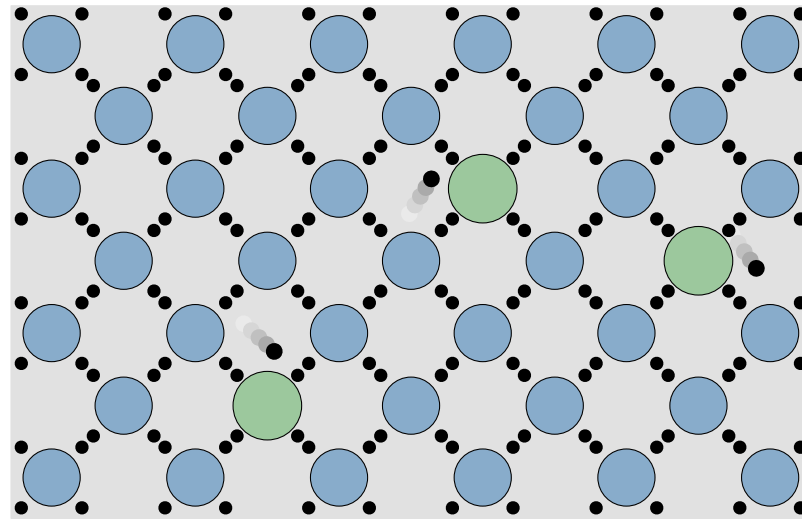


Doped semiconductors



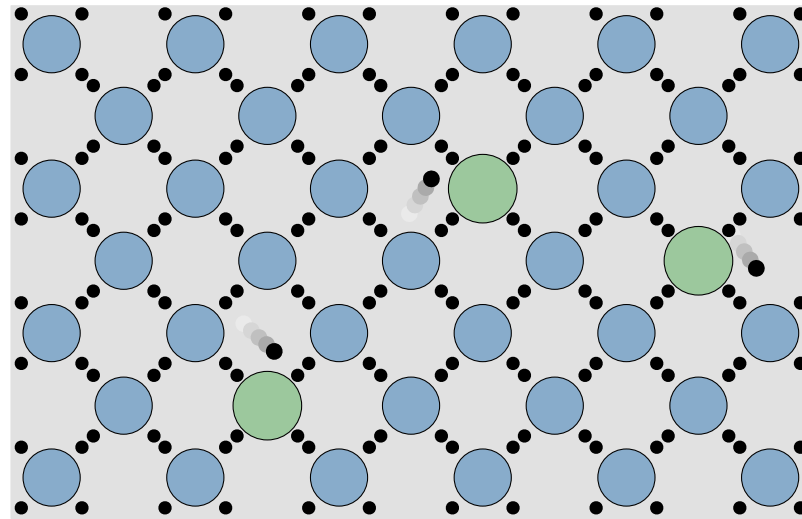
intrinsic silicon: no conduction

Doped semiconductors



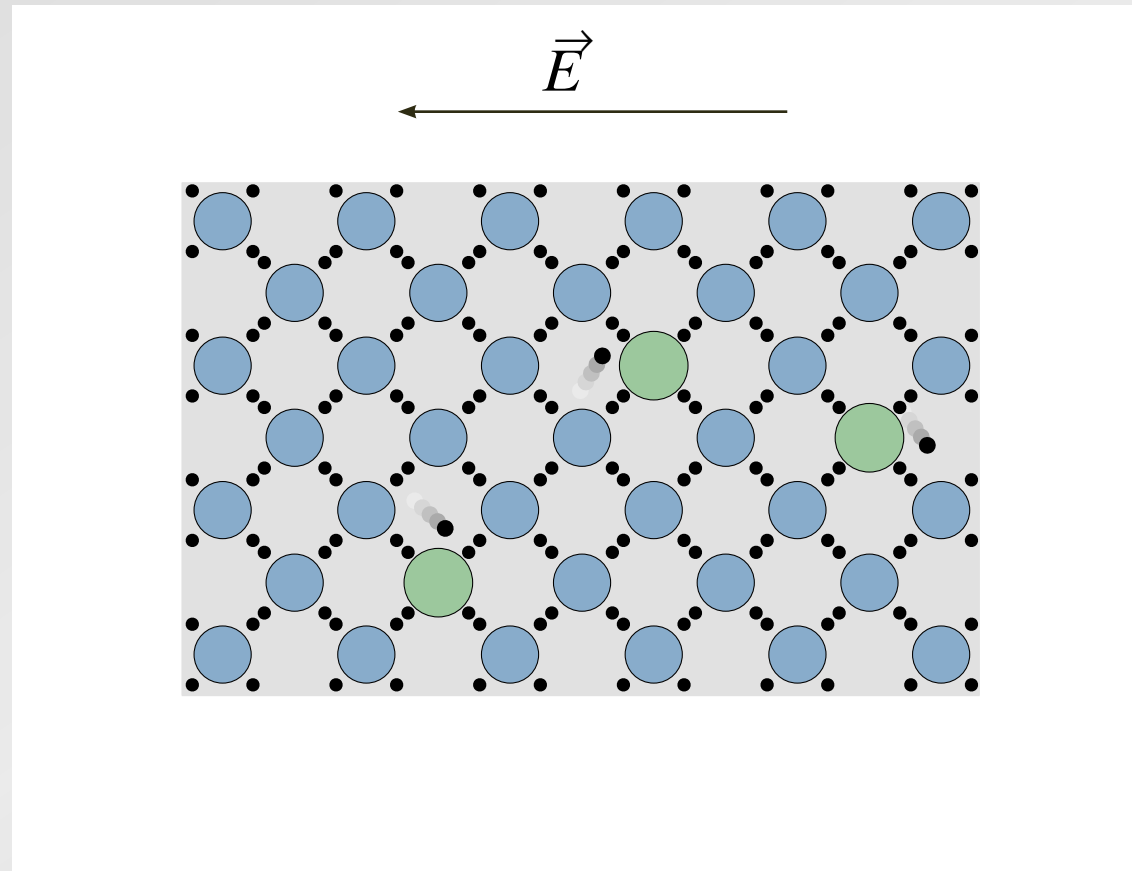
substitute phosphorous: surplus of (free) electrons

Doped semiconductors



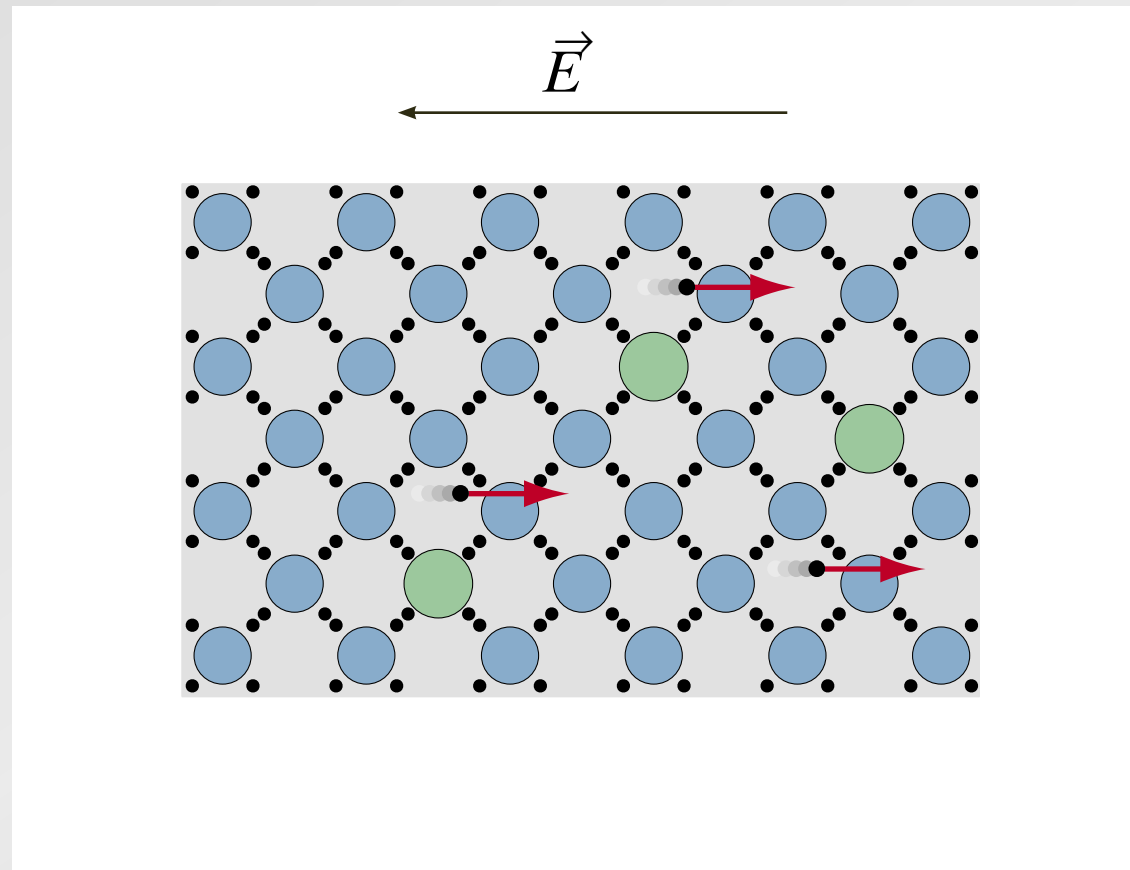
(but material as a whole still neutral!)

Doped semiconductors



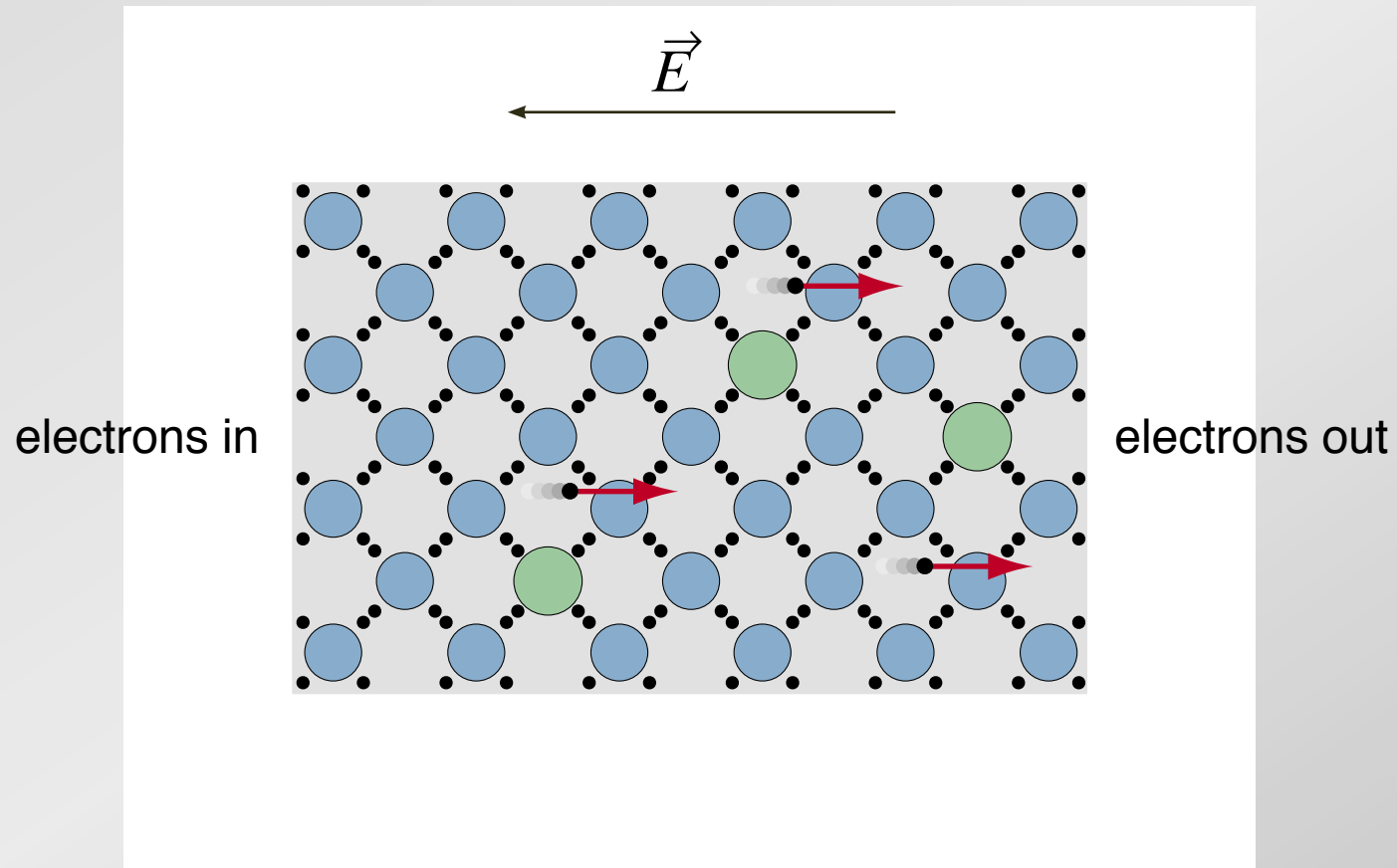
apply electric field...

Doped semiconductors



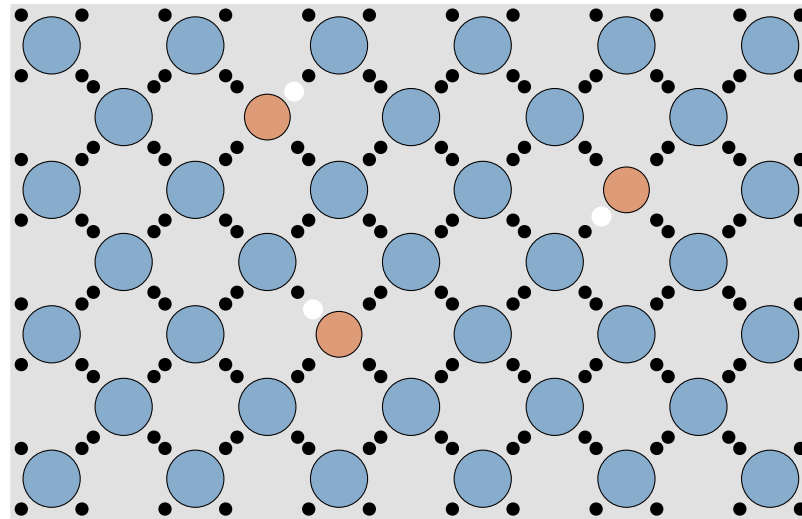
...free electrons lead to conduction

Doped semiconductors



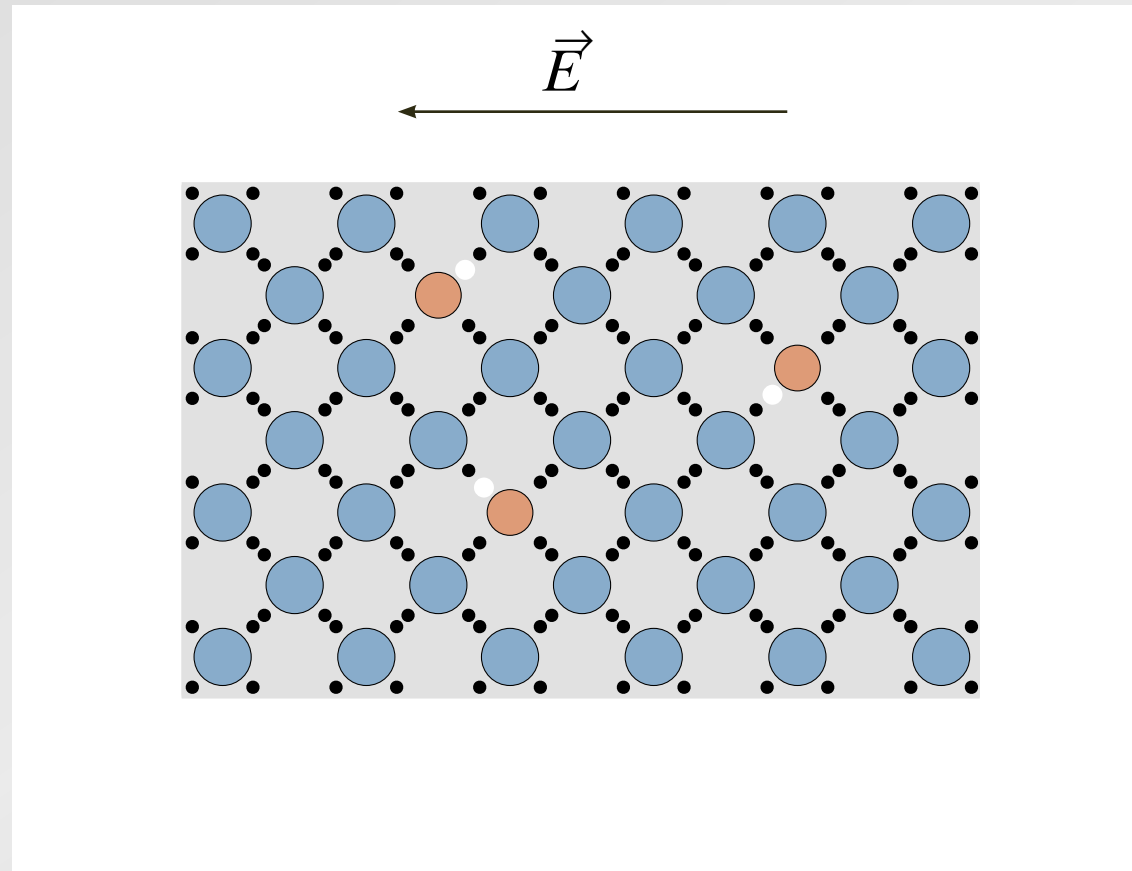
...free electrons lead to conduction

Doped semiconductors



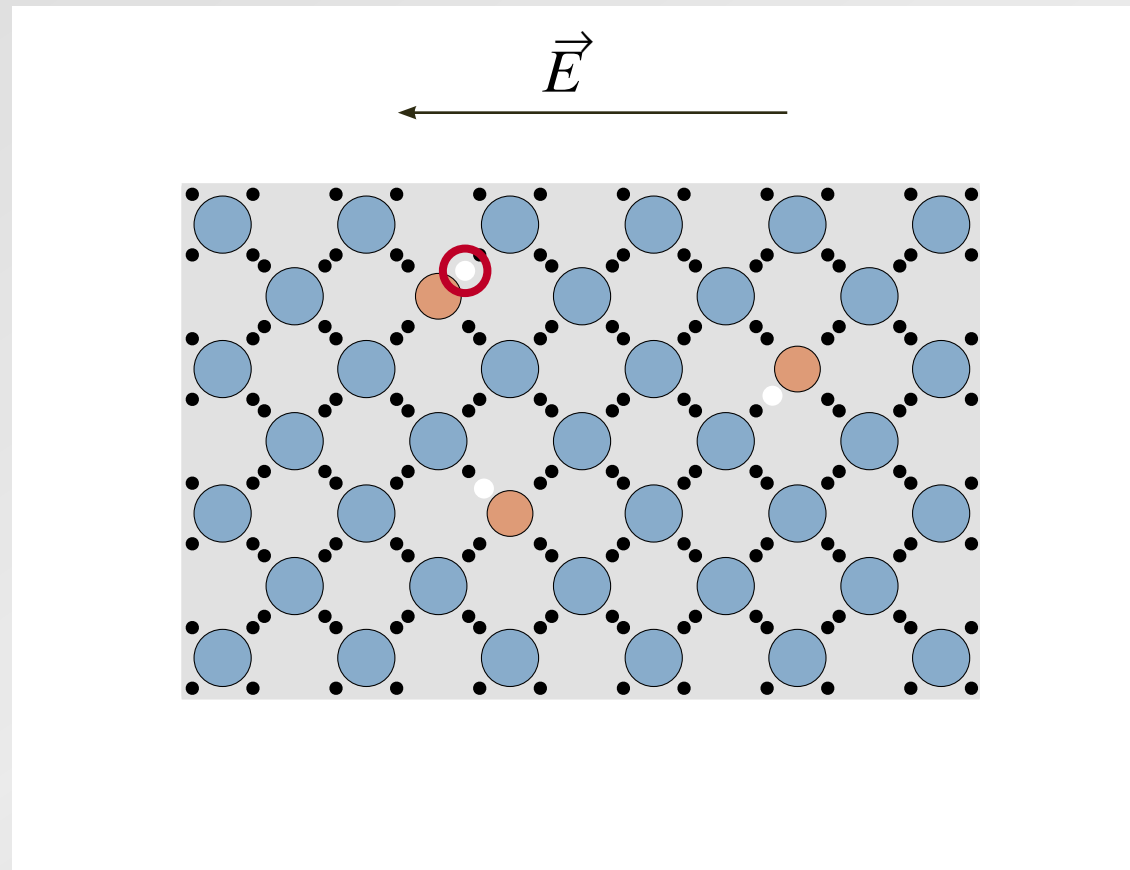
substitute boron: deficit of electrons leaves "holes"

Doped semiconductors



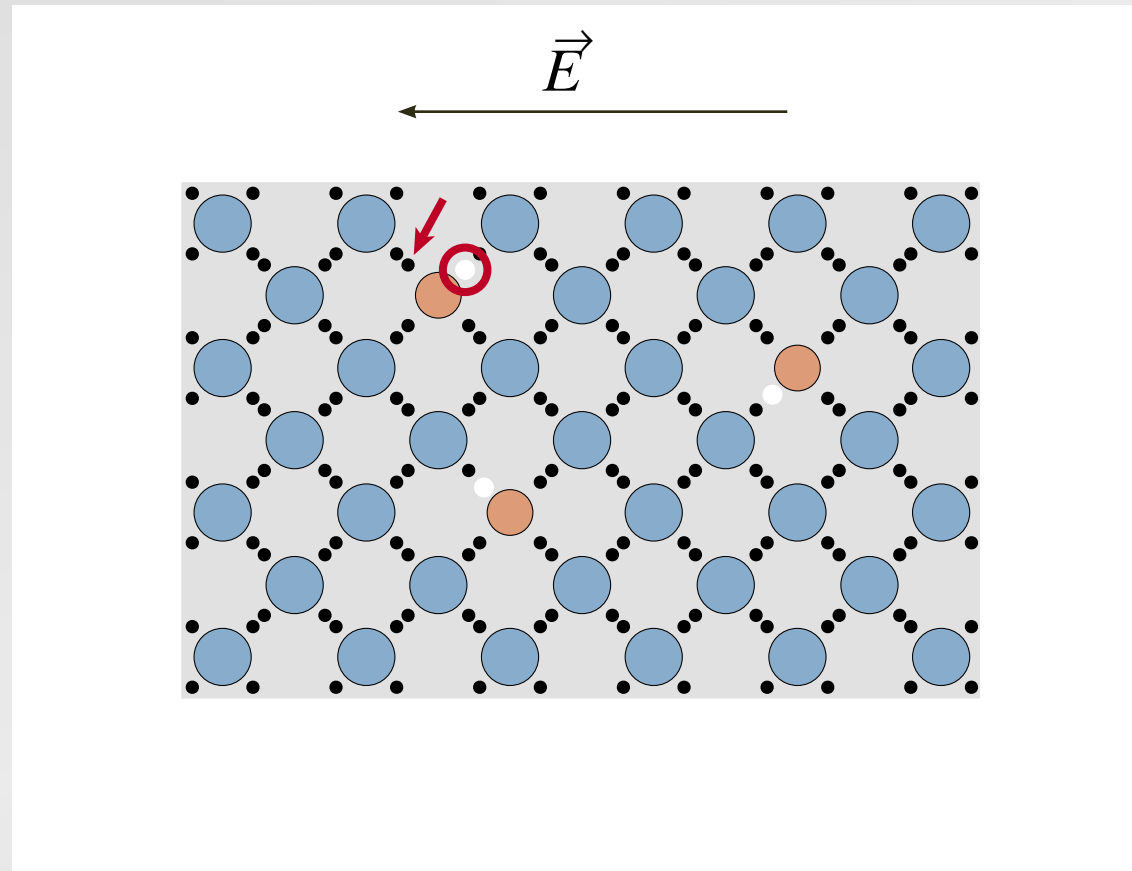
apply electric field...

Doped semiconductors



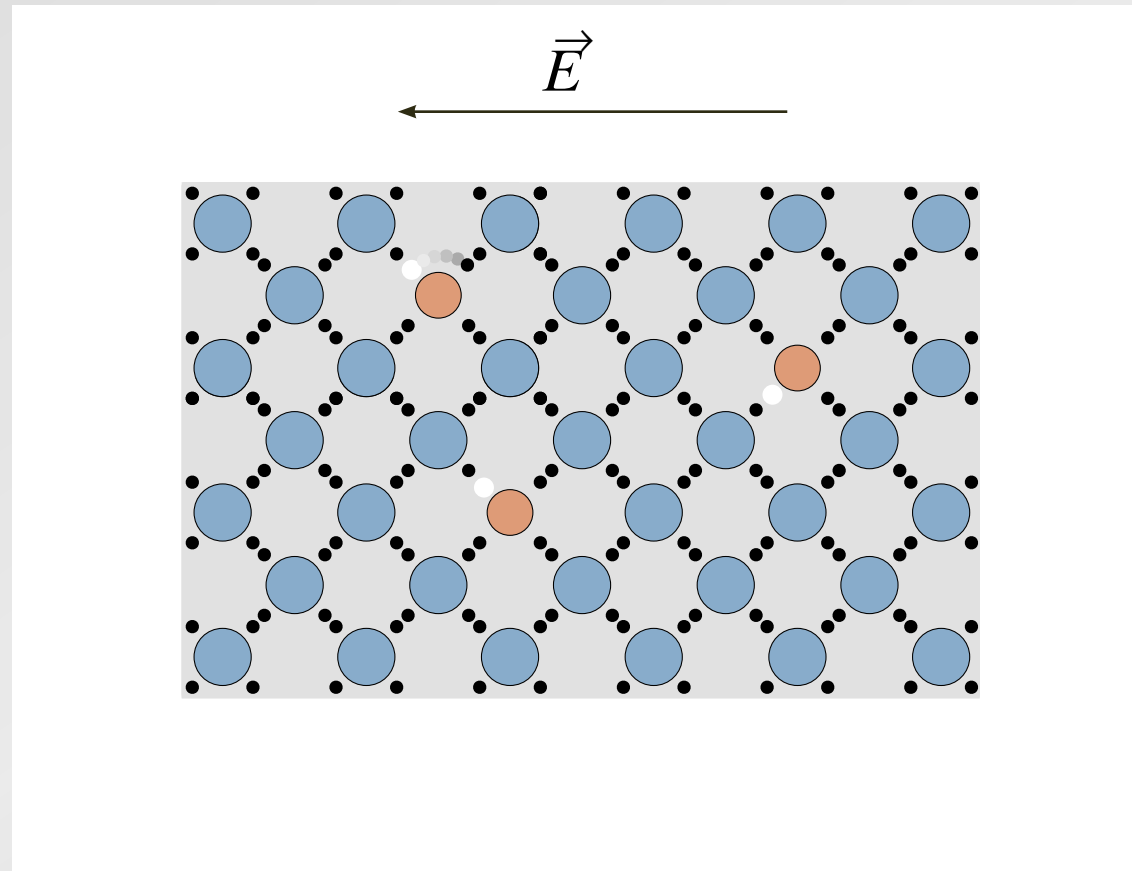
...presence of holes leads to conduction

Doped semiconductors



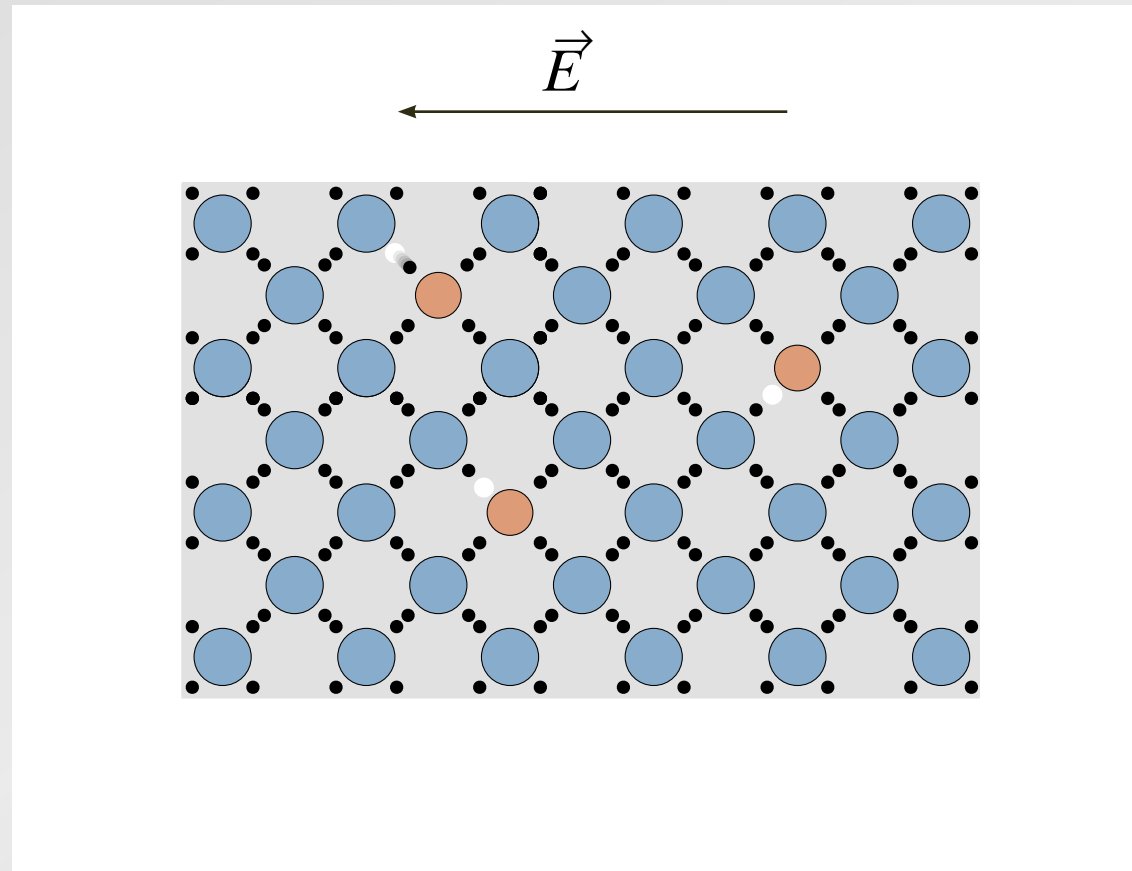
...presence of holes leads to conduction

Doped semiconductors



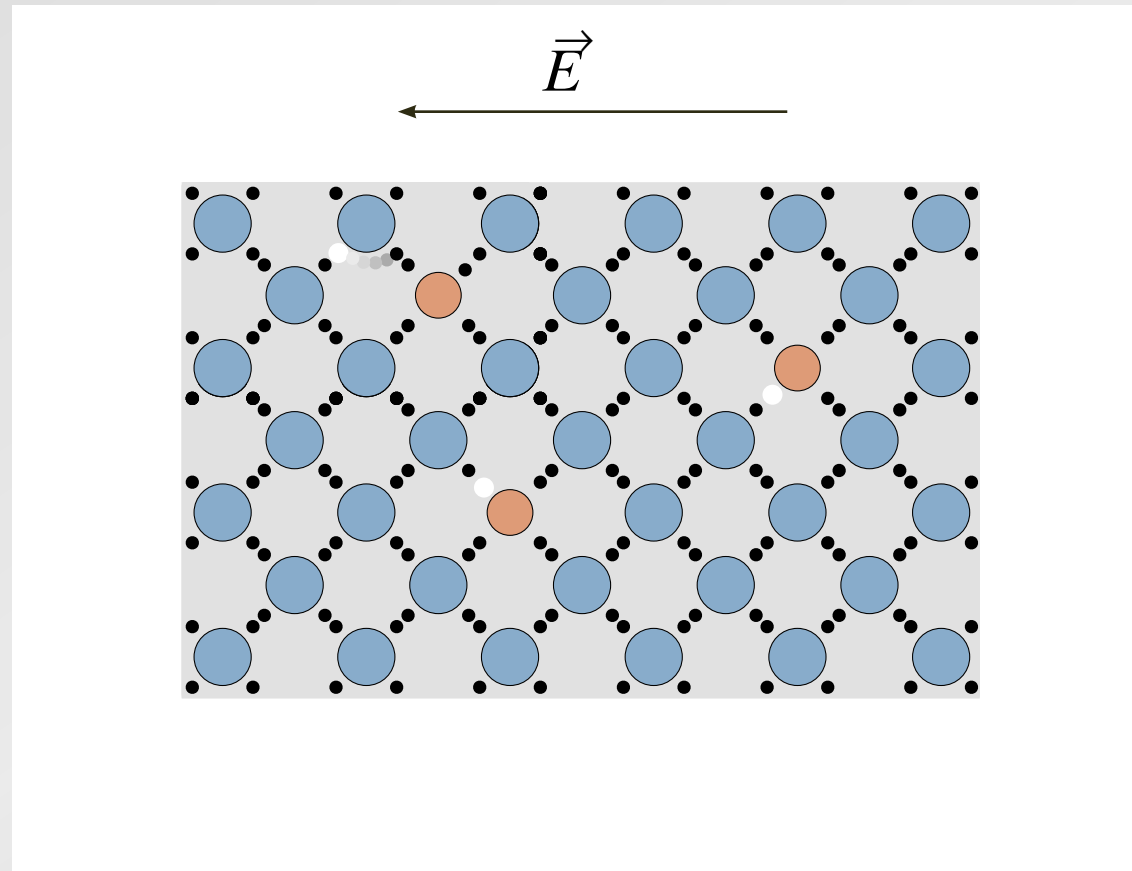
...presence of holes leads to conduction

Doped semiconductors



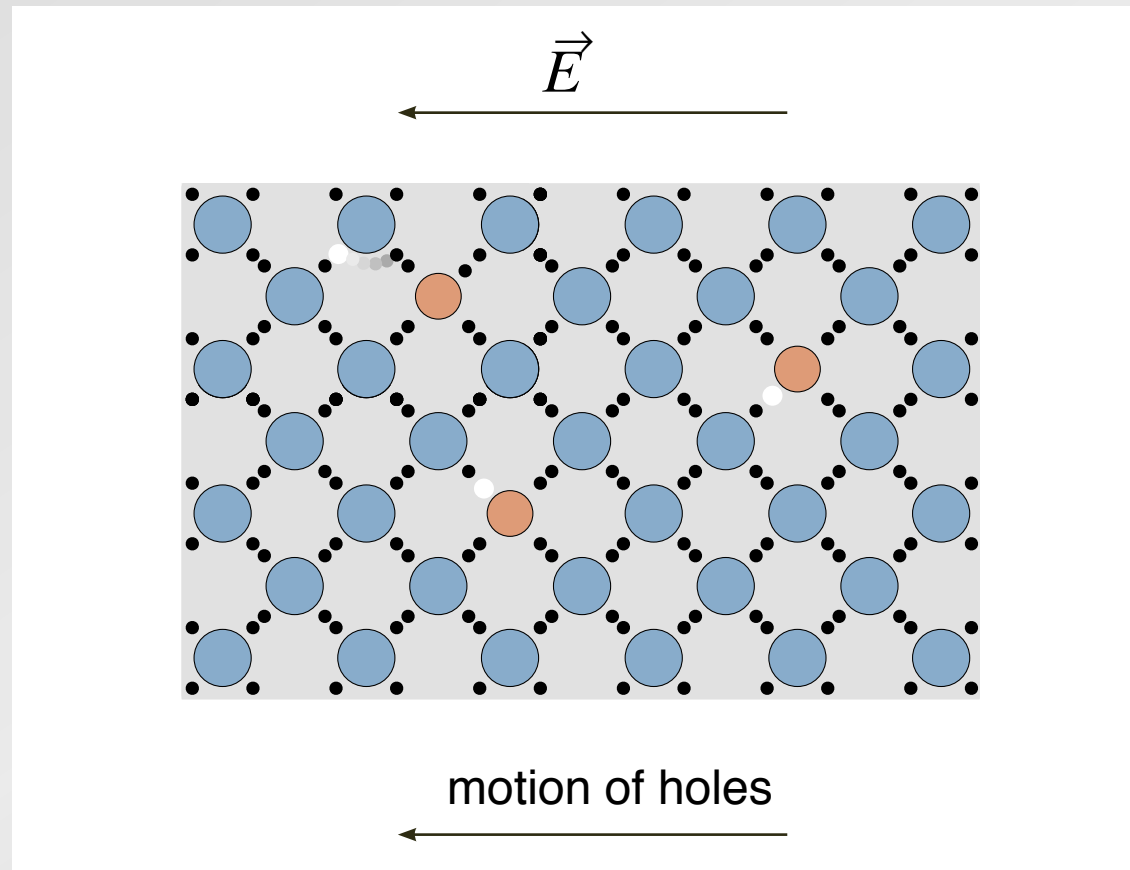
...presence of holes leads to conduction

Doped semiconductors



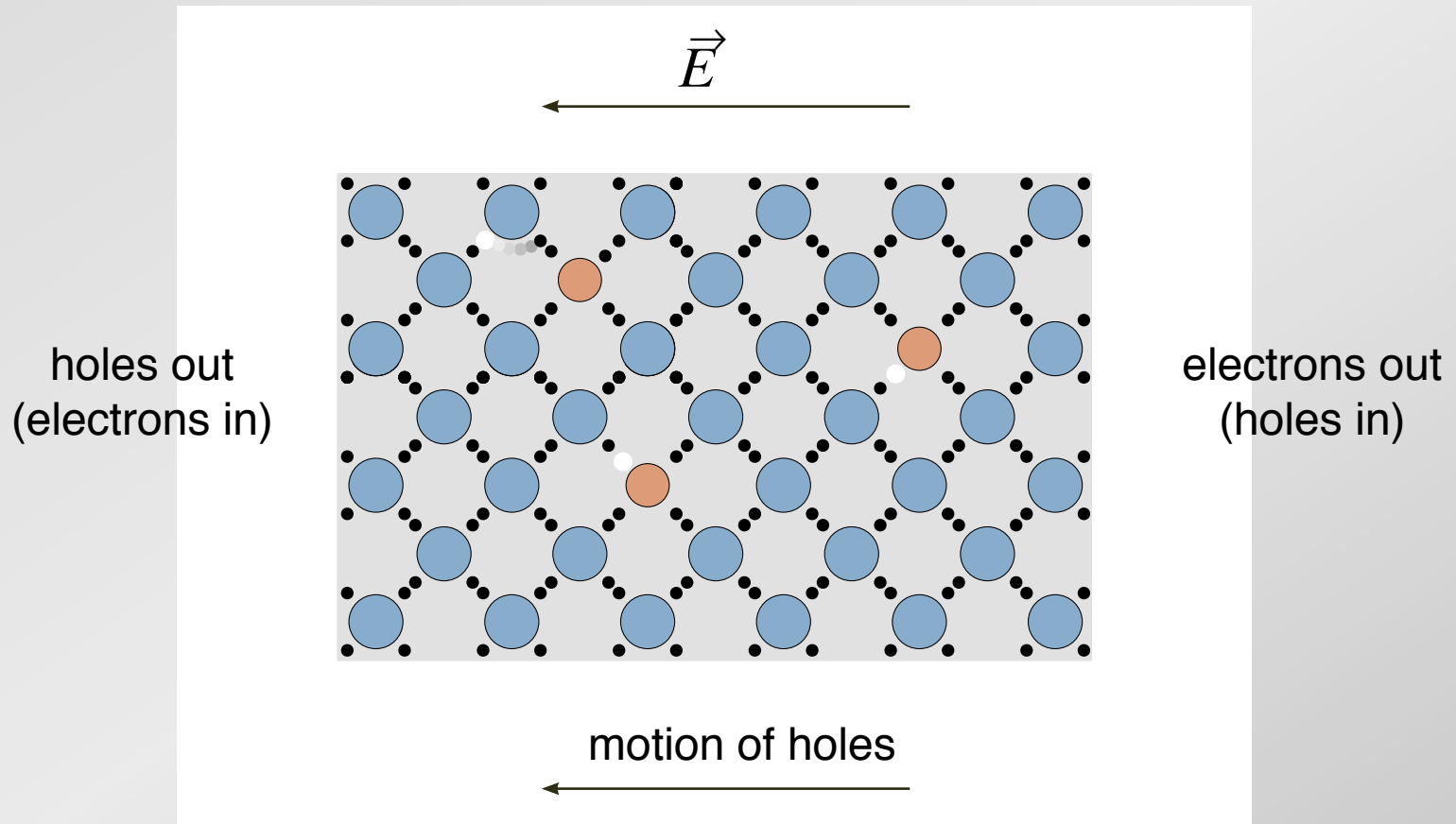
...presence of holes leads to conduction

Doped semiconductors



holes are like positively charged particles

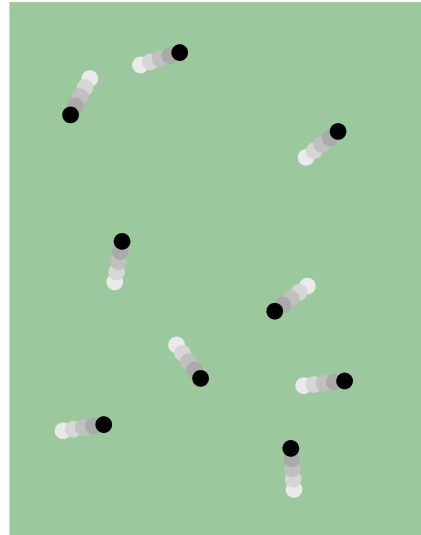
Doped semiconductors



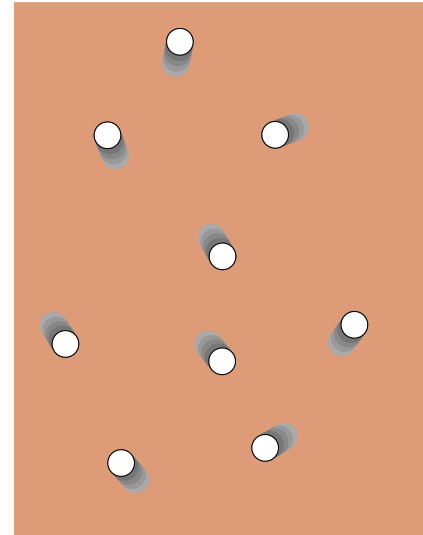
holes are like positively charged particles

Doped semiconductors

n-type



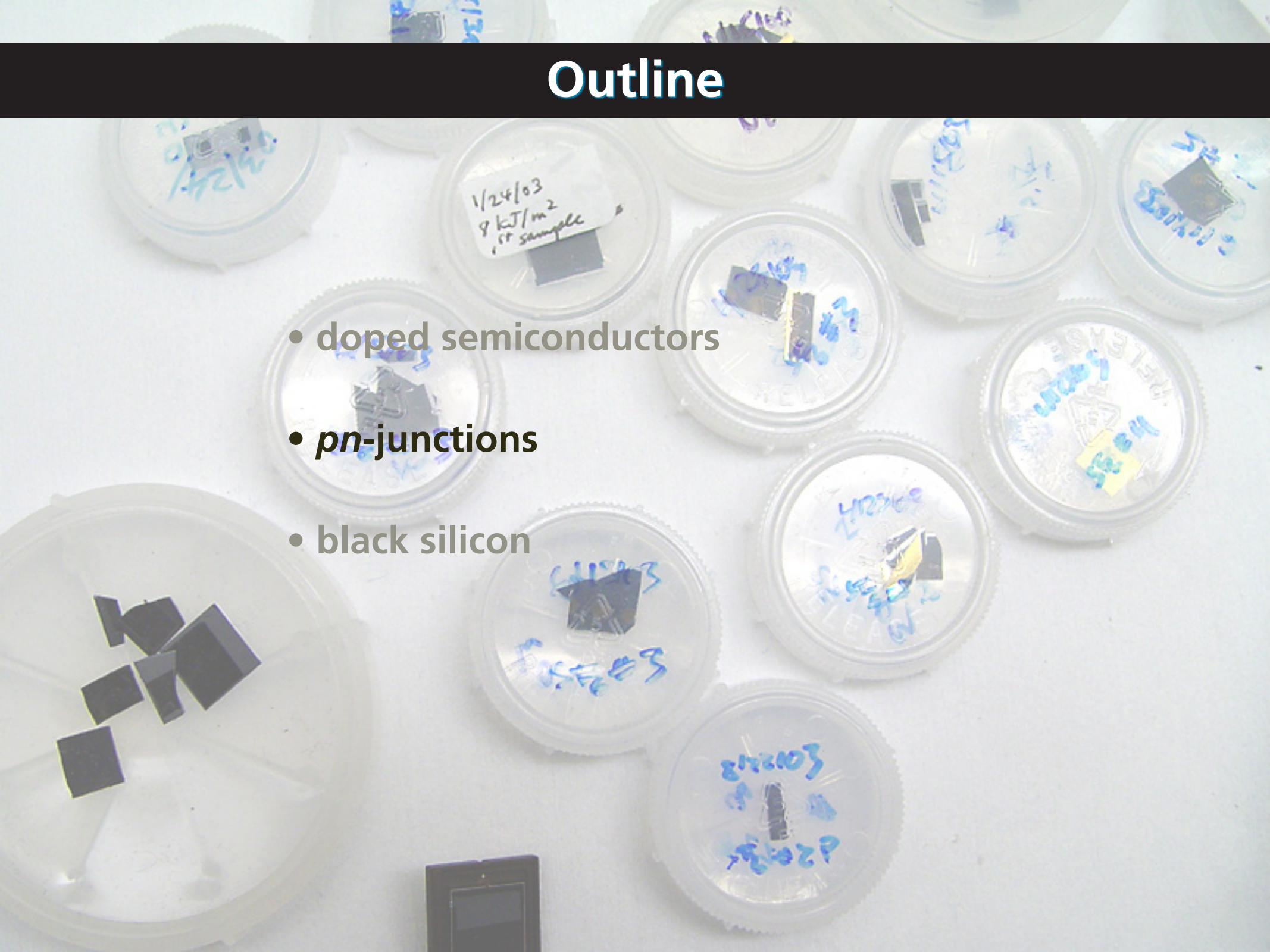
p-type



simplify representation

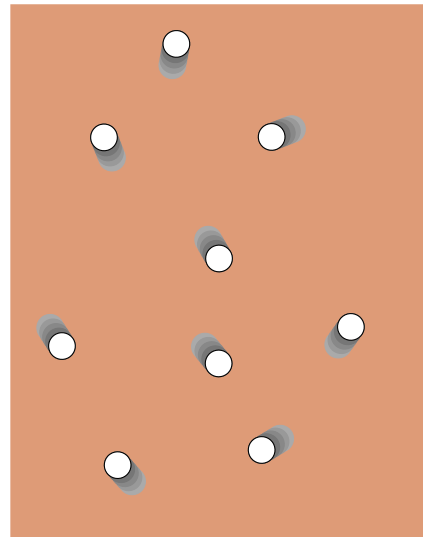
Outline

- doped semiconductors
- *pn*-junctions
- black silicon



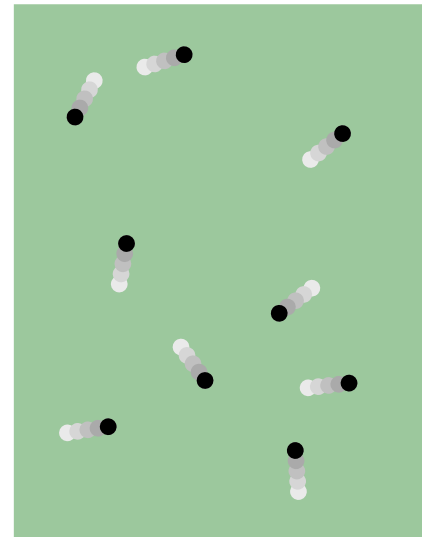
pn-junctions

neutral



p-type

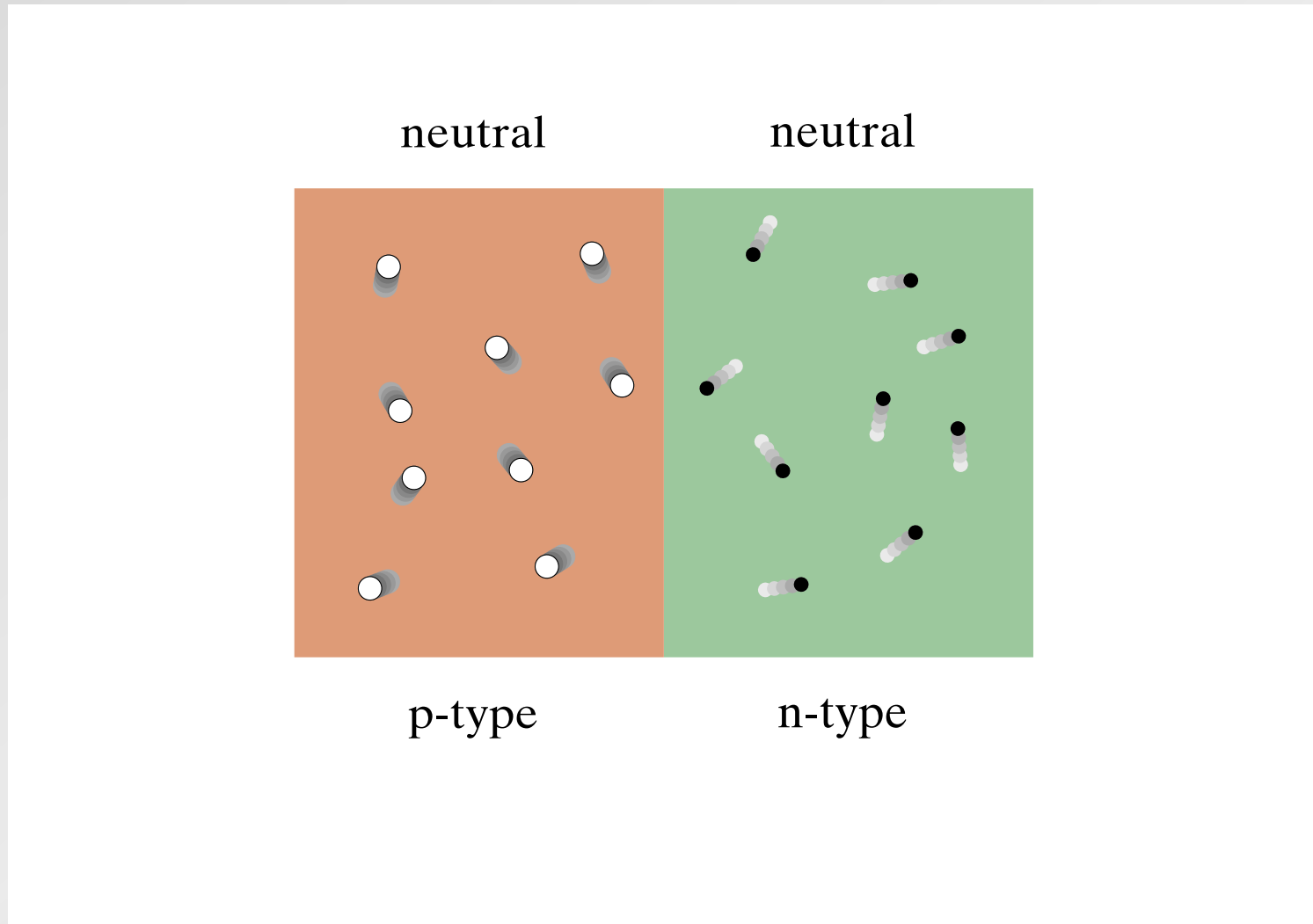
neutral



n-type

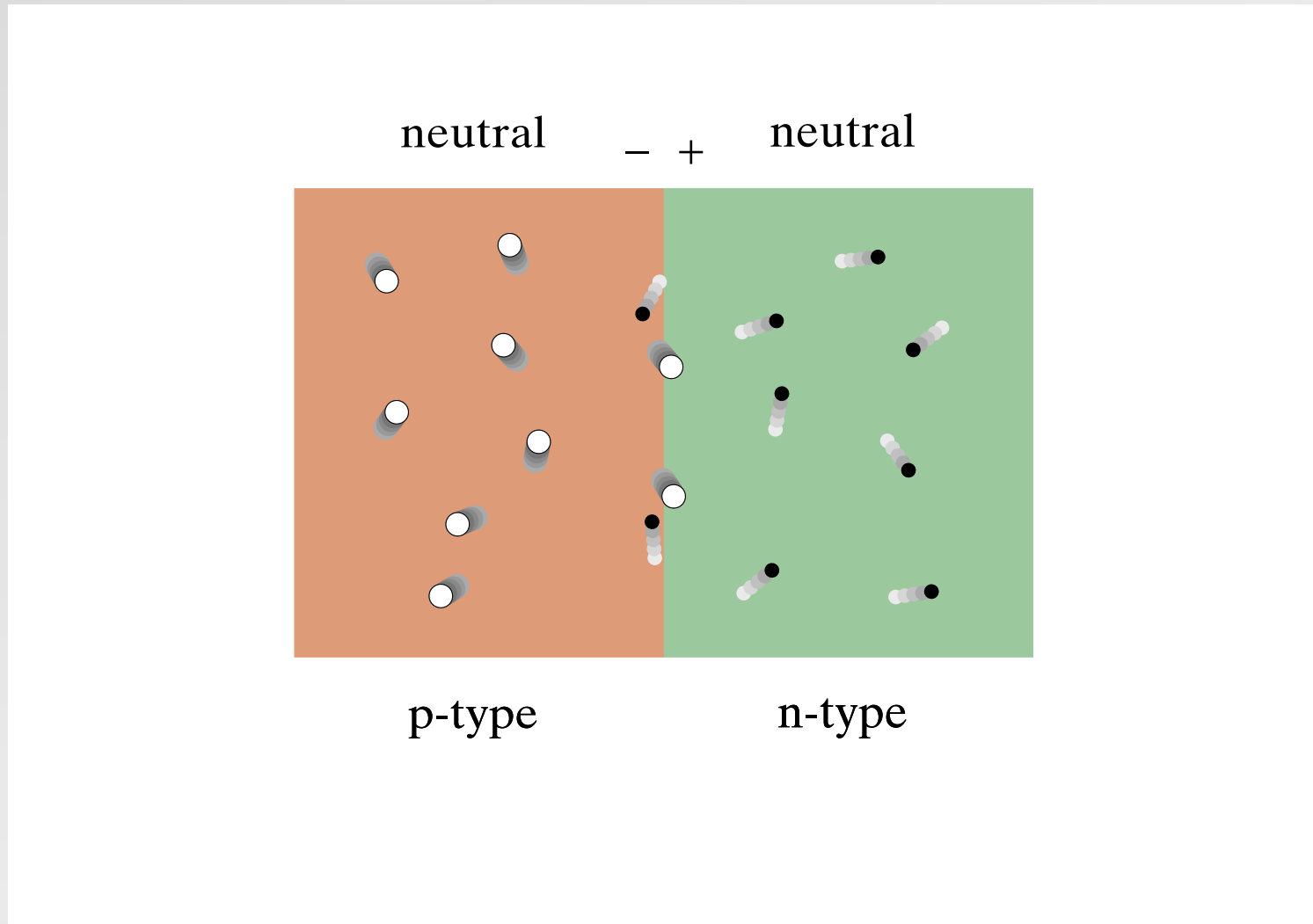
bring *p* and *n* materials together...

pn-junctions



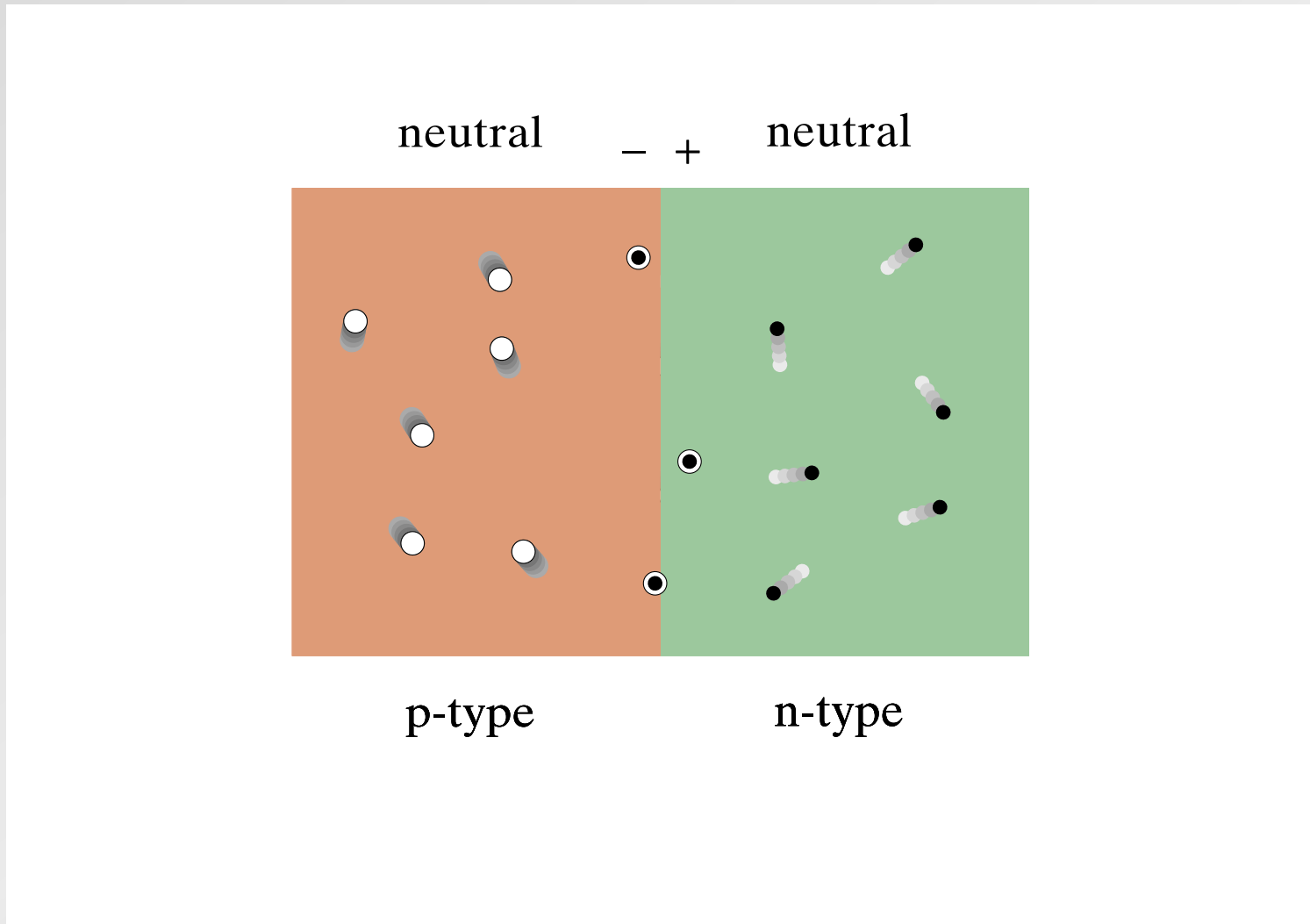
bring *p* and *n* materials together...

pn-junctions



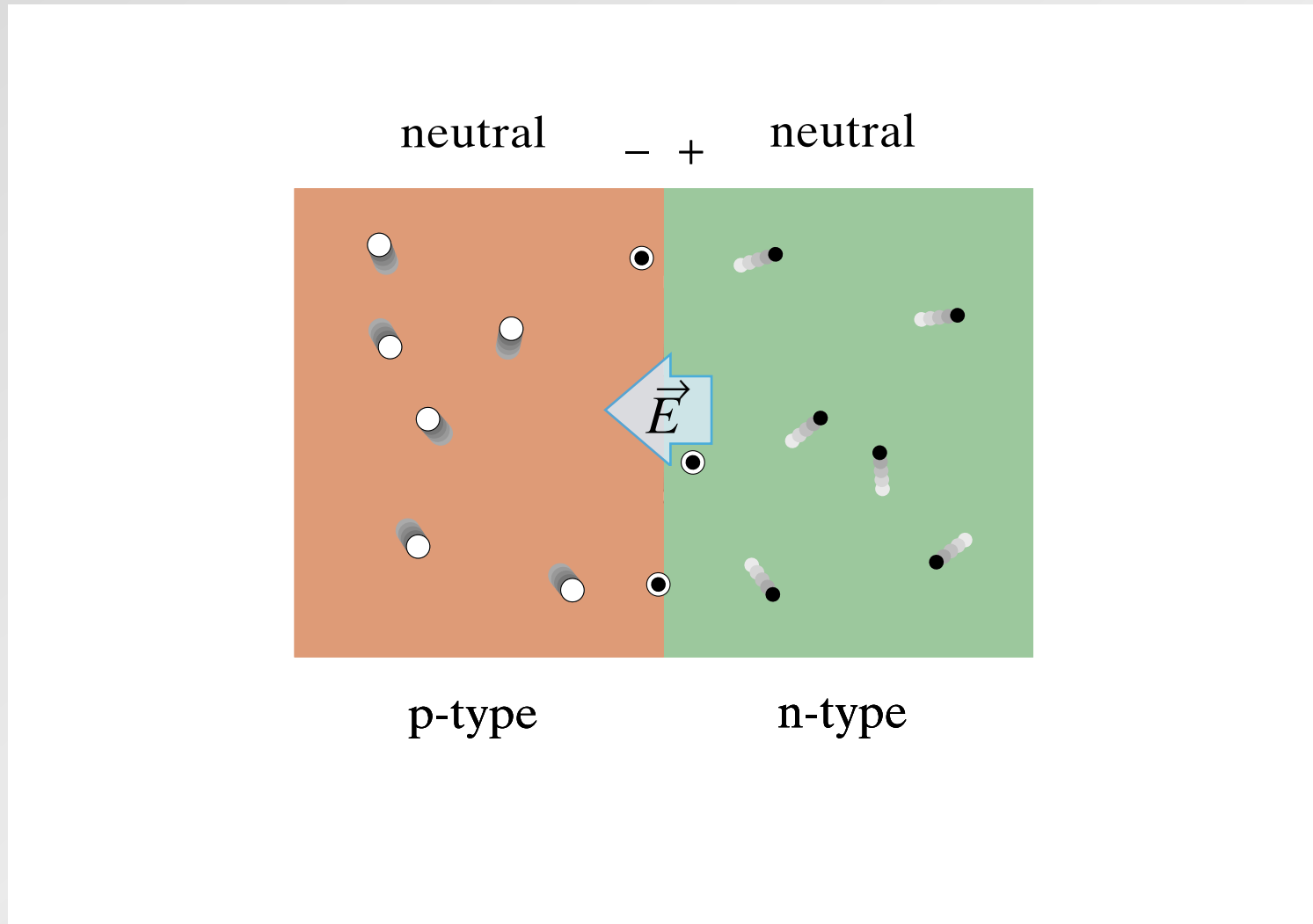
electrons and holes diffuse across junction...

pn-junctions



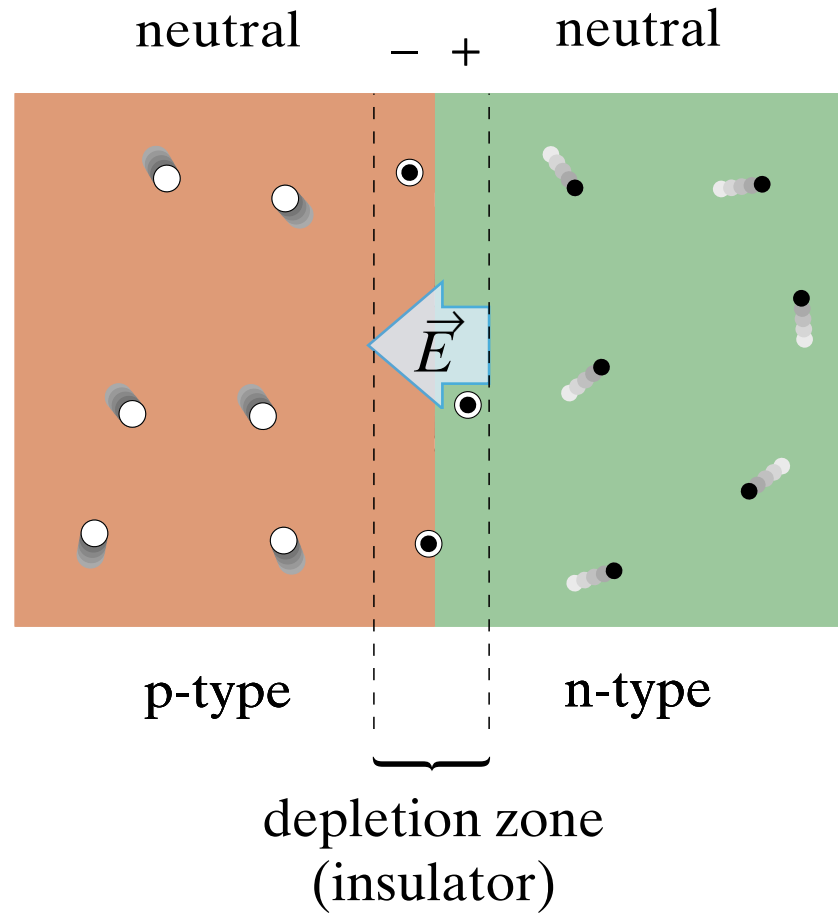
...and get 'trapped' after they combine

pn-junctions



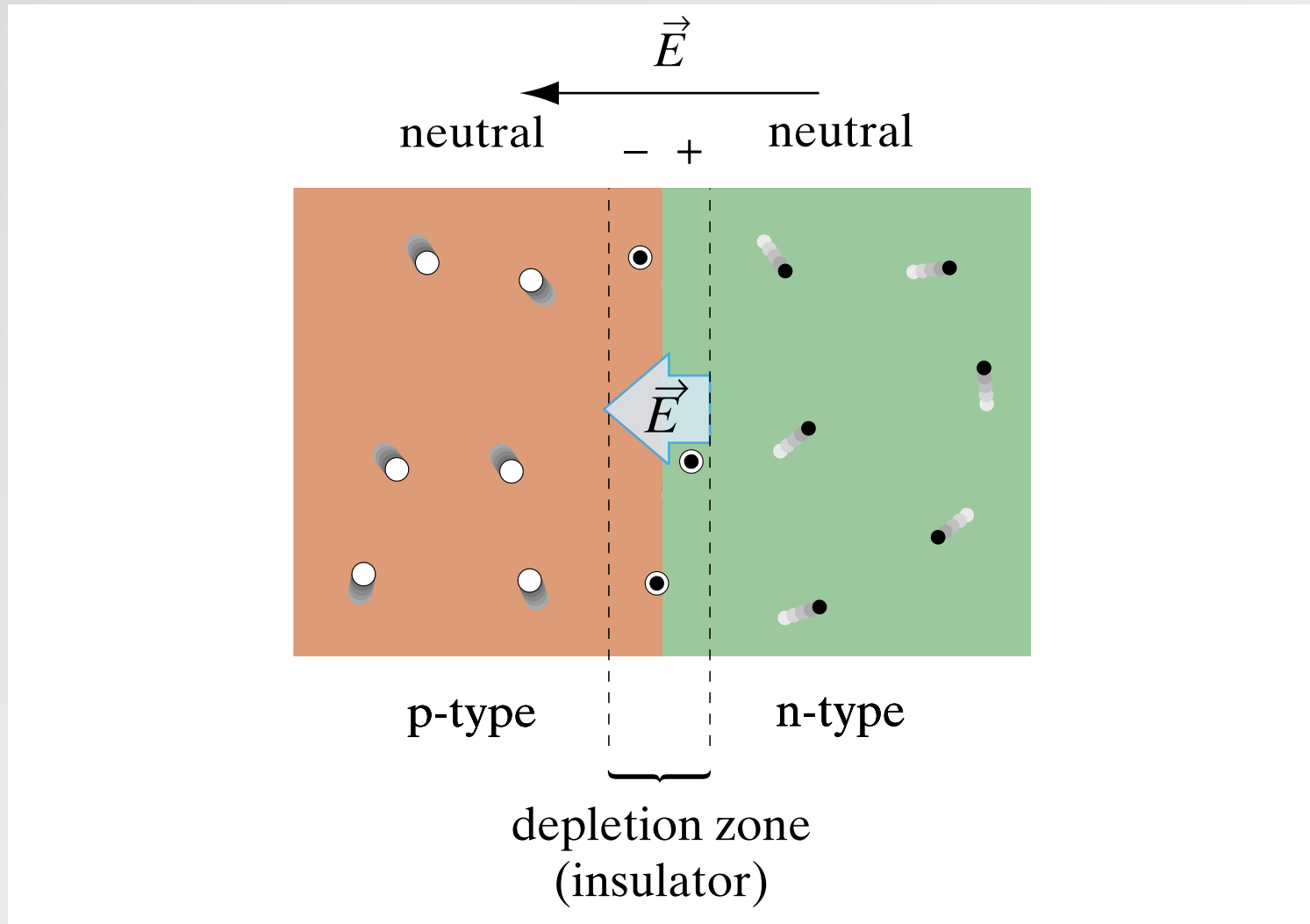
build-up of charge leads to electric field that stops diffusion

pn-junctions



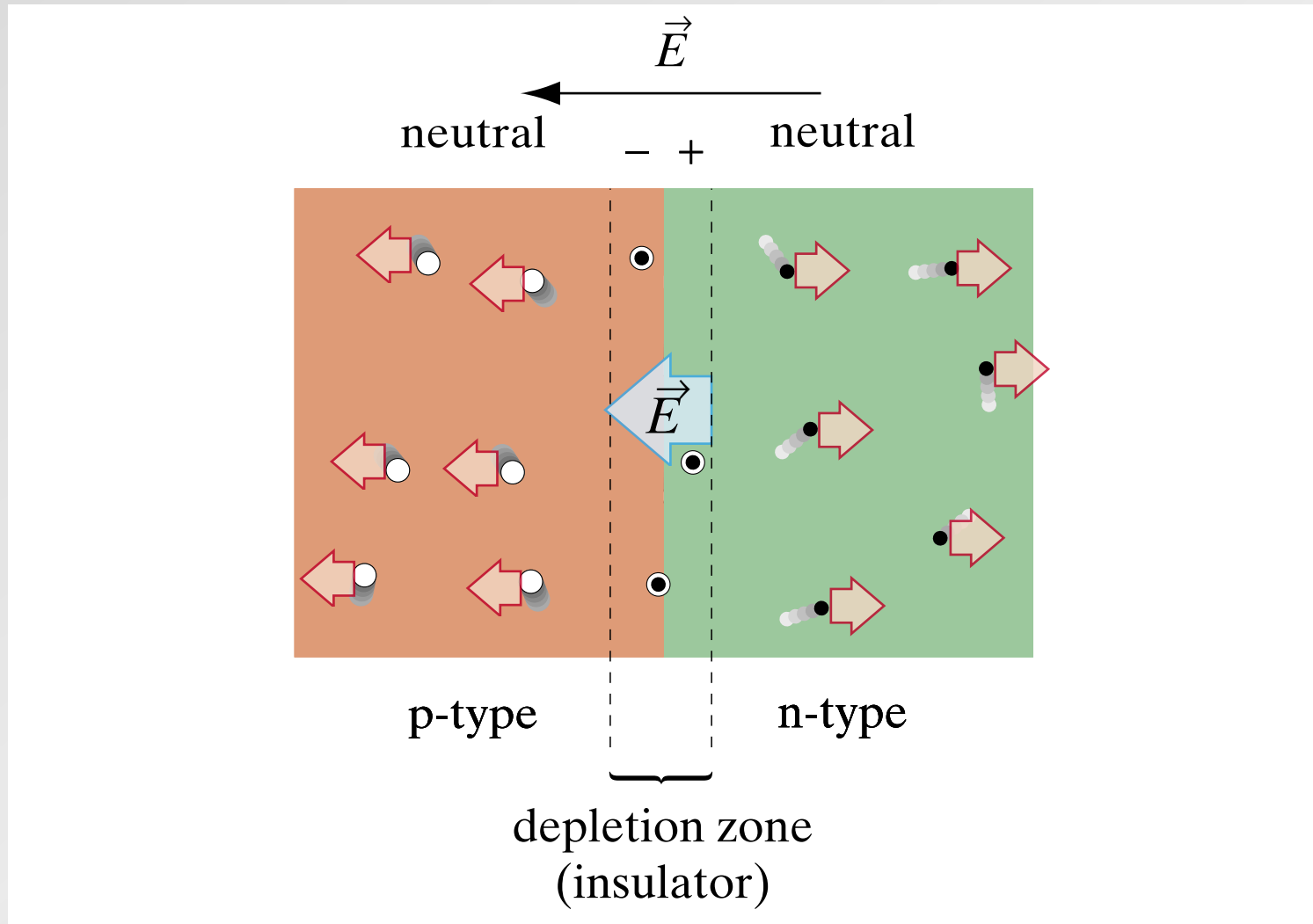
non-conducting layer at junction

pn-junctions



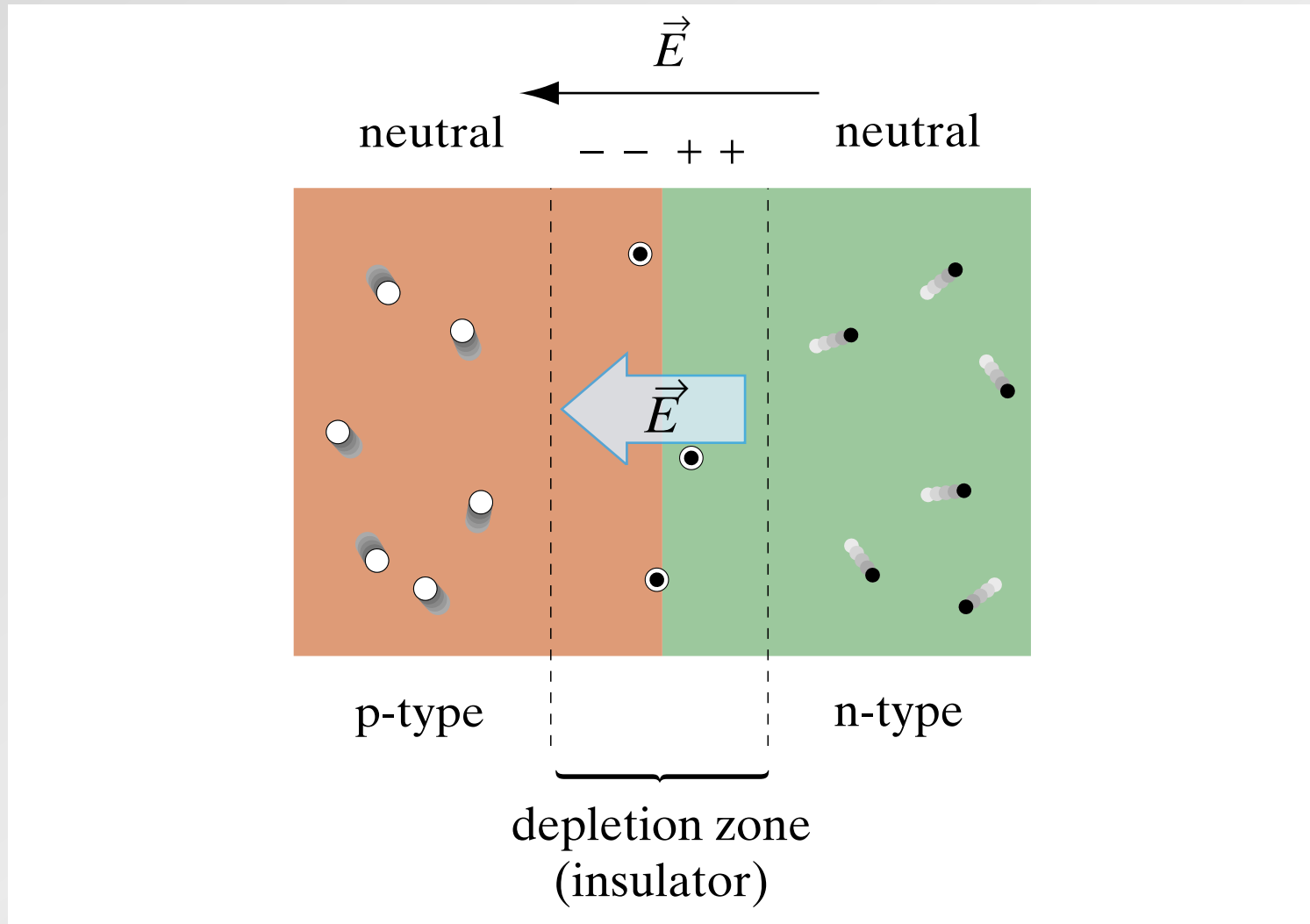
apply electric field...

pn-junctions



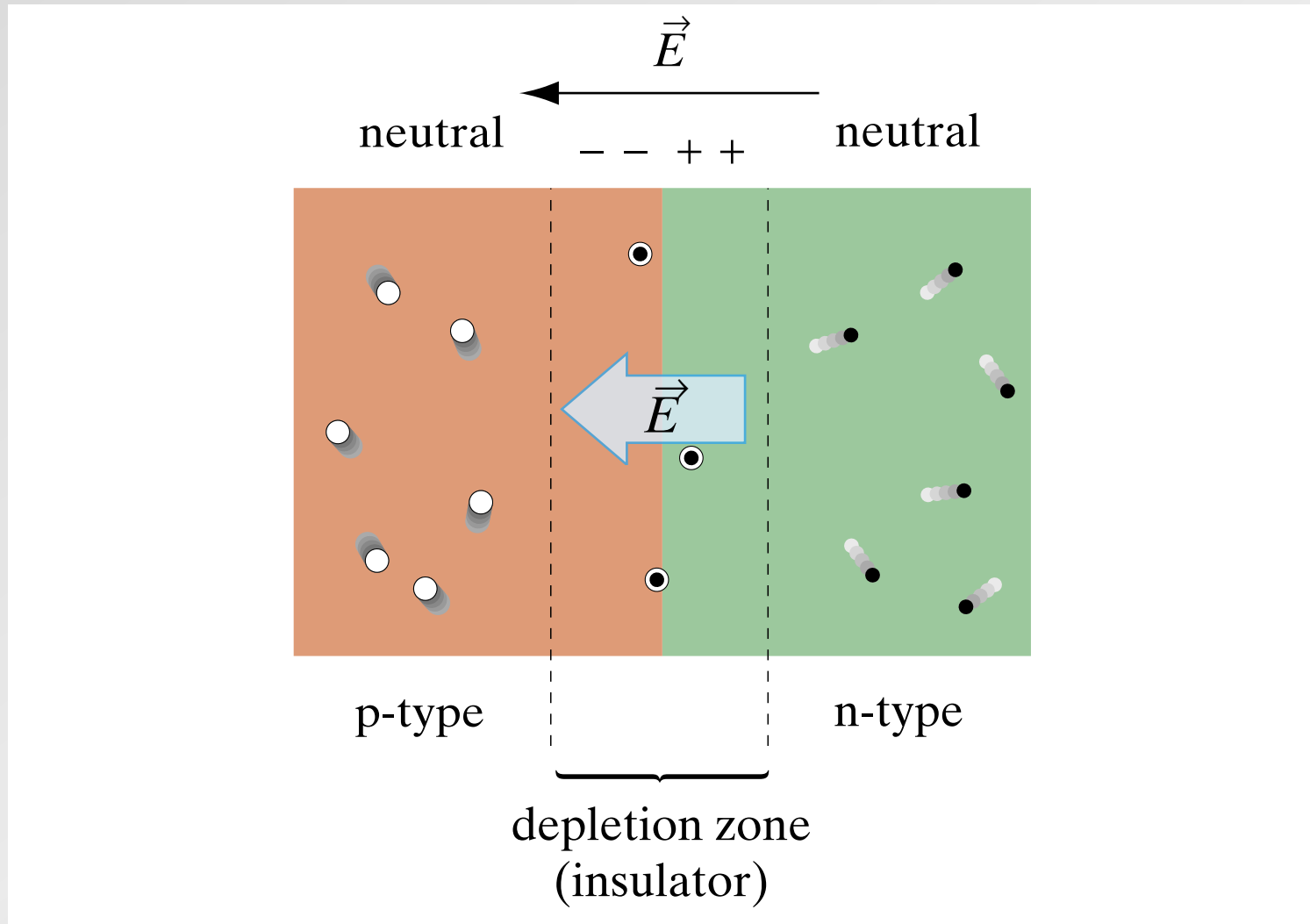
...holes pushed to left, electrons to right...

pn-junctions



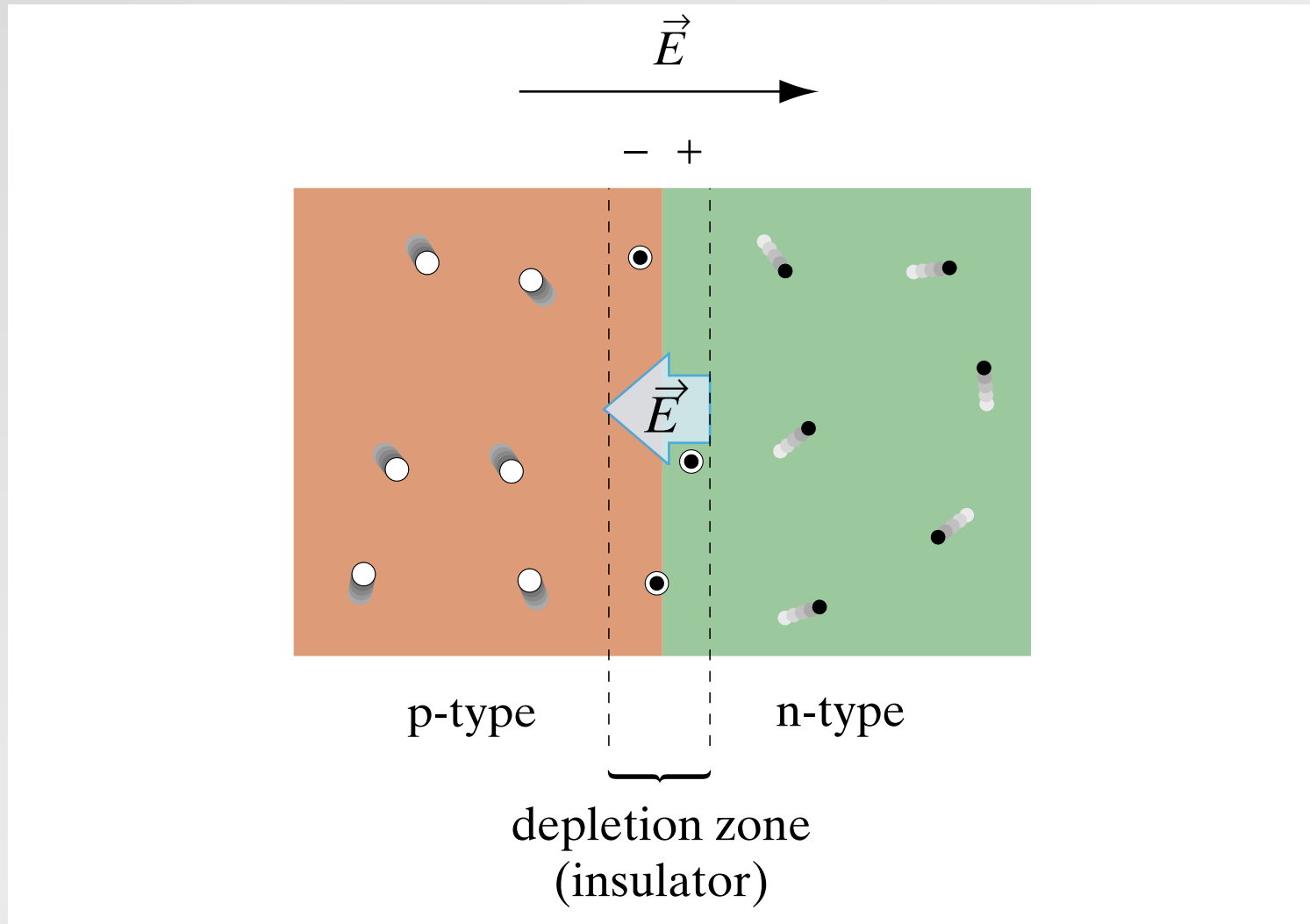
...and so depletion zone expands

pn-junctions



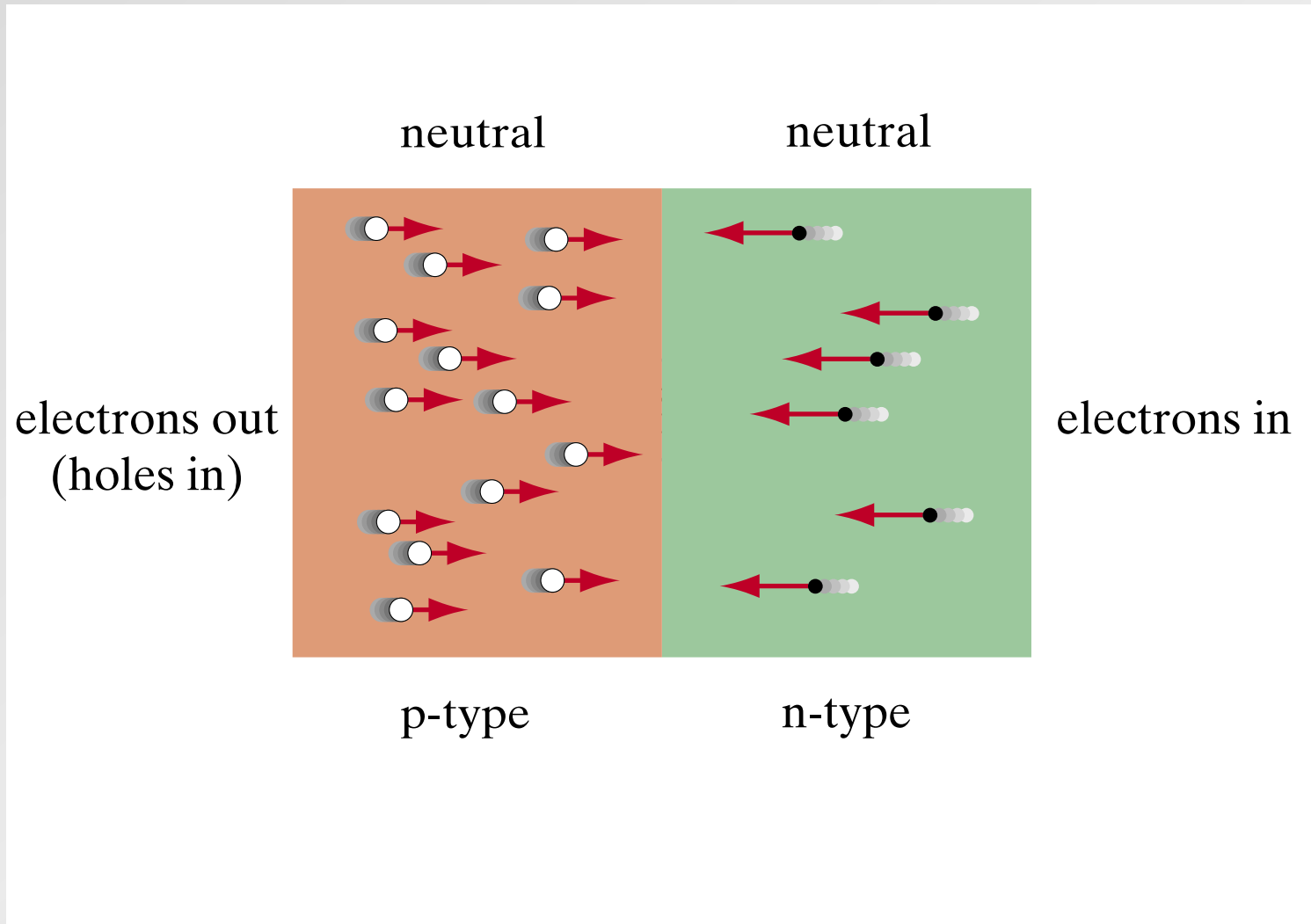
NO conduction

pn-junctions



reverse electric field...

pn-junctions



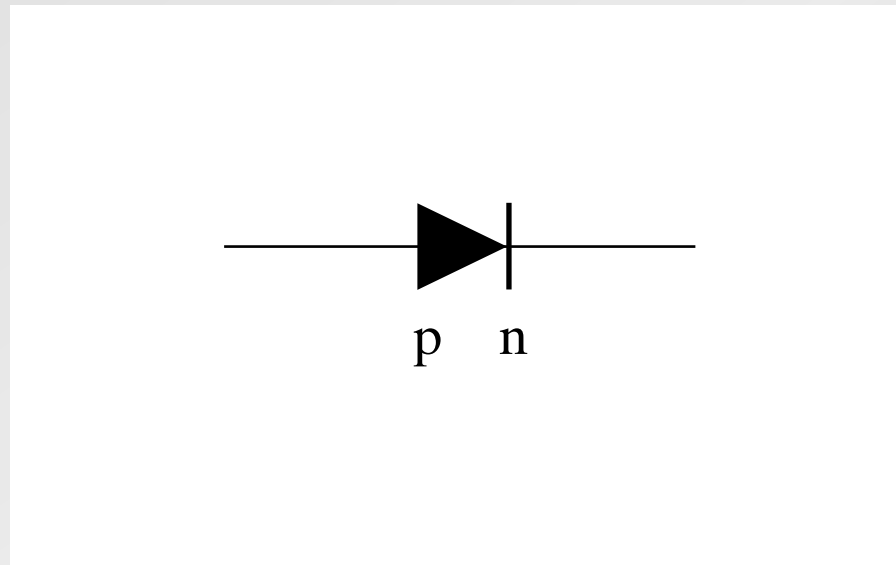
...depletion zone shrinks and current flows

pn-junctions

so *pn*-junction like one-way valve for charge flow

pn-junctions

diode

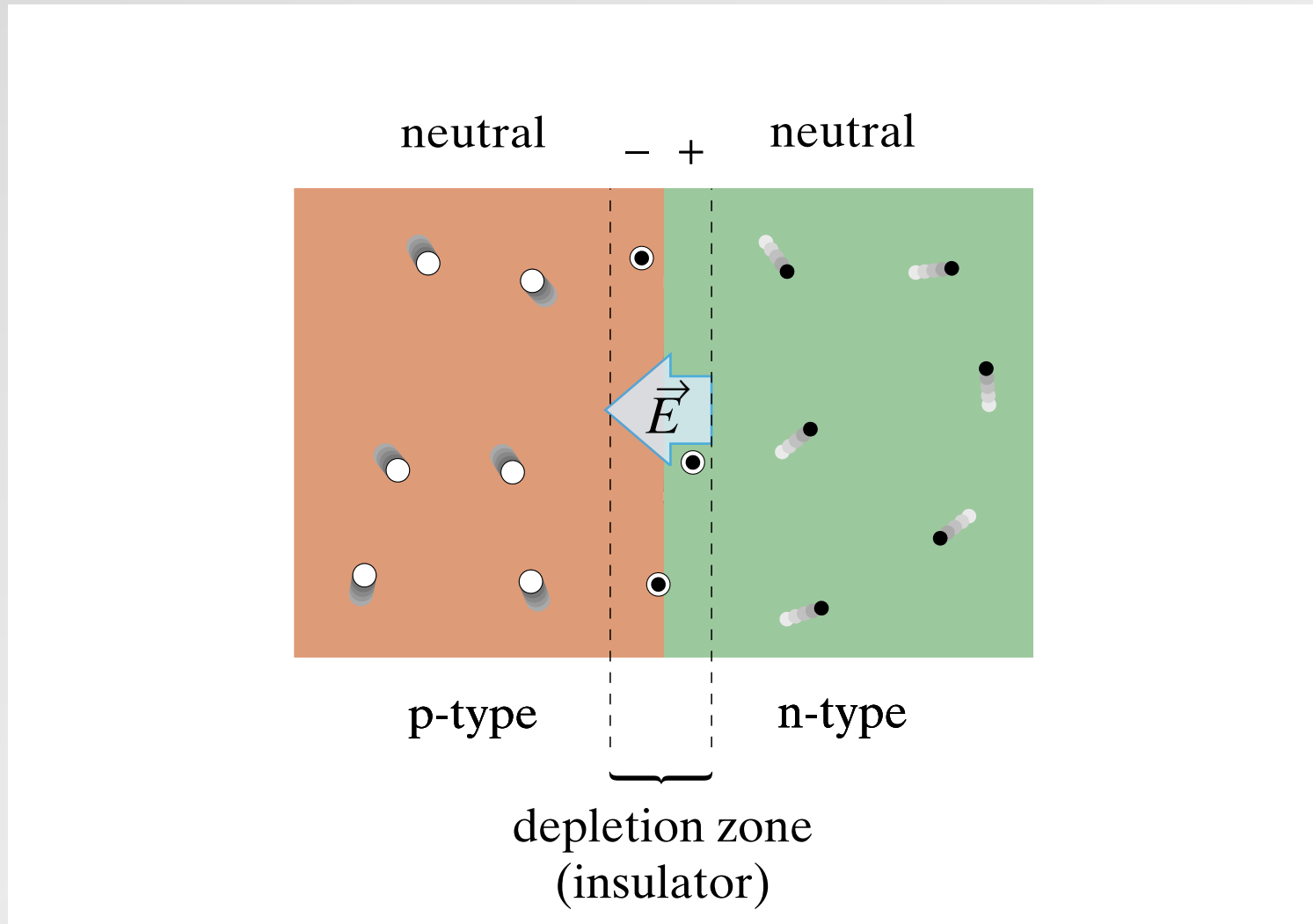


current flows along arrow only (from *p* to *n*)

pn-junctions

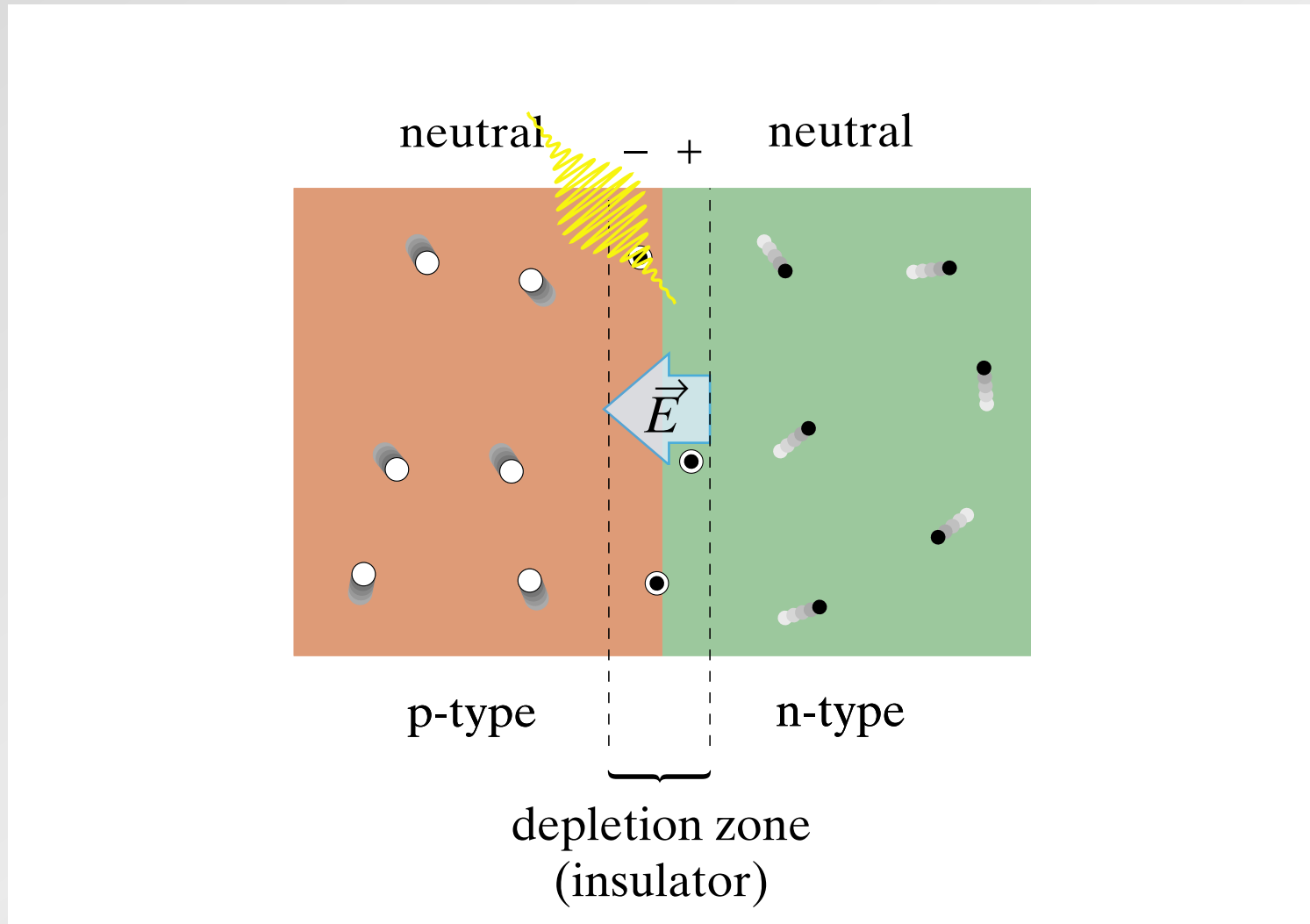
can also be used as a light detector!

pn-junctions



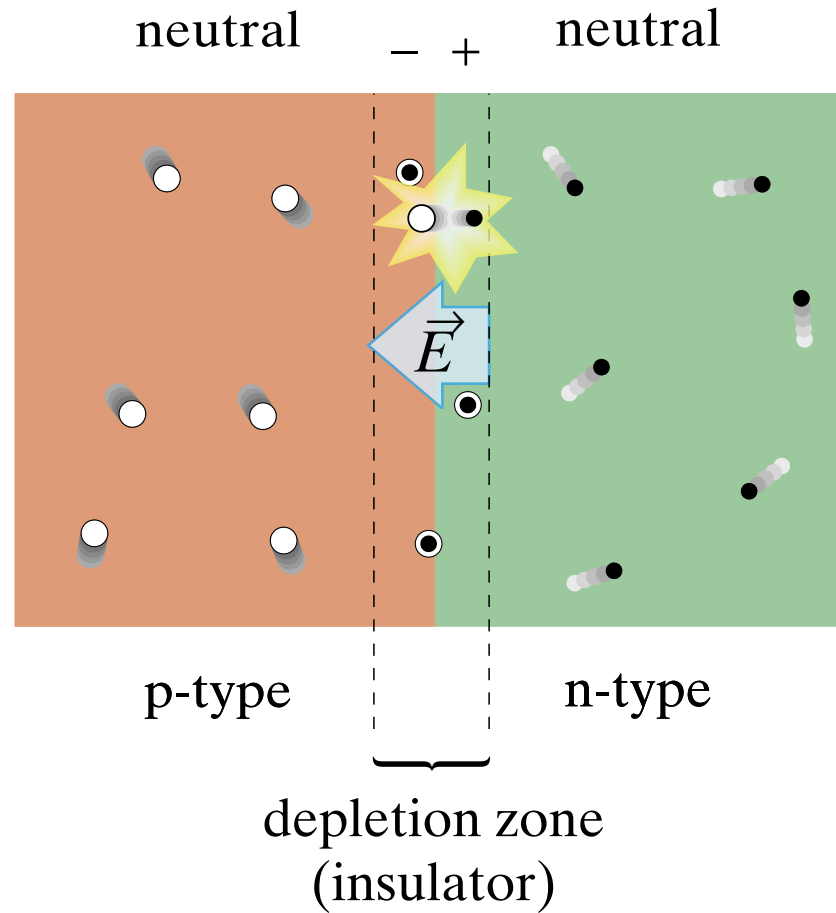
depletion layer can convert light into electric energy

pn-junctions



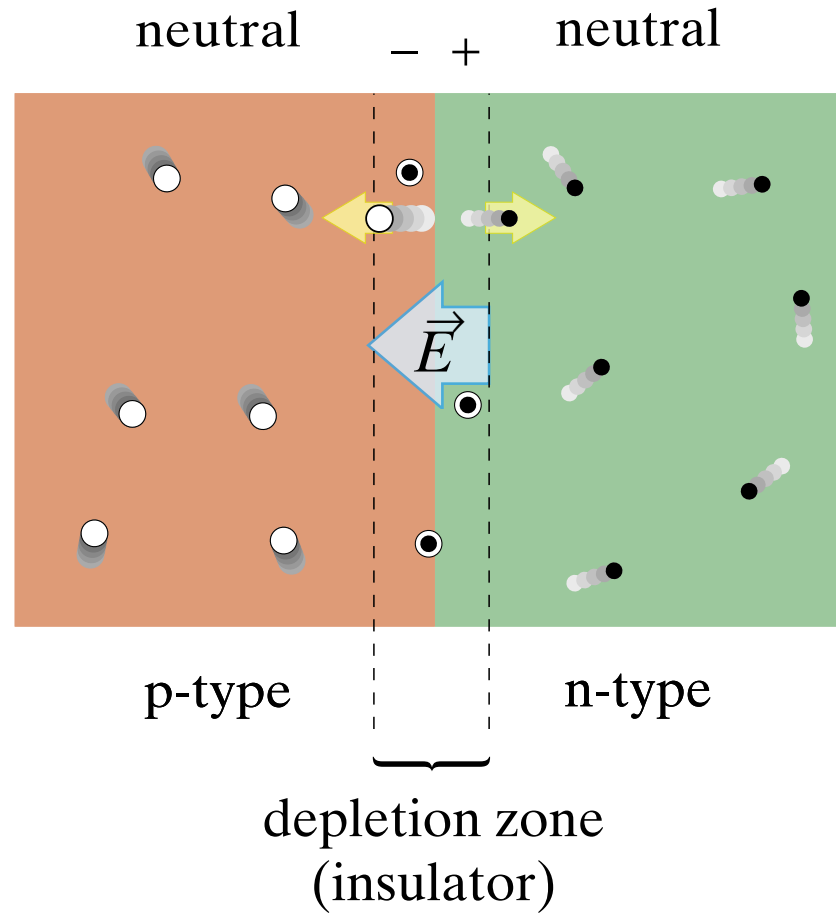
incident photon knocks out electron...

pn-junctions



...creating an electron-hole pair

pn-junctions

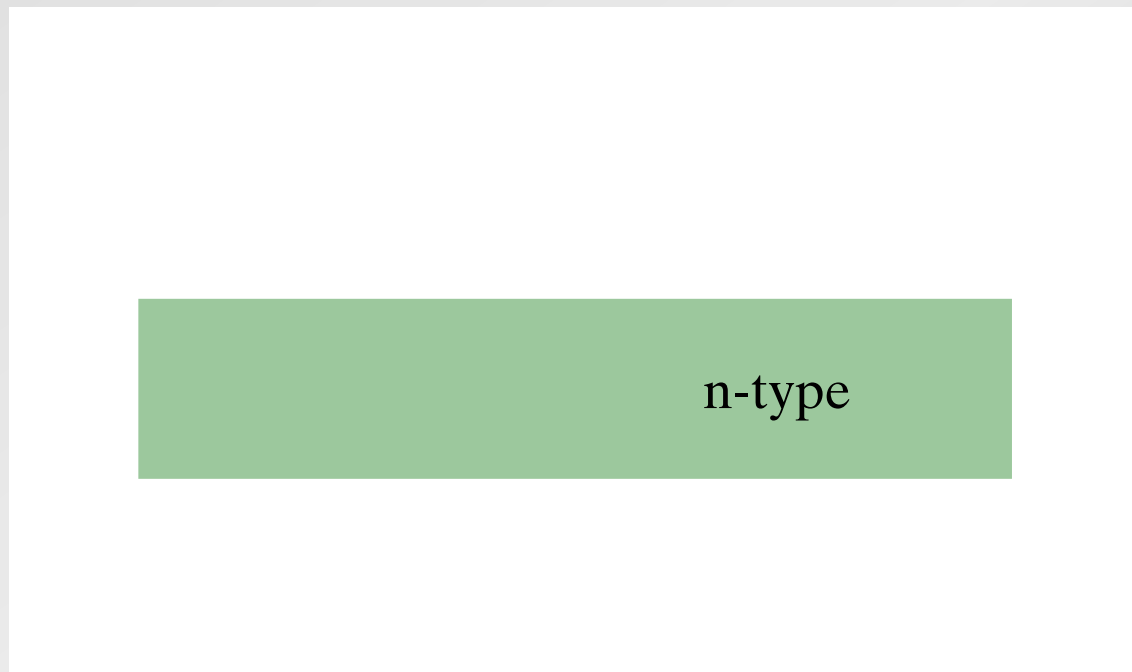


E-field separates eh-pair, causing current

pn-junctions

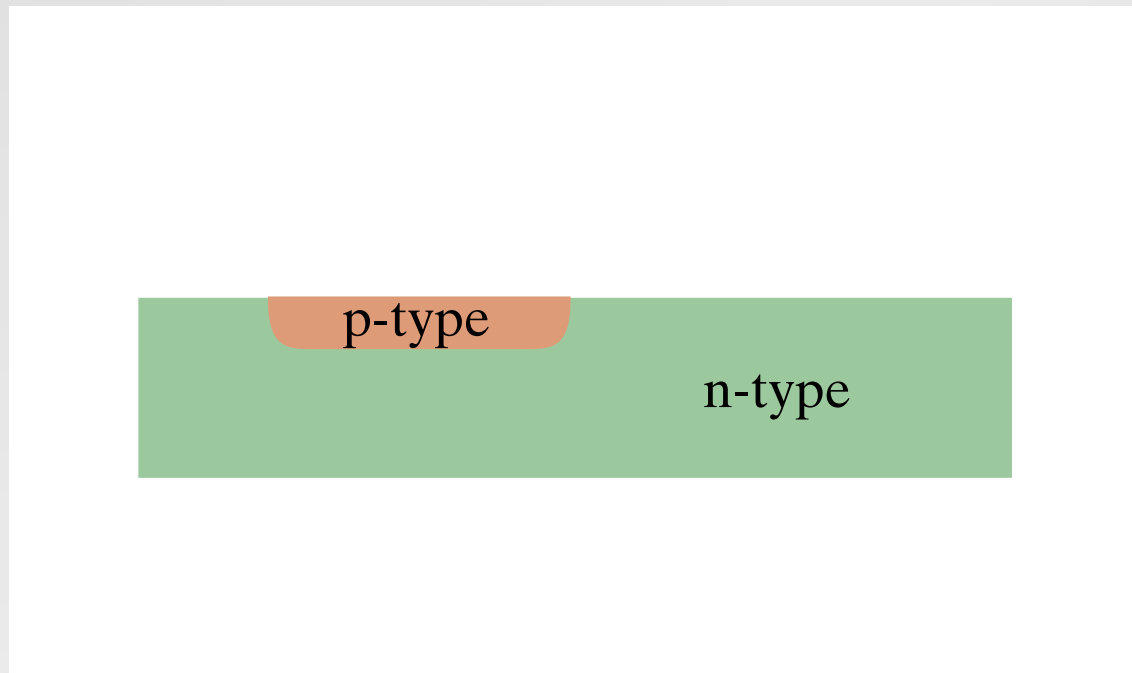
how to make a miniature diode on a chip?

pn-junctions



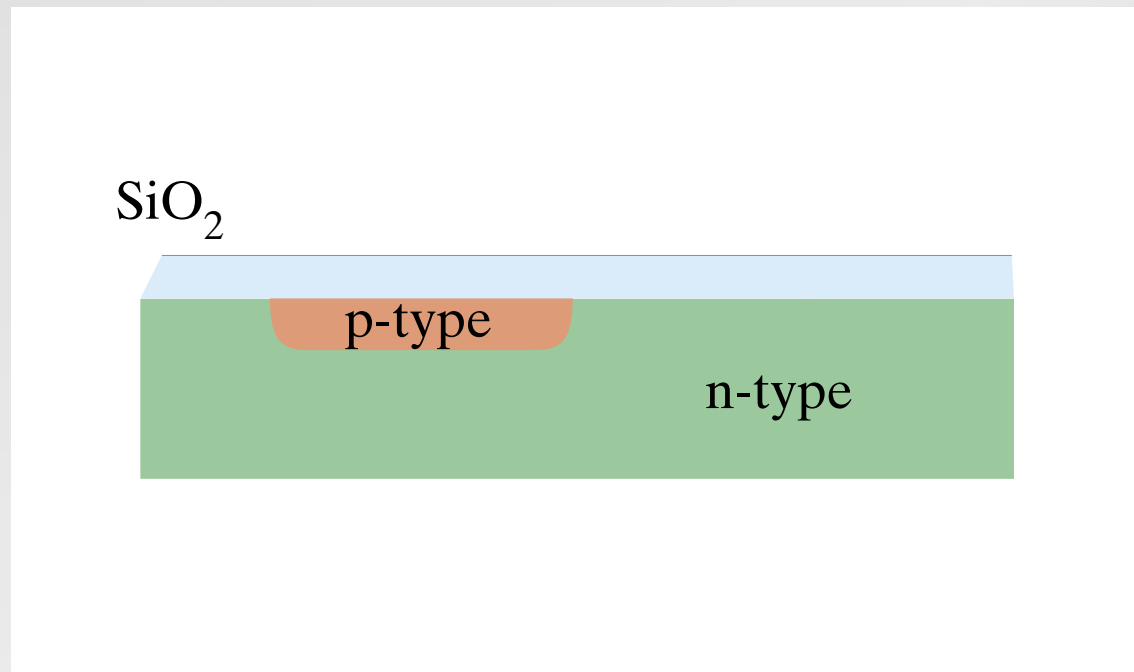
begin with an *n*-doped wafer

pn-junctions



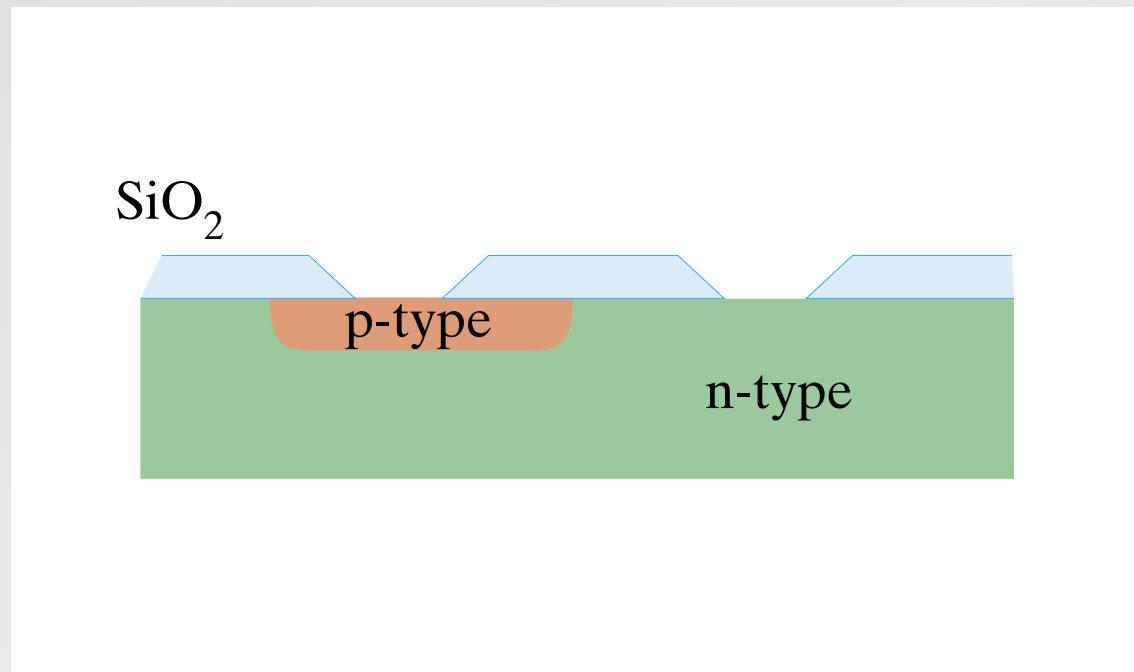
***p*-dope small region**

pn-junctions



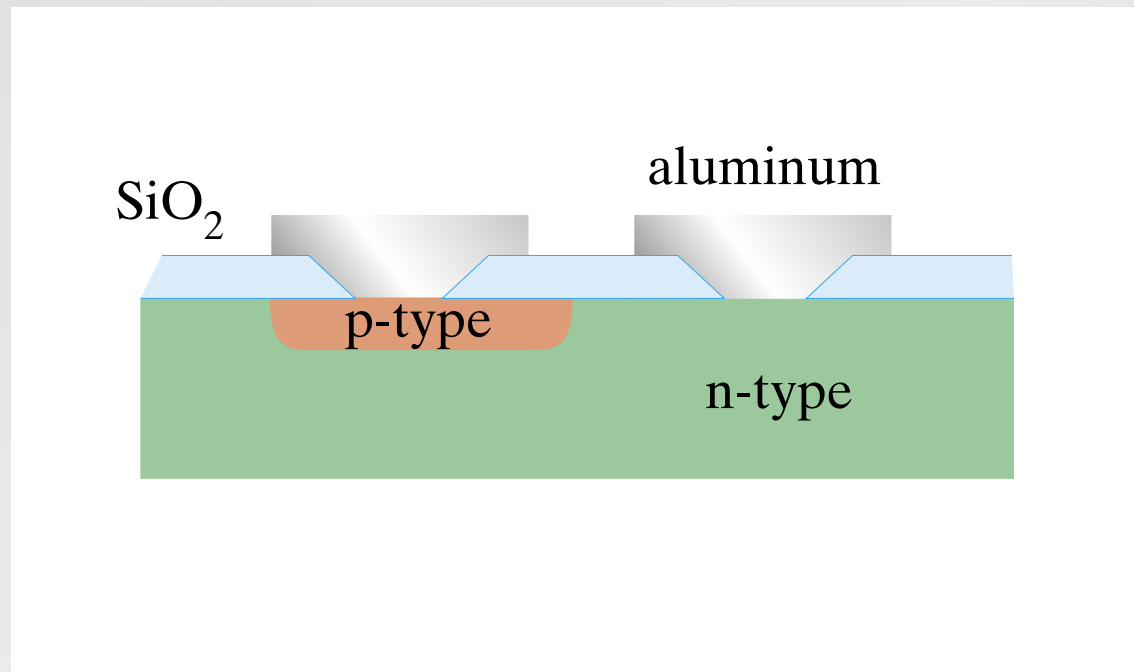
cover with insulating layer

pn-junctions



etch insulating layer

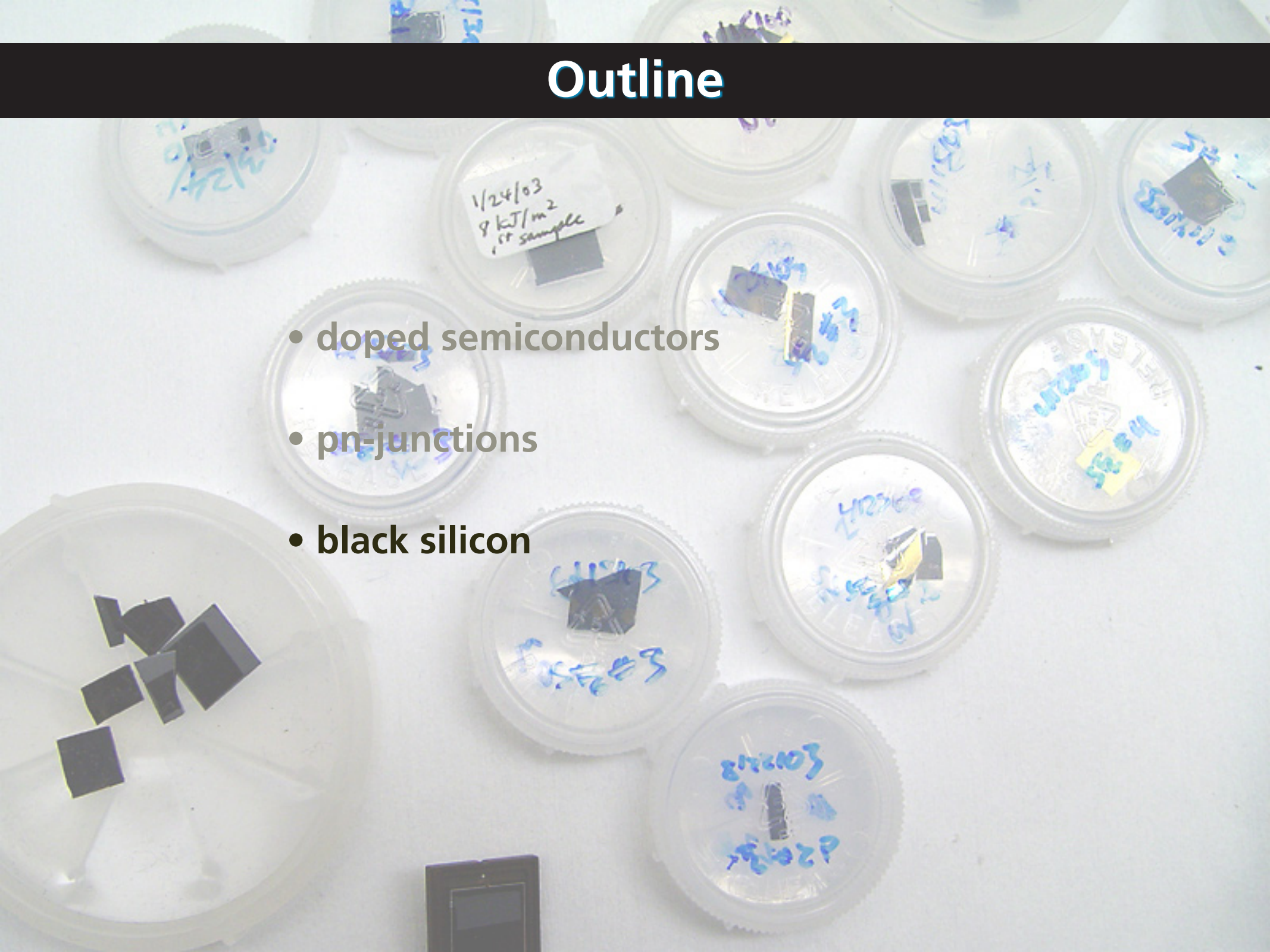
pn-junctions



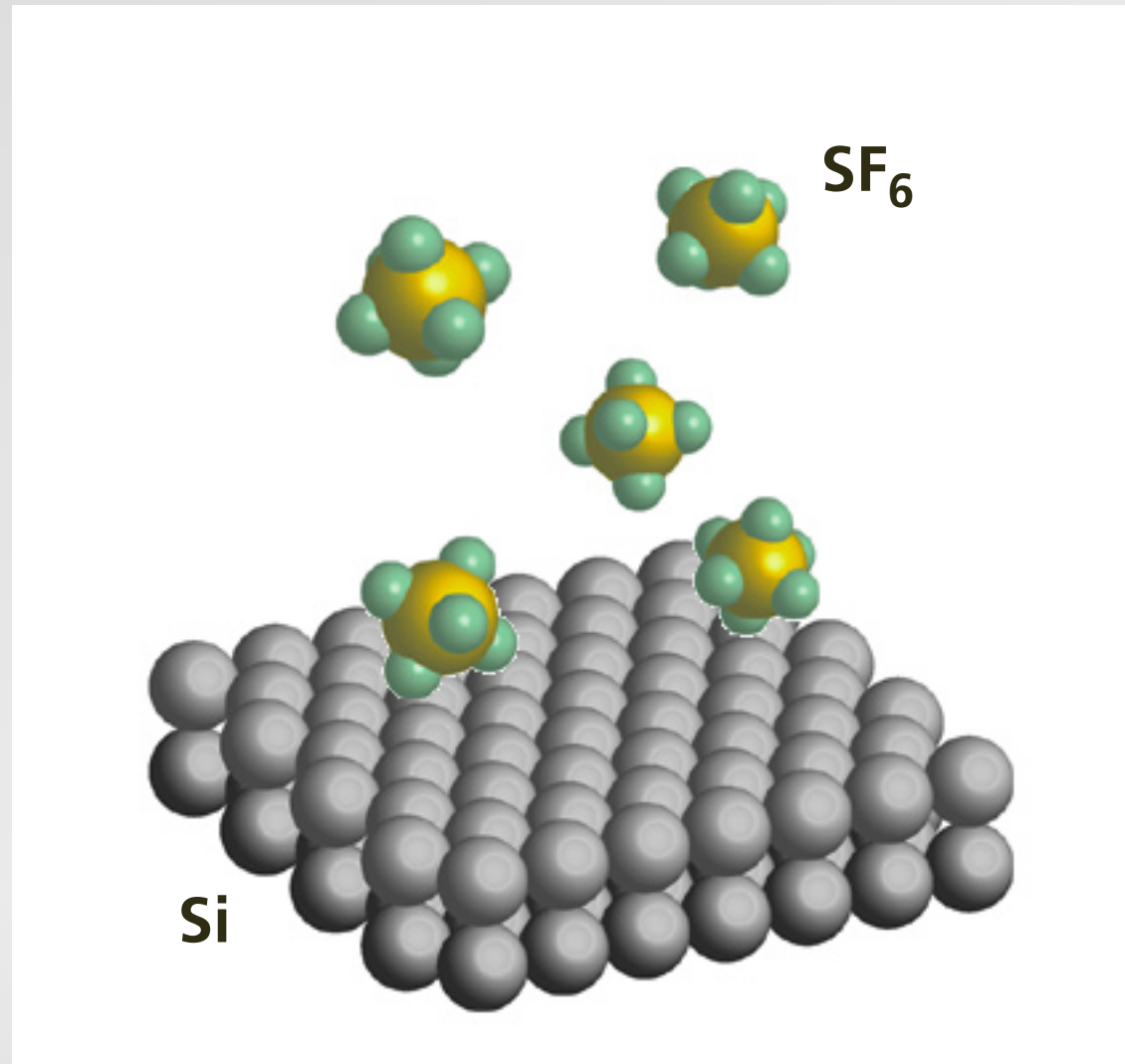
add aluminum contacts

Outline

- doped semiconductors
- pn-junctions
- black silicon

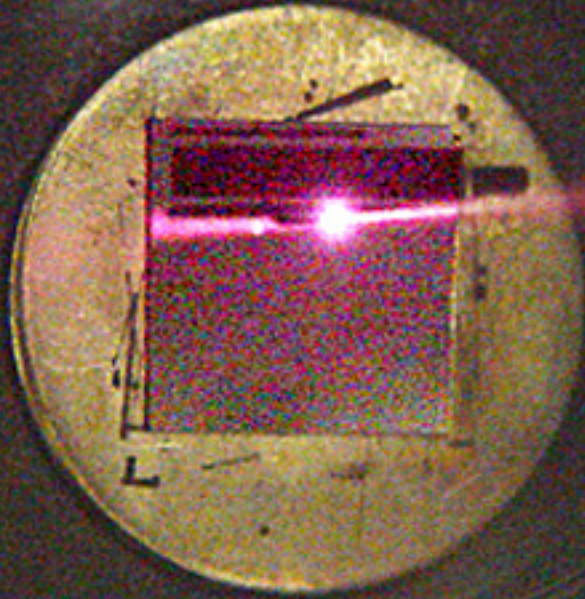


Black silicon

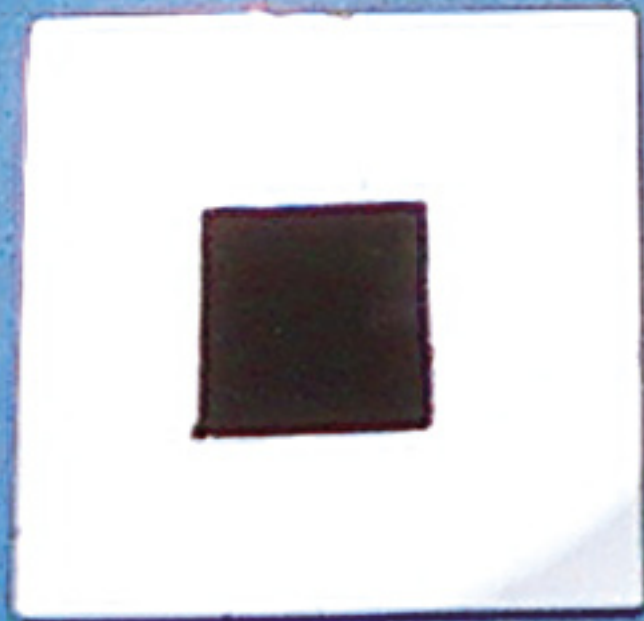


irradiate with 100-fs 10 kJ/m² pulses

Black silicon



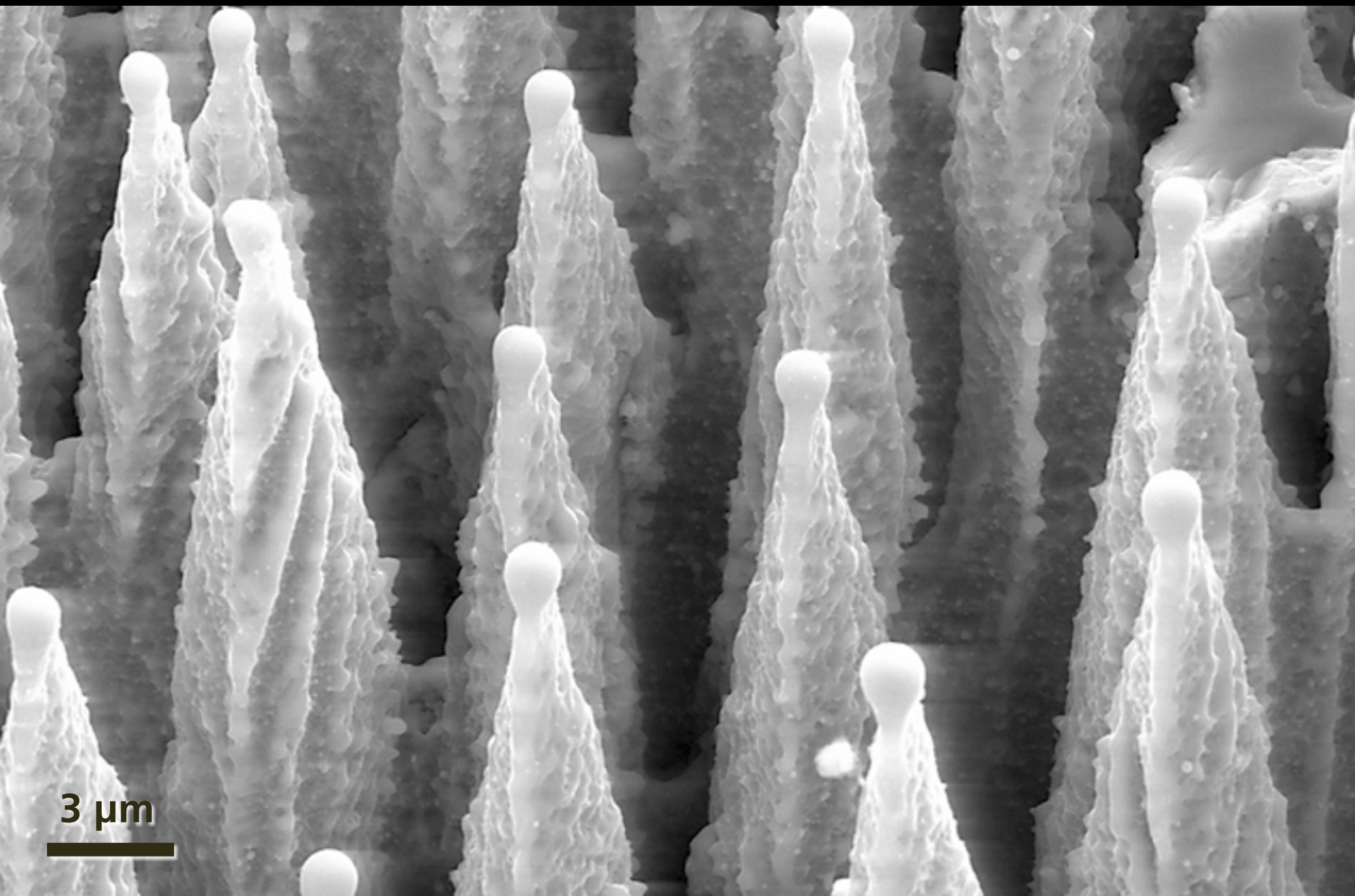
Black silicon



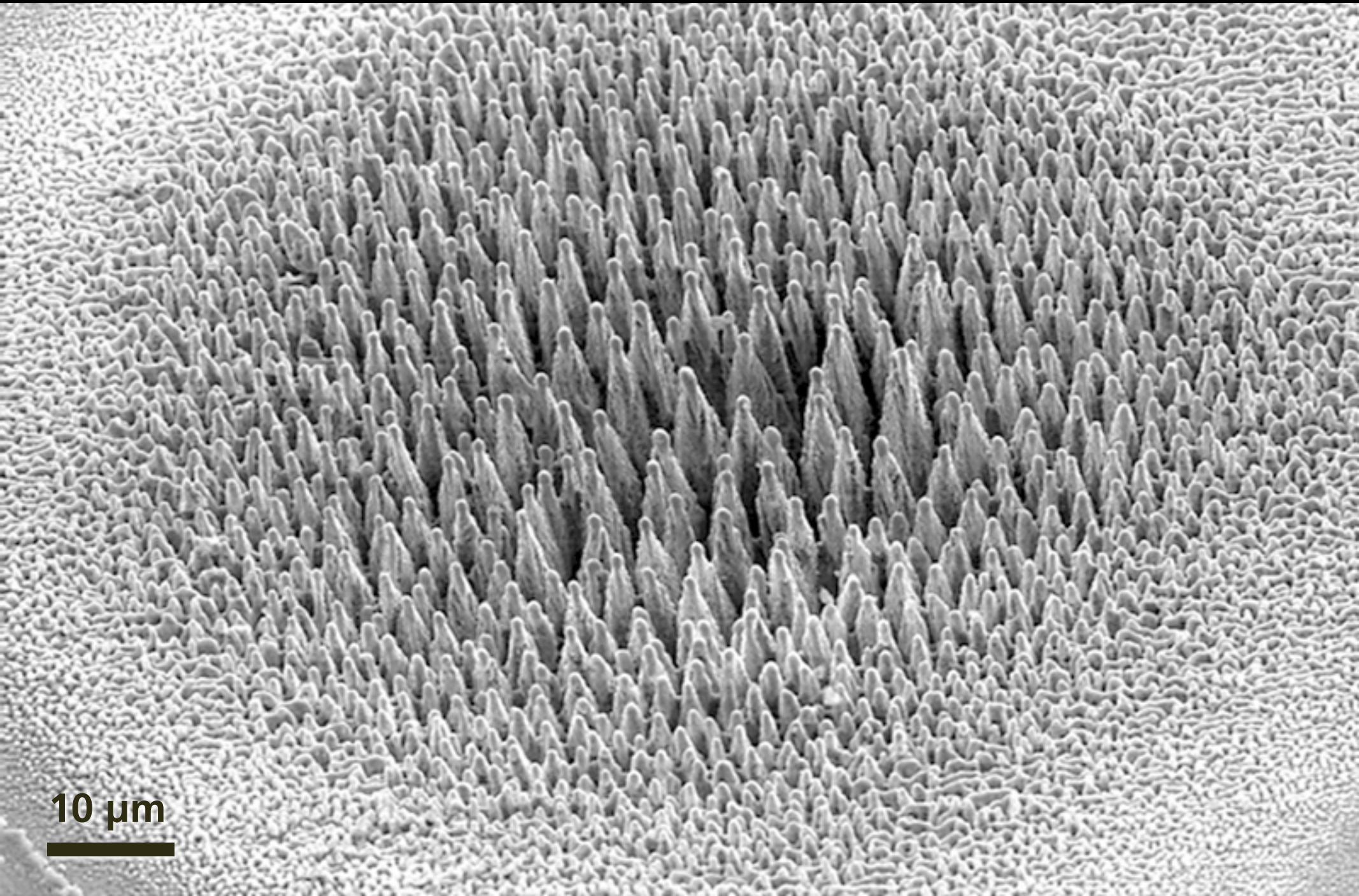
“black silicon”



Black silicon

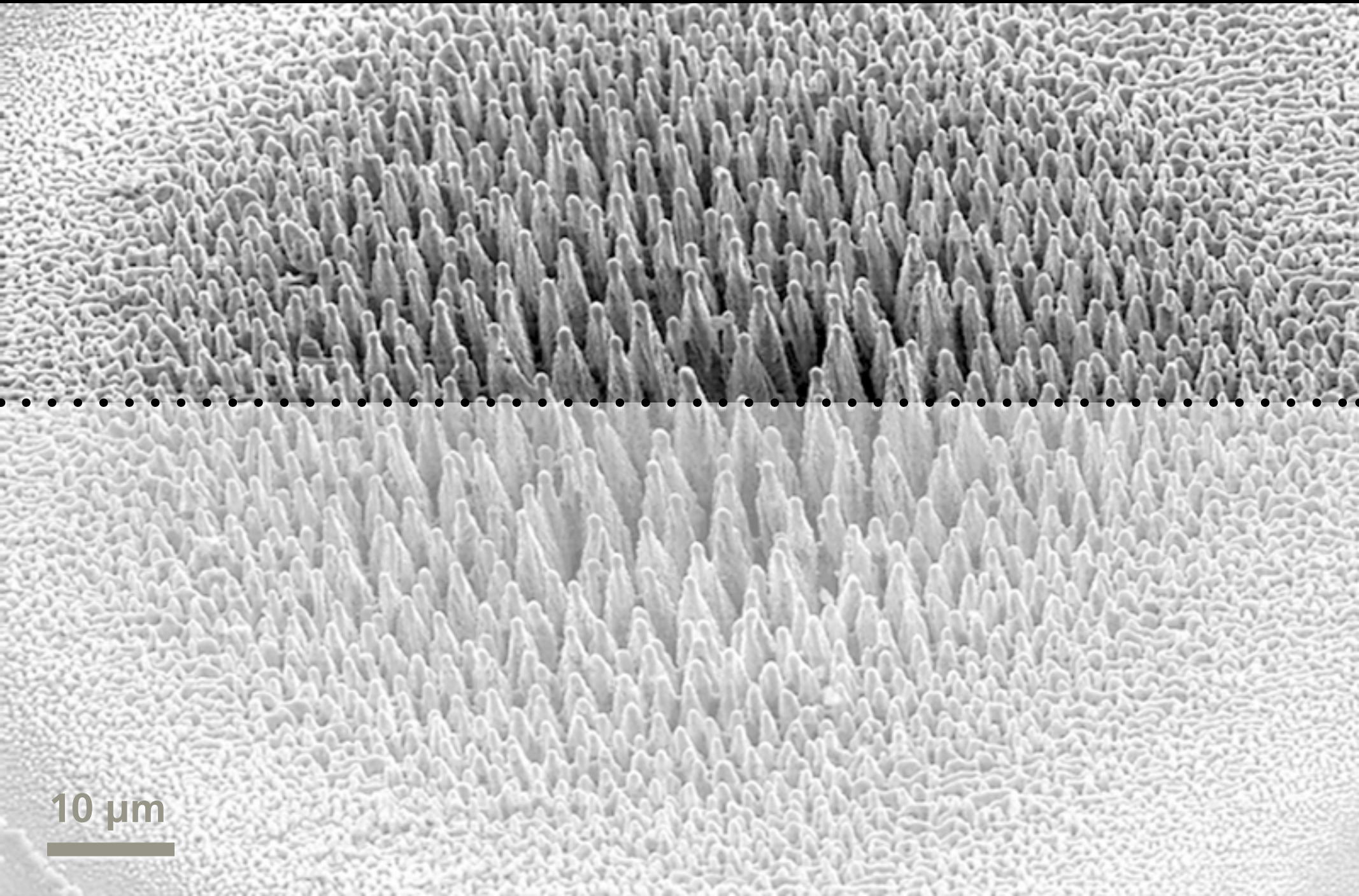


Black silicon



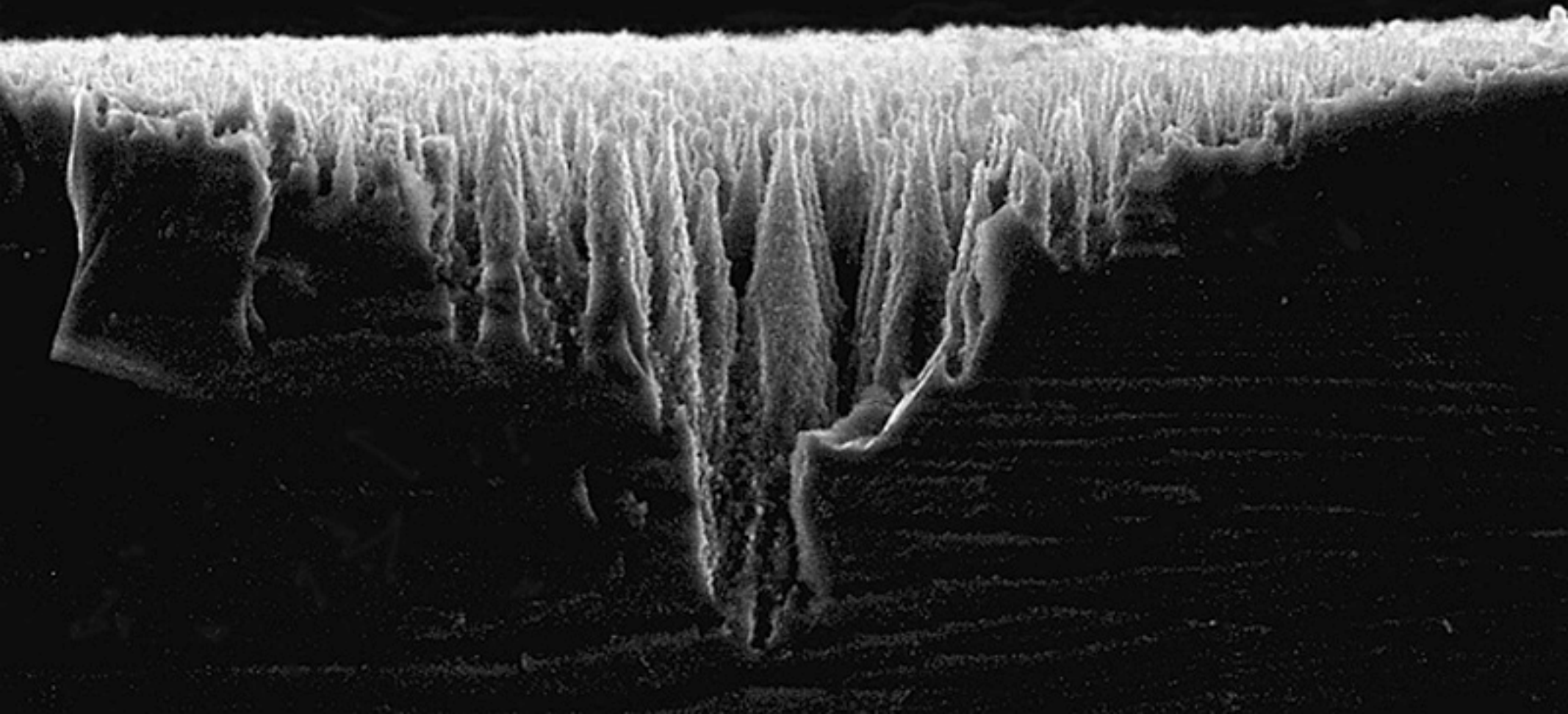
10 μm

Black silicon

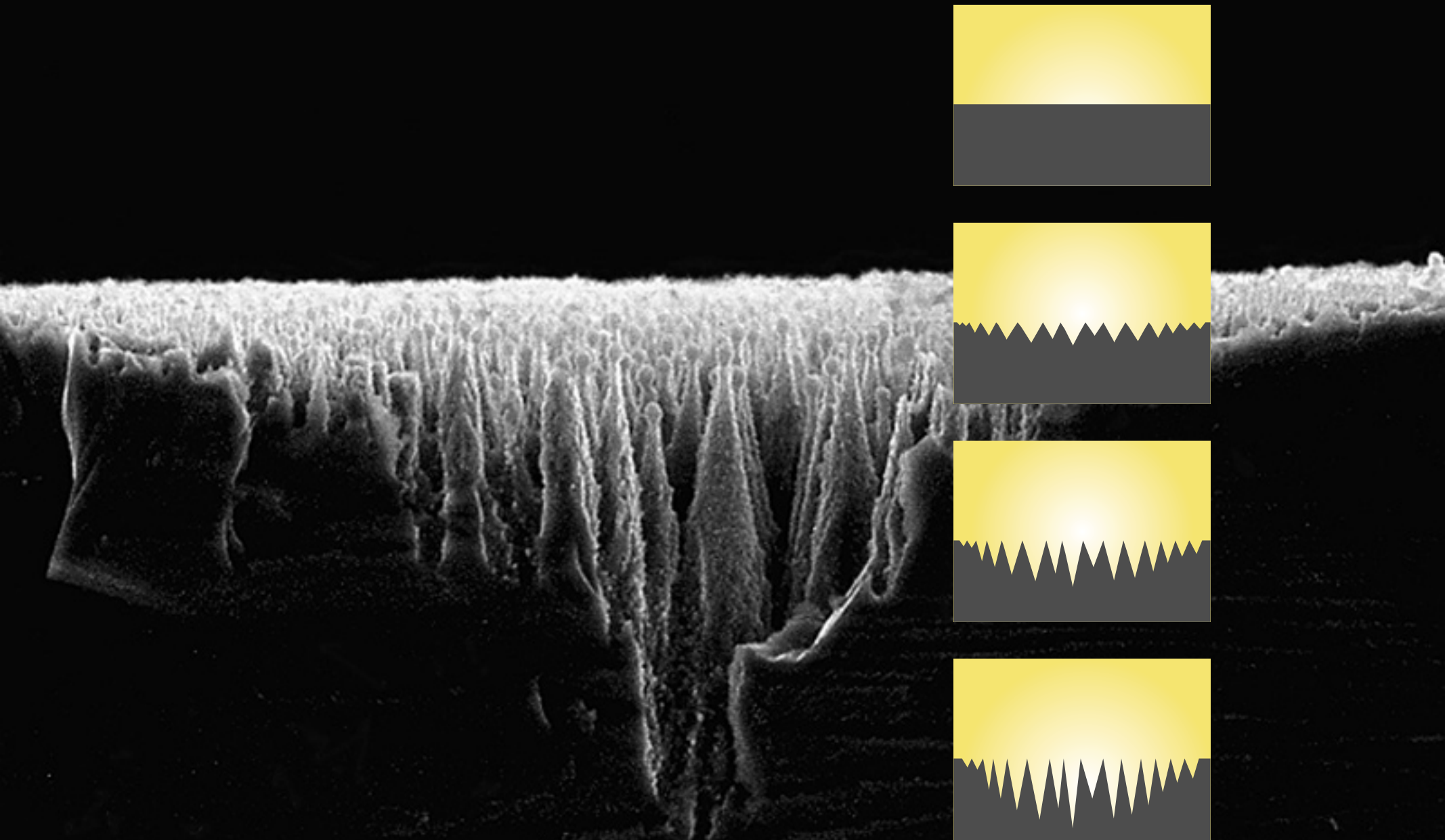


10 μm

Black silicon

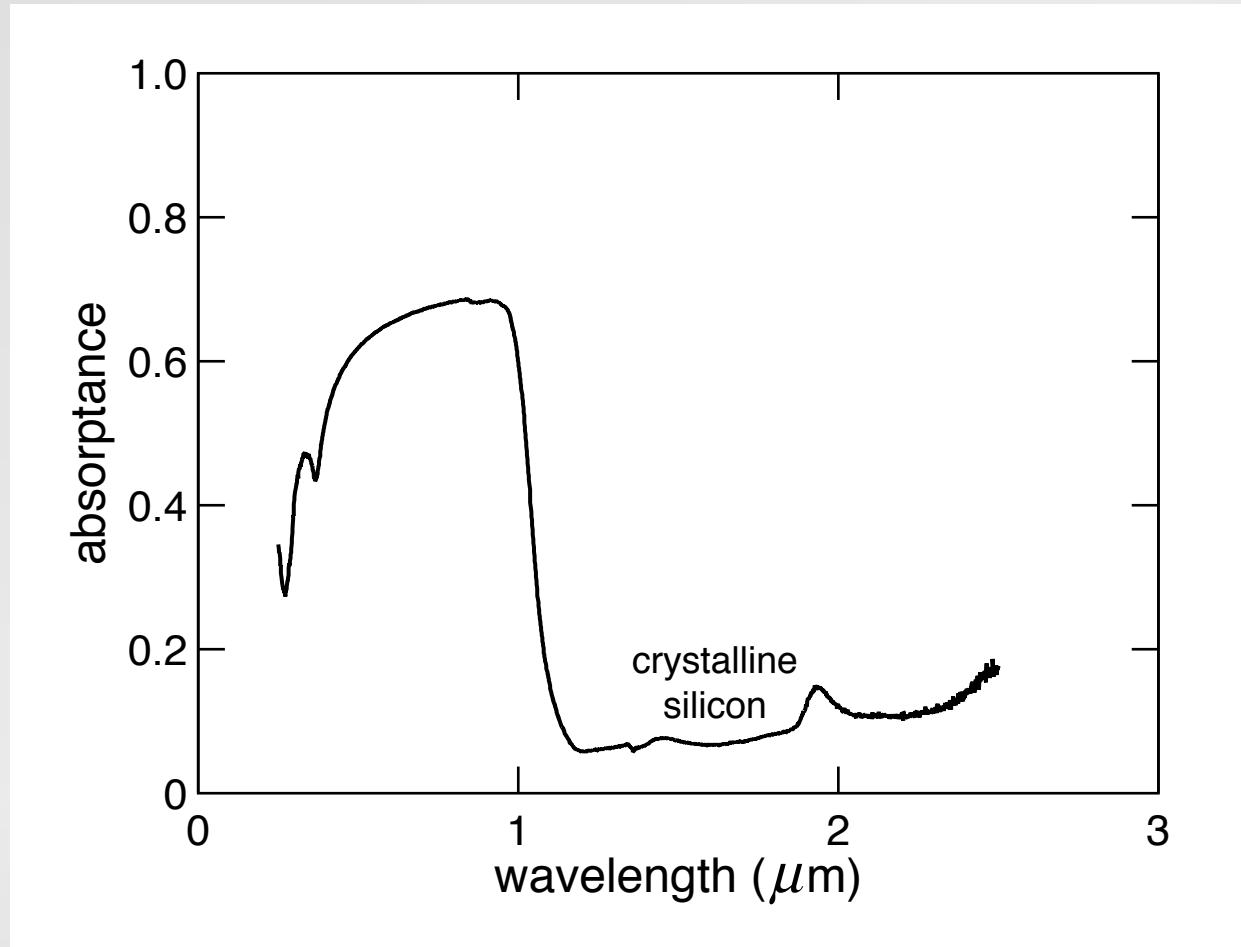


Black silicon



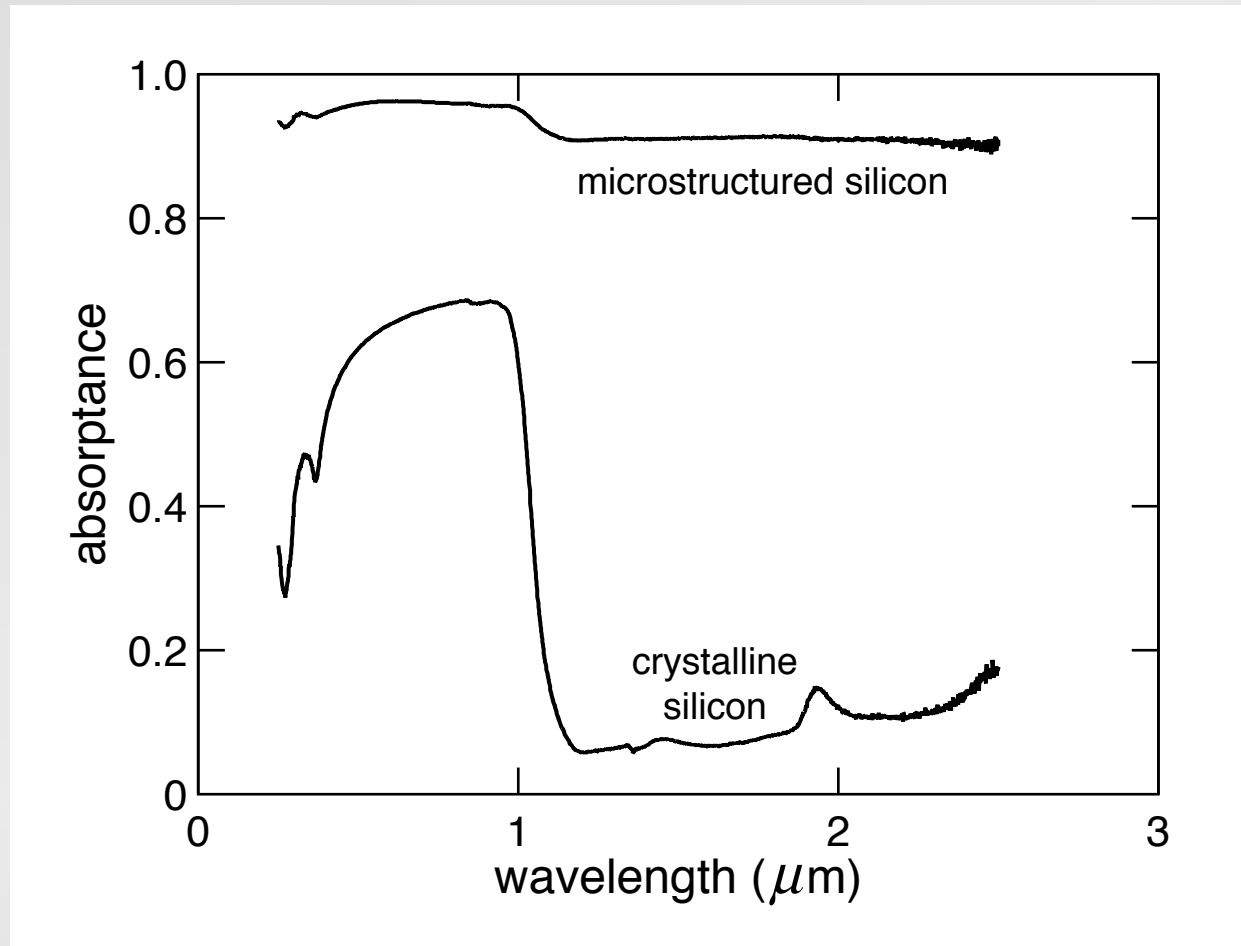
Black silicon

absorptance



Black silicon

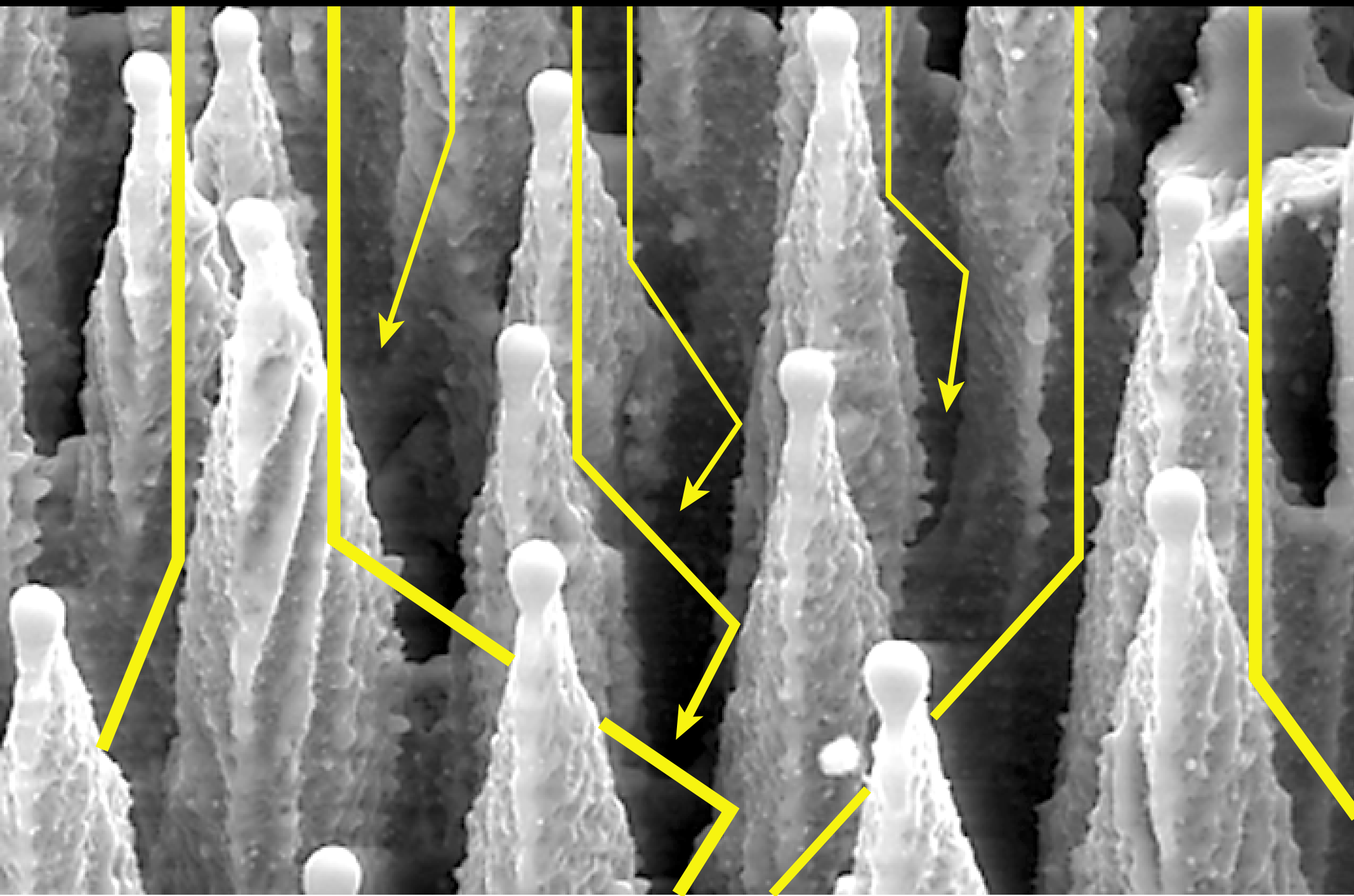
absorptance



Black silicon

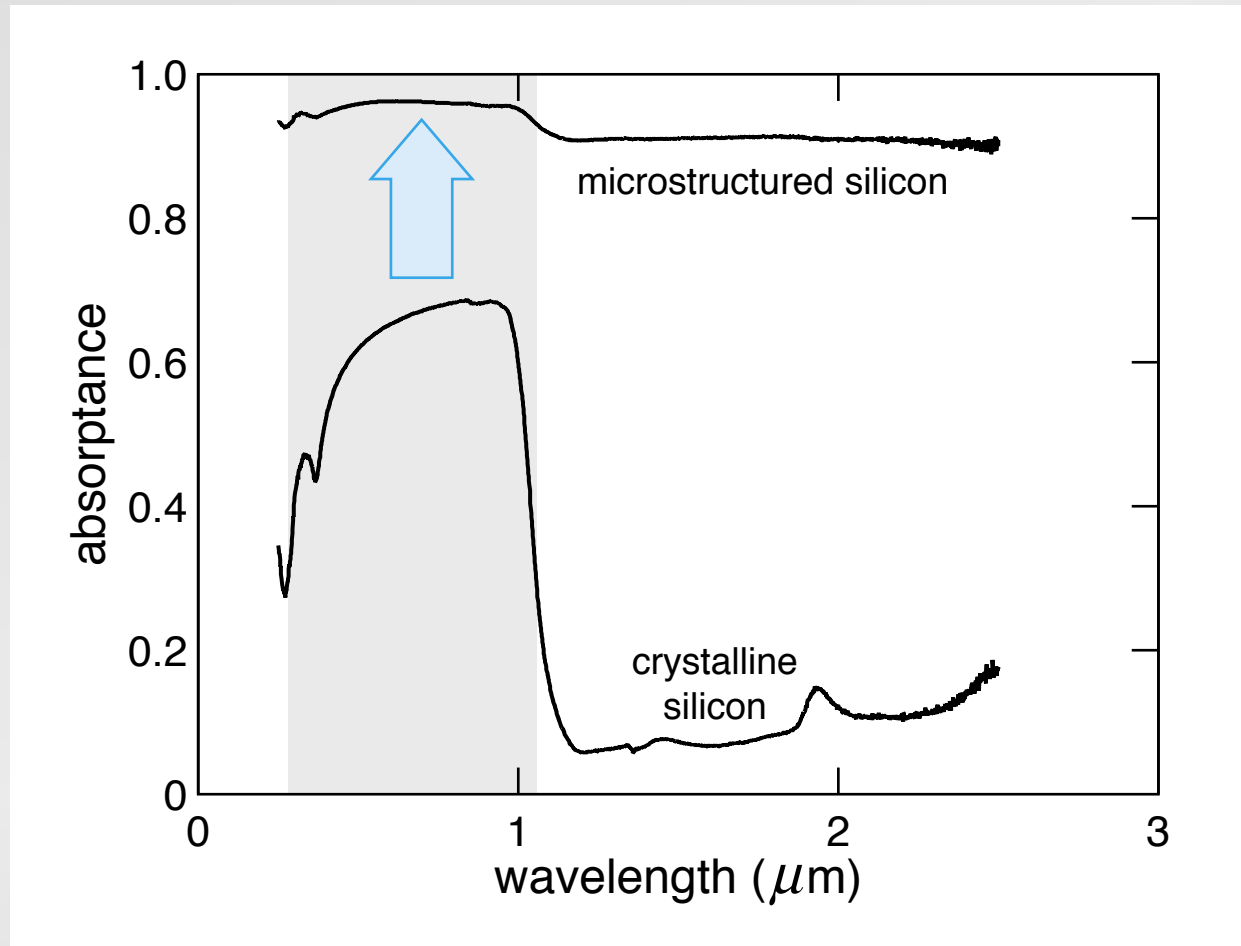
What causes the near-unity absorptance?

Black silicon



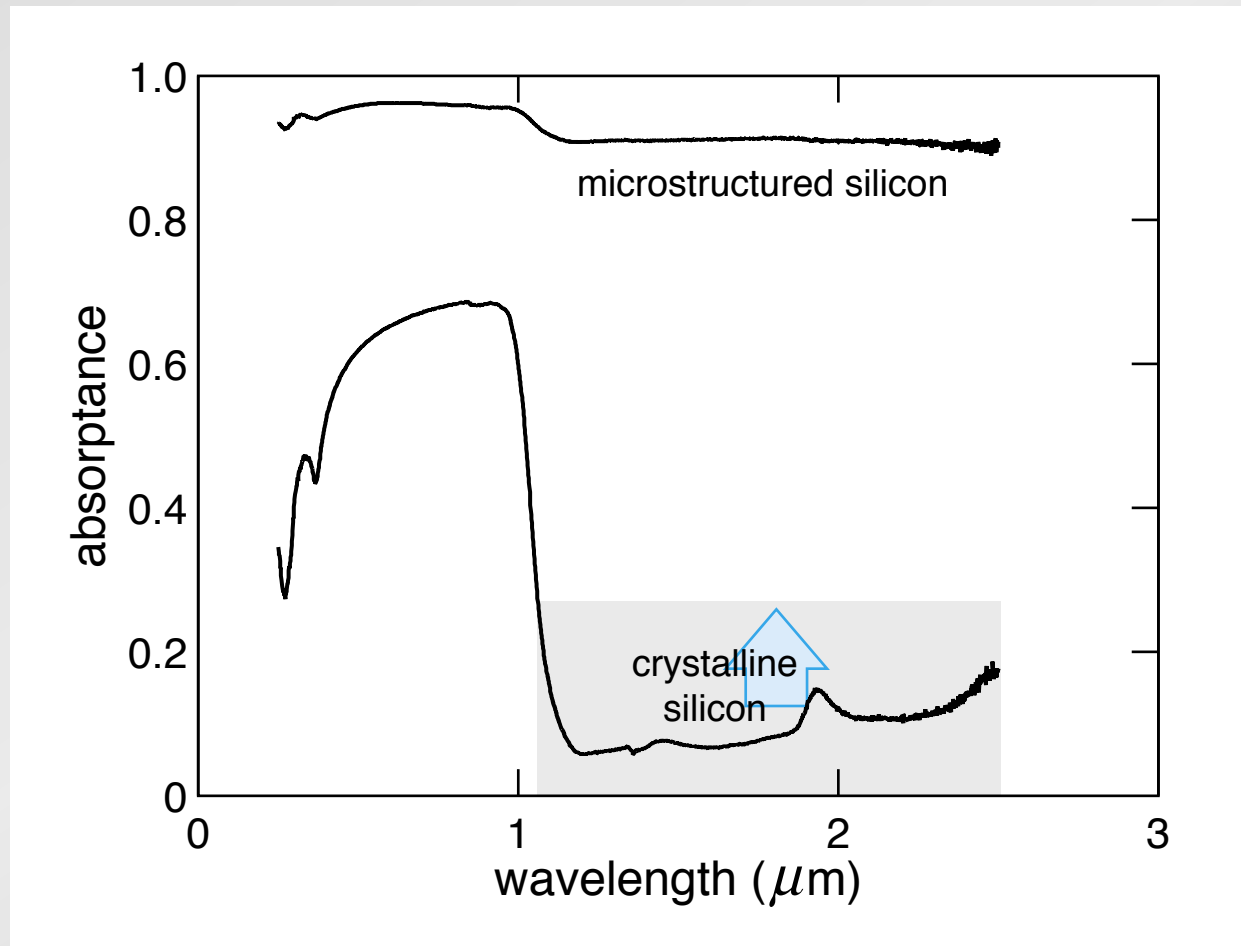
Black silicon

multiple reflections enhance absorption



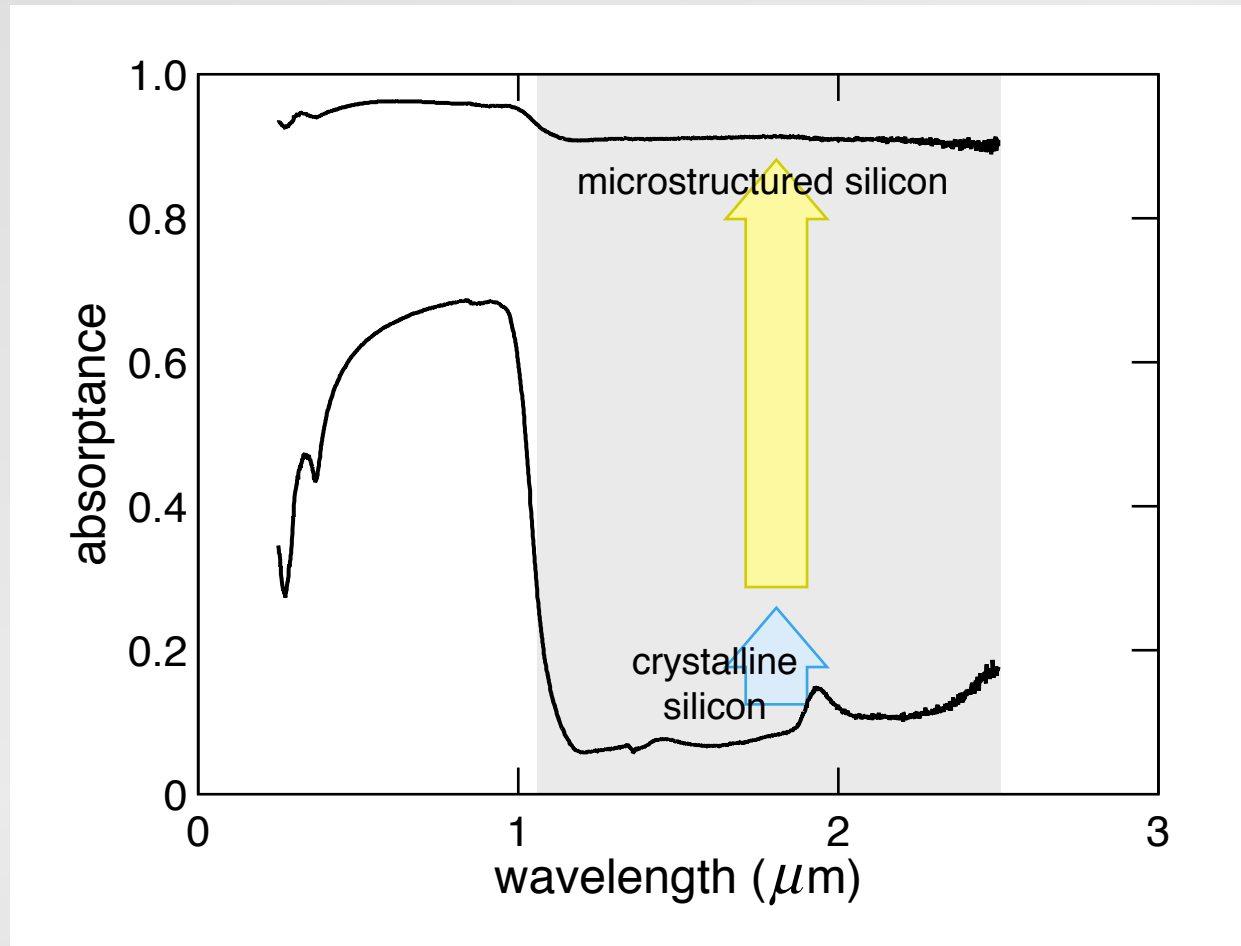
Black silicon

multiple reflections enhance absorption

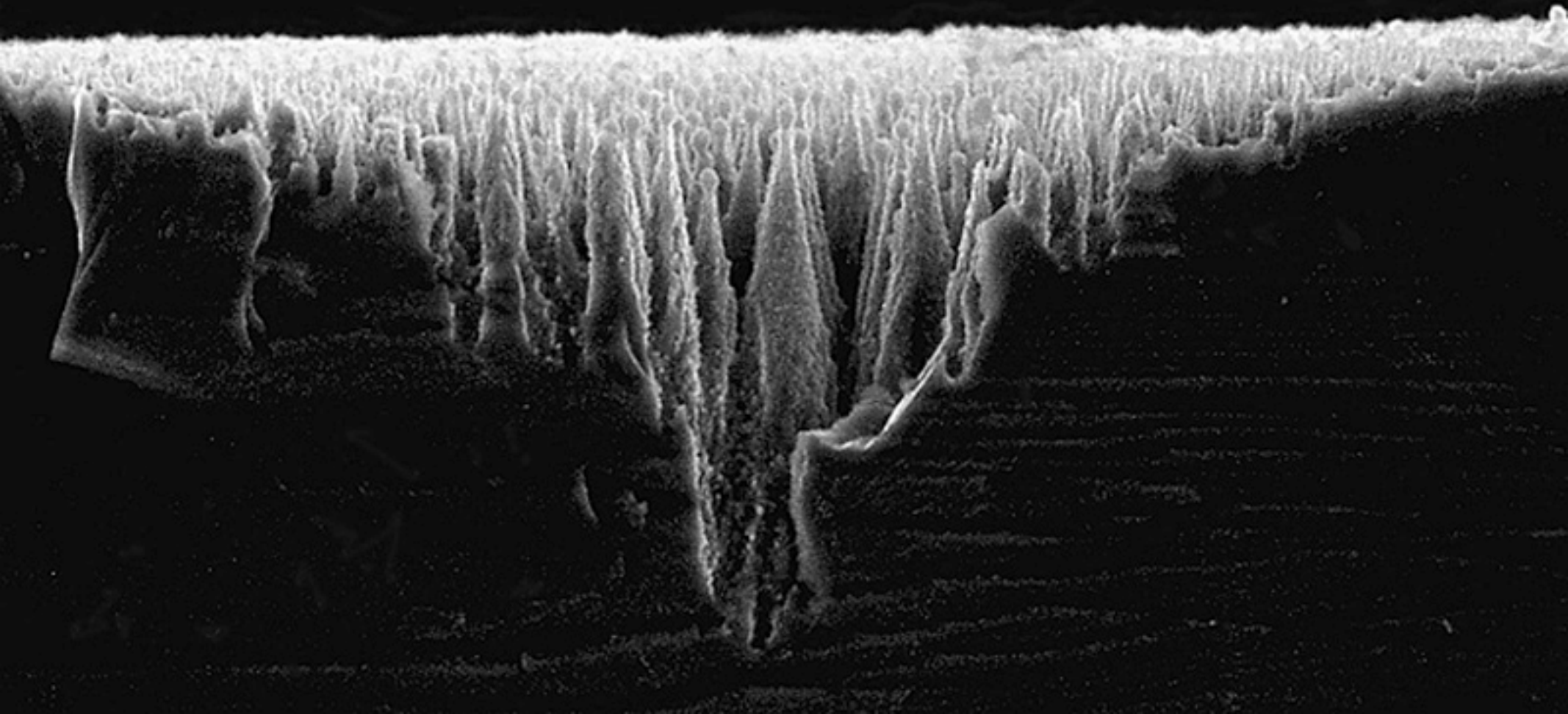


Black silicon

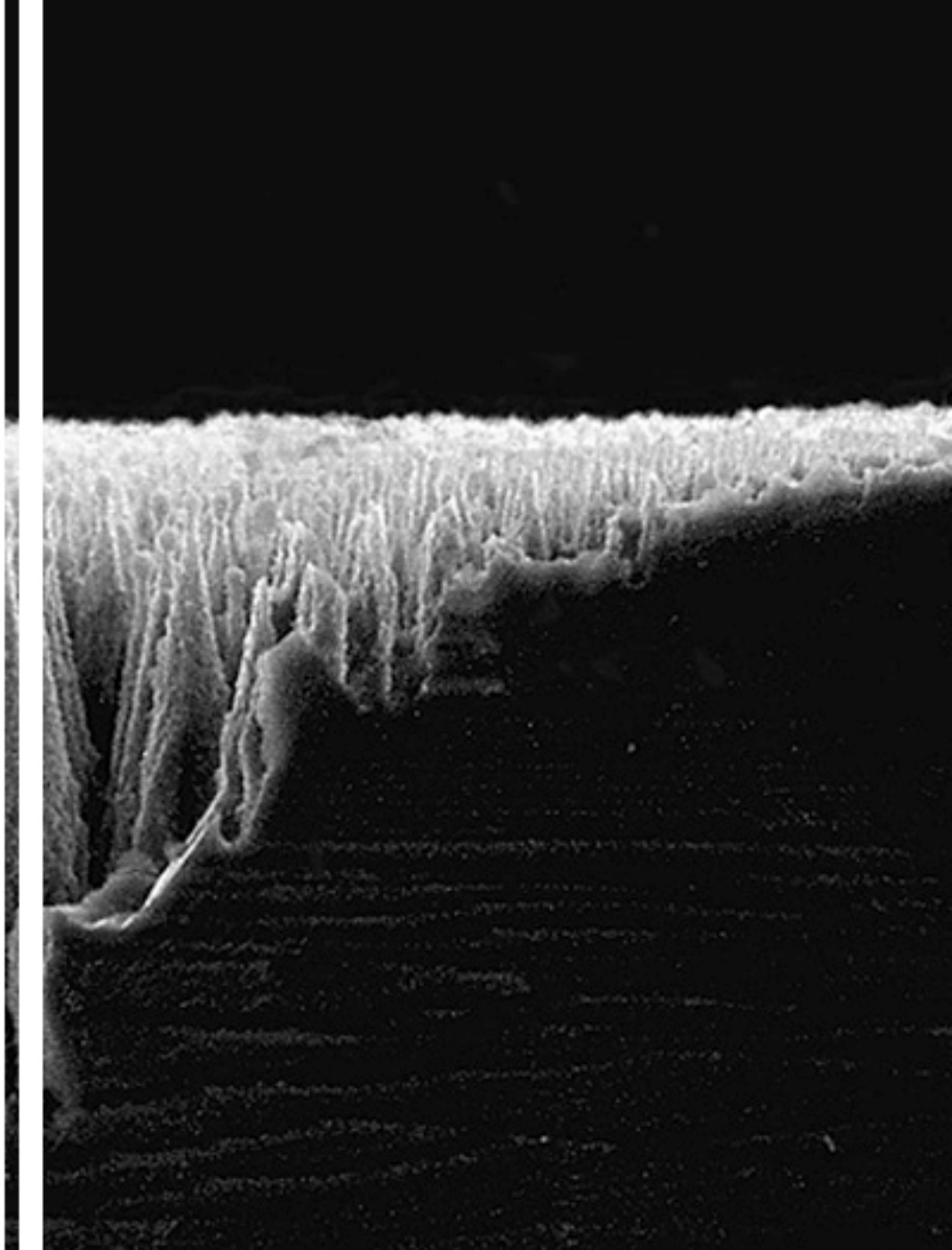
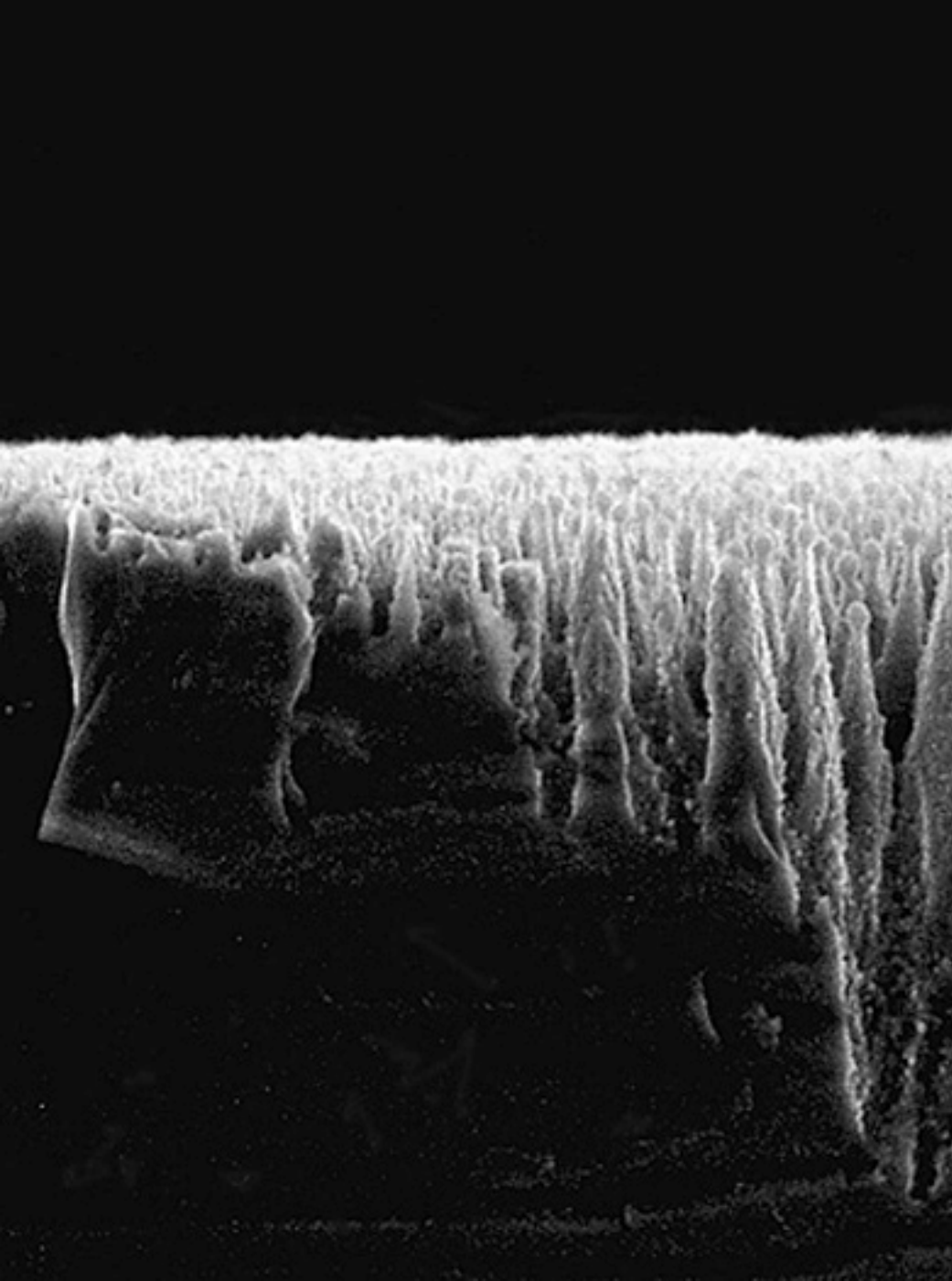
heavy sulfur doping causes infrared absorption



Black silicon

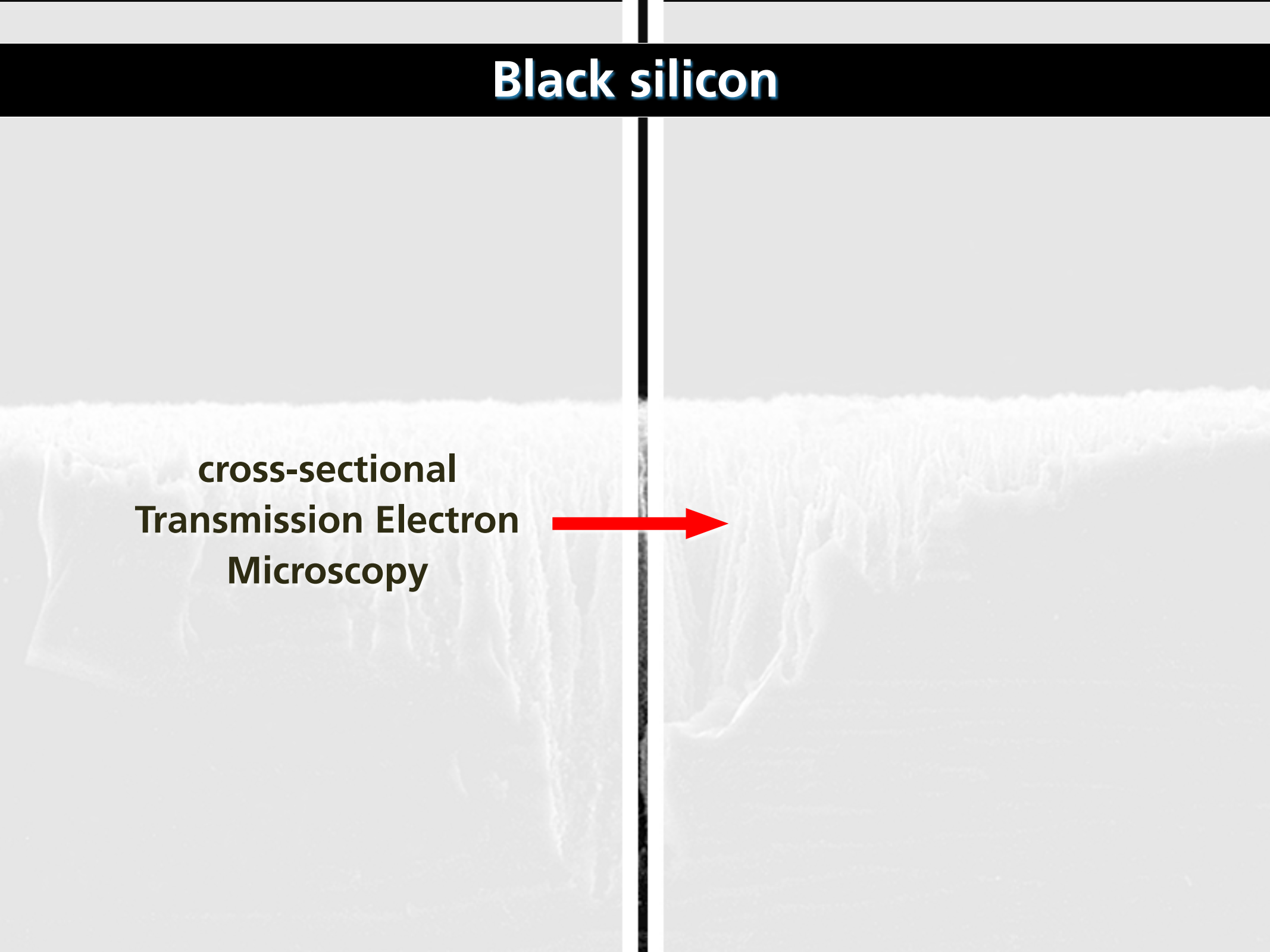


Black silicon



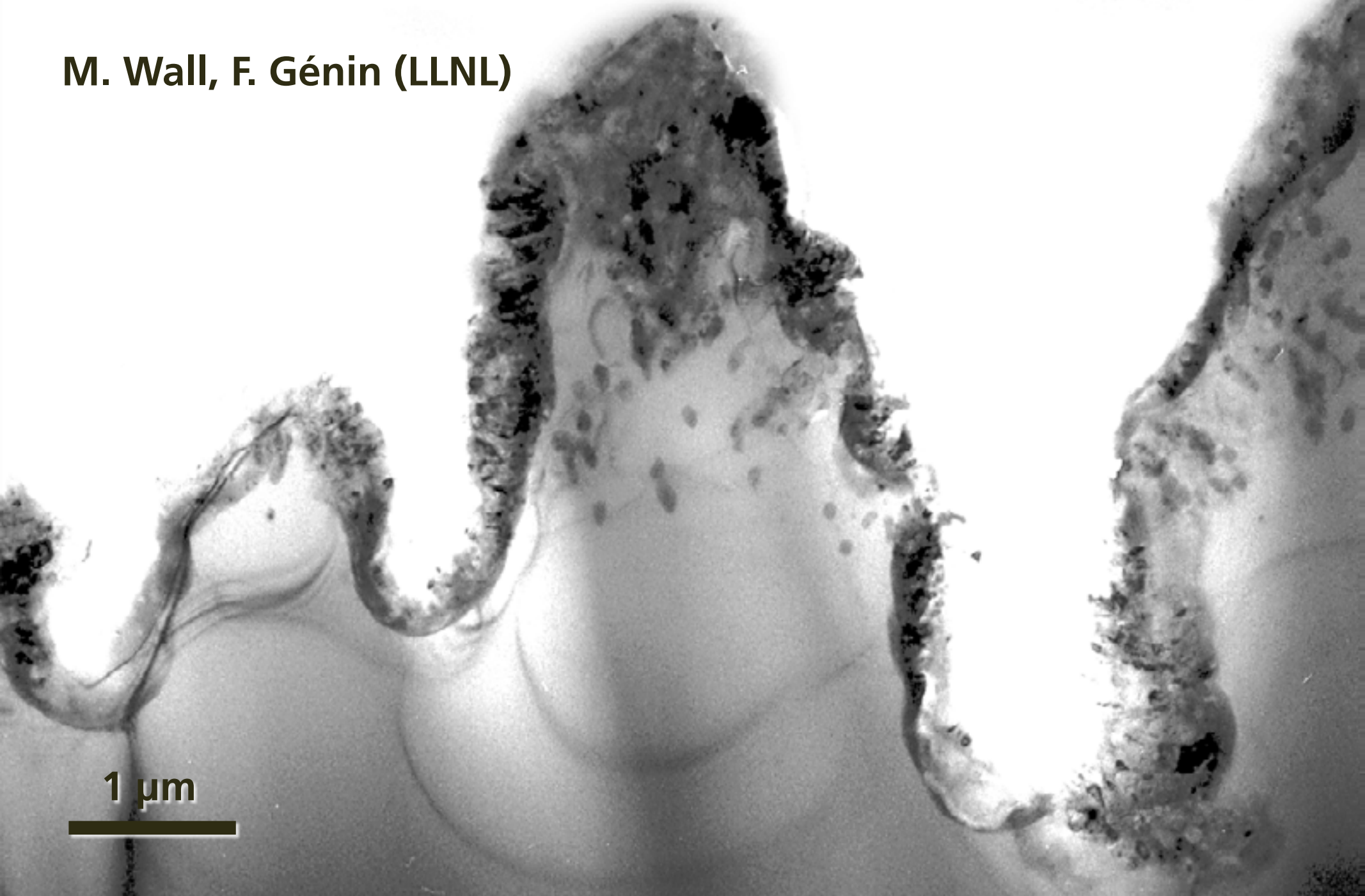
Black silicon

**cross-sectional
Transmission Electron
Microscopy**



Black silicon

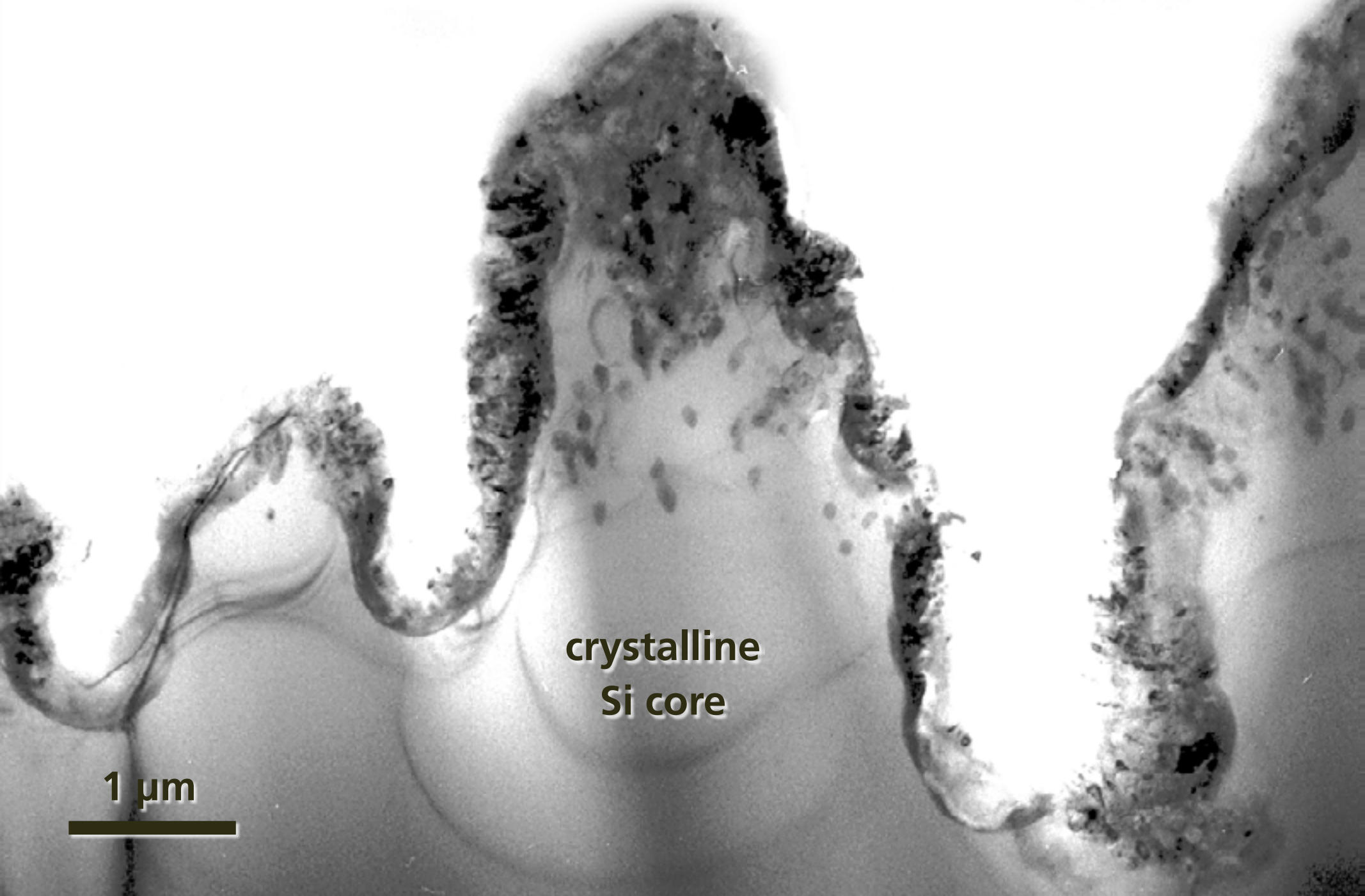
M. Wall, F. Génin (LLNL)



1 μm



Black silicon

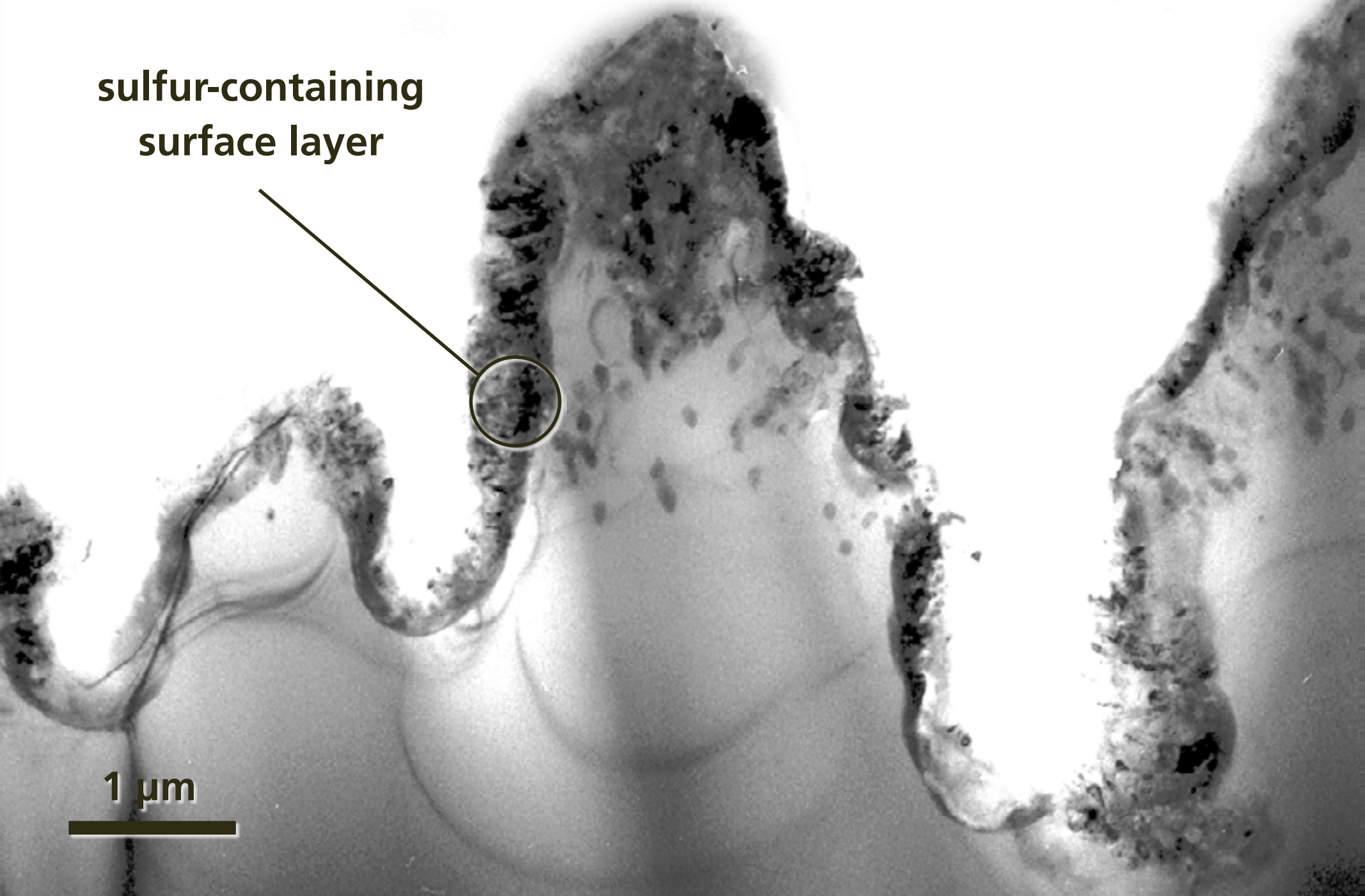


crystalline
Si core

1 μm

Black silicon

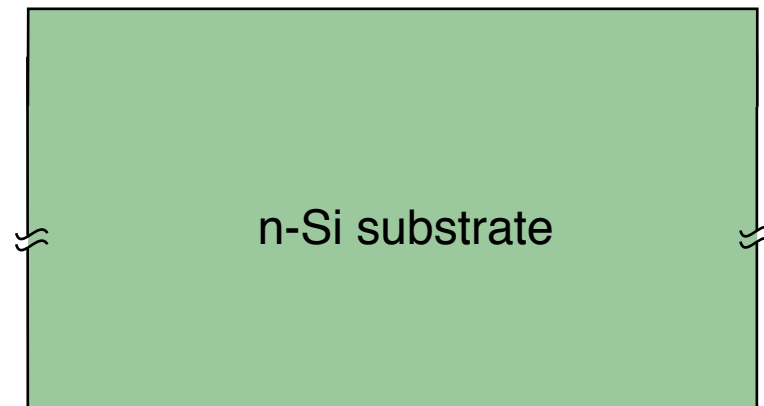
sulfur-containing
surface layer



1 μm

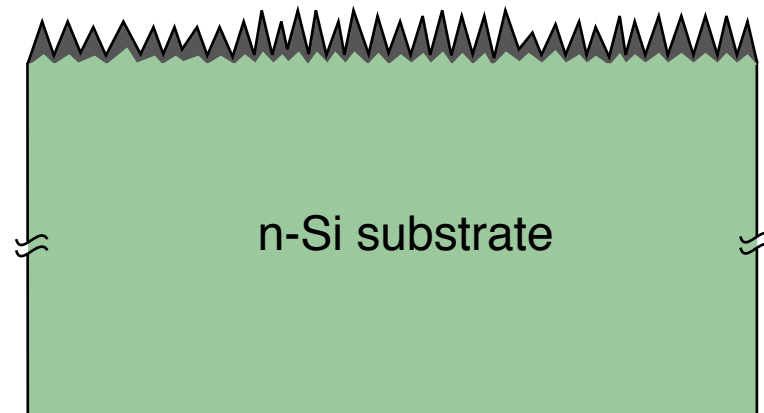
Black silicon

black silicon/n-type silicon junction



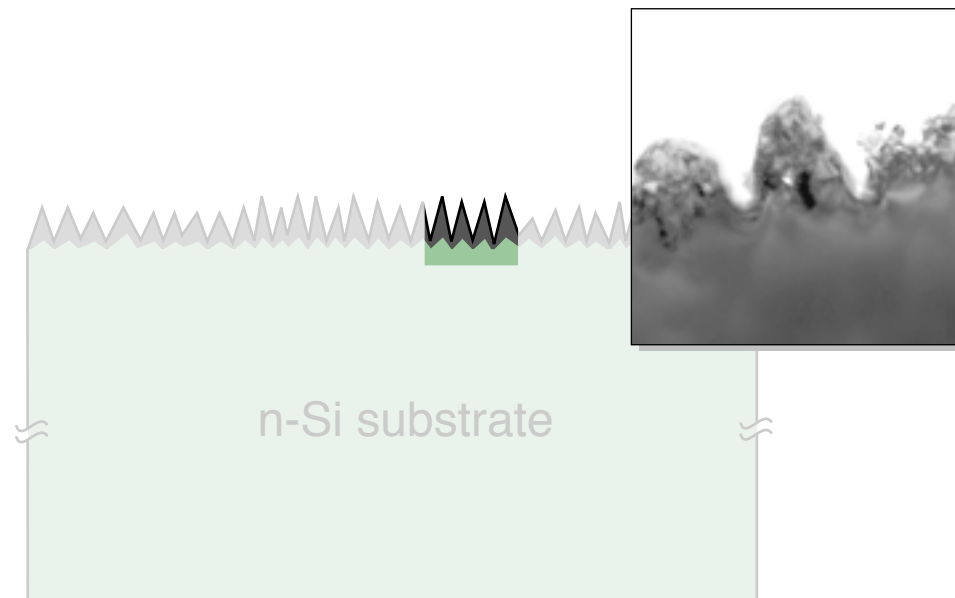
Black silicon

black silicon/n-type silicon junction



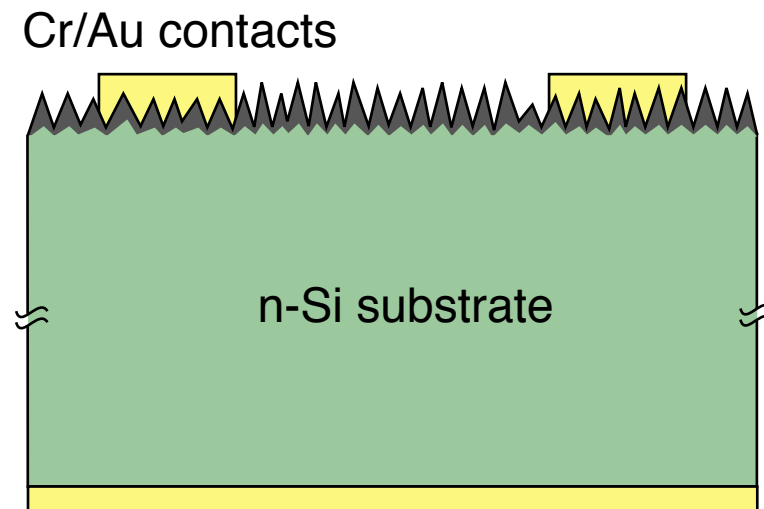
Black silicon

black silicon/n-type silicon junction



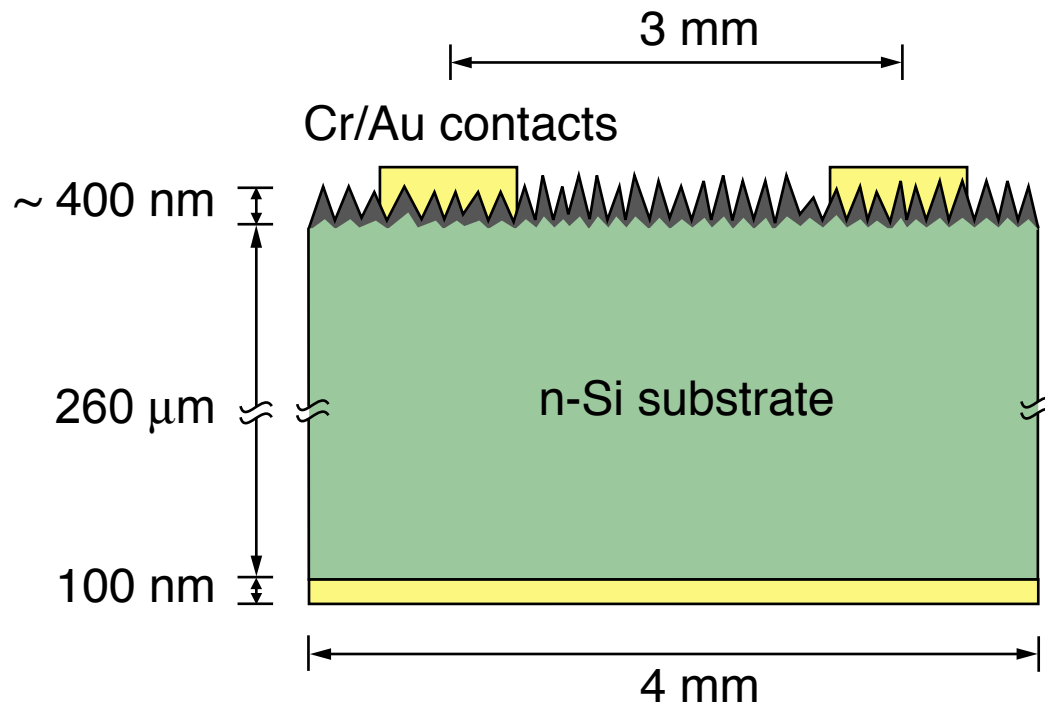
Black silicon

black silicon/n-type silicon junction



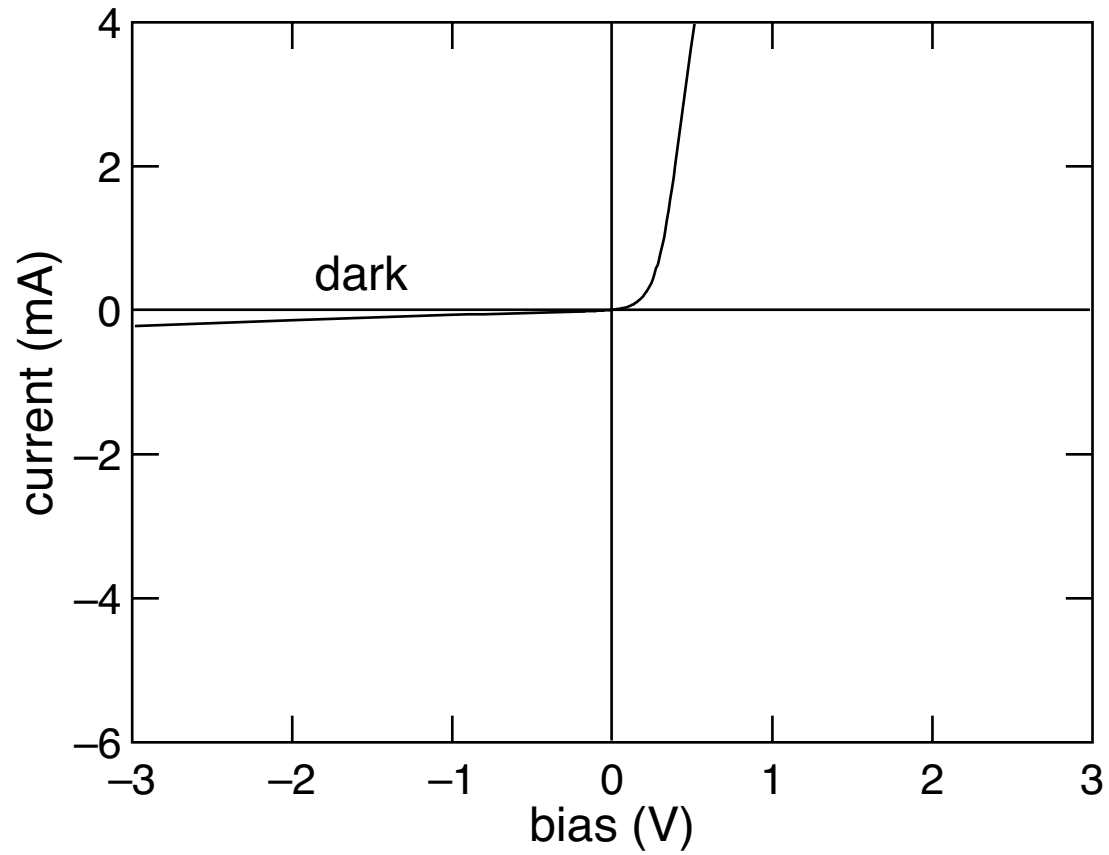
Black silicon

black silicon/n-type silicon junction



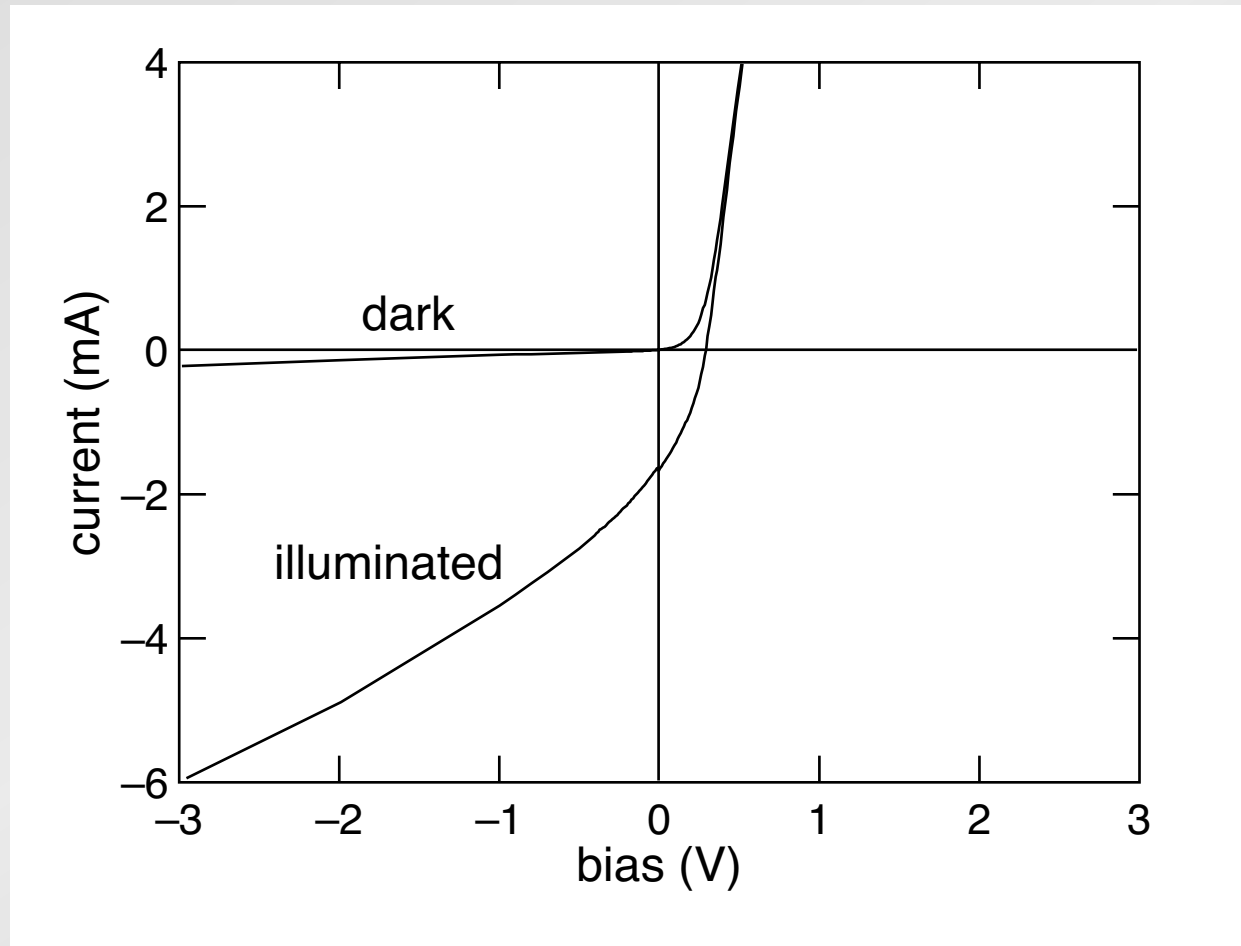
Black silicon

I/*V* characteristics



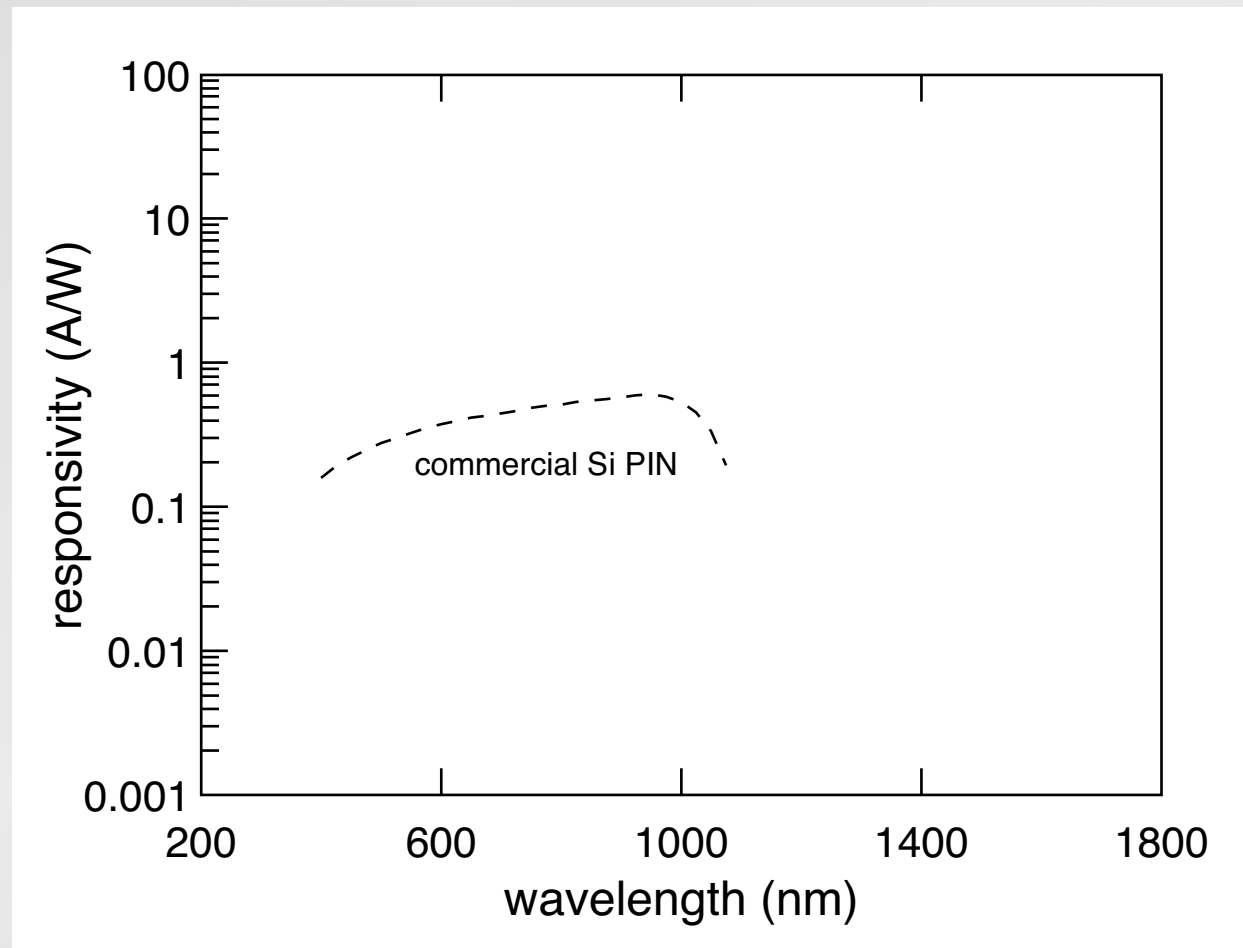
Black silicon

I/*V* characteristics



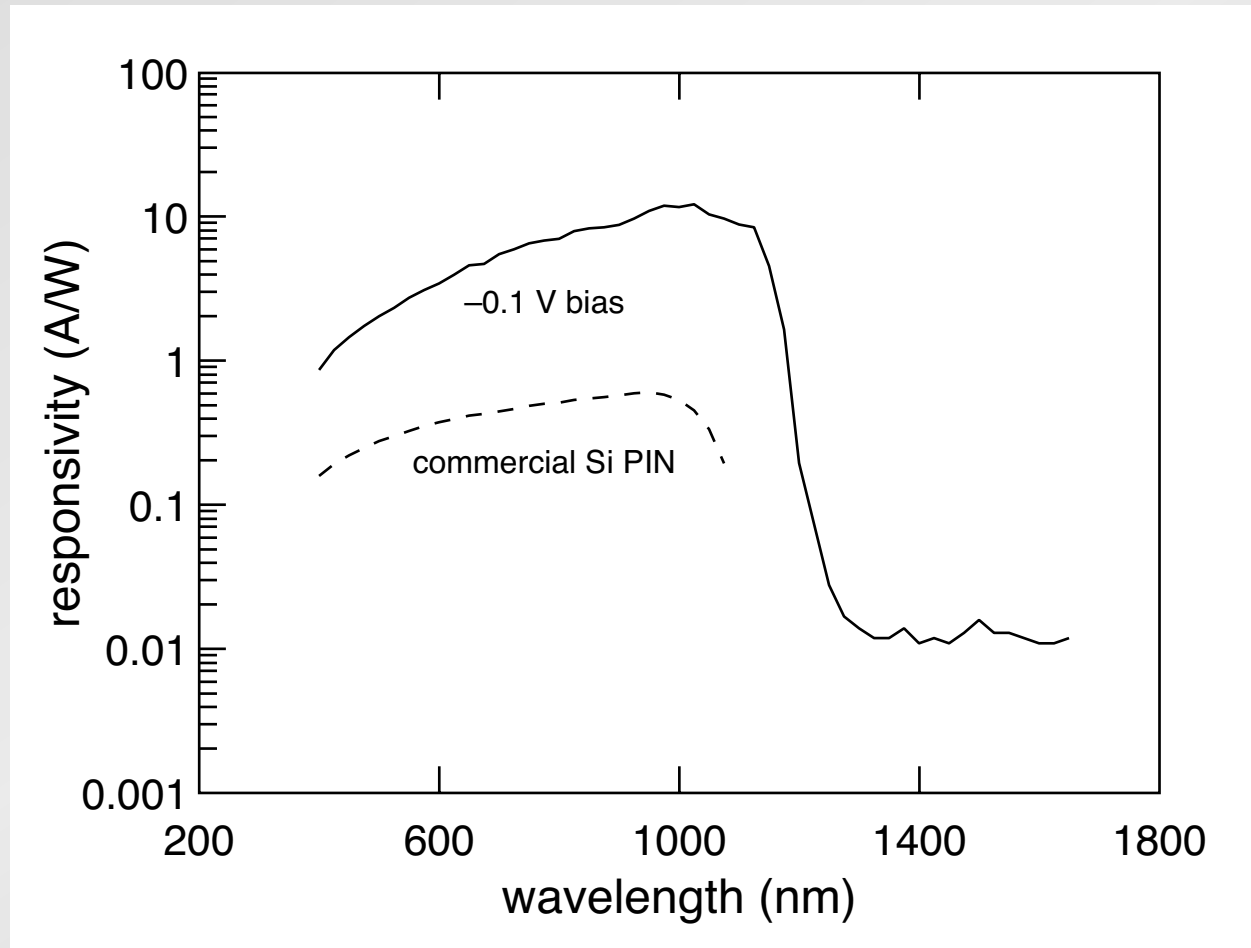
Black silicon

responsivity



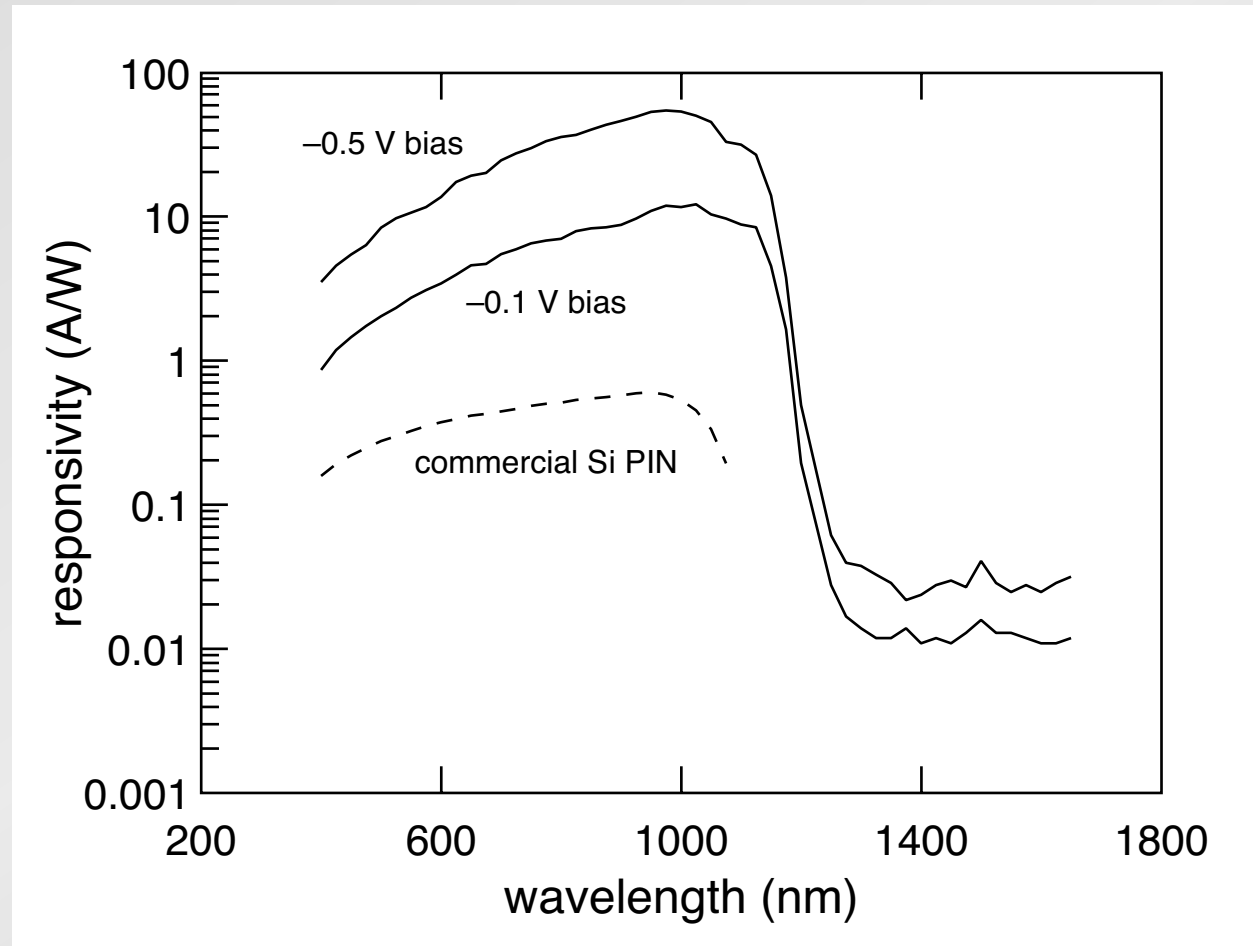
Black silicon

responsivity



Black silicon

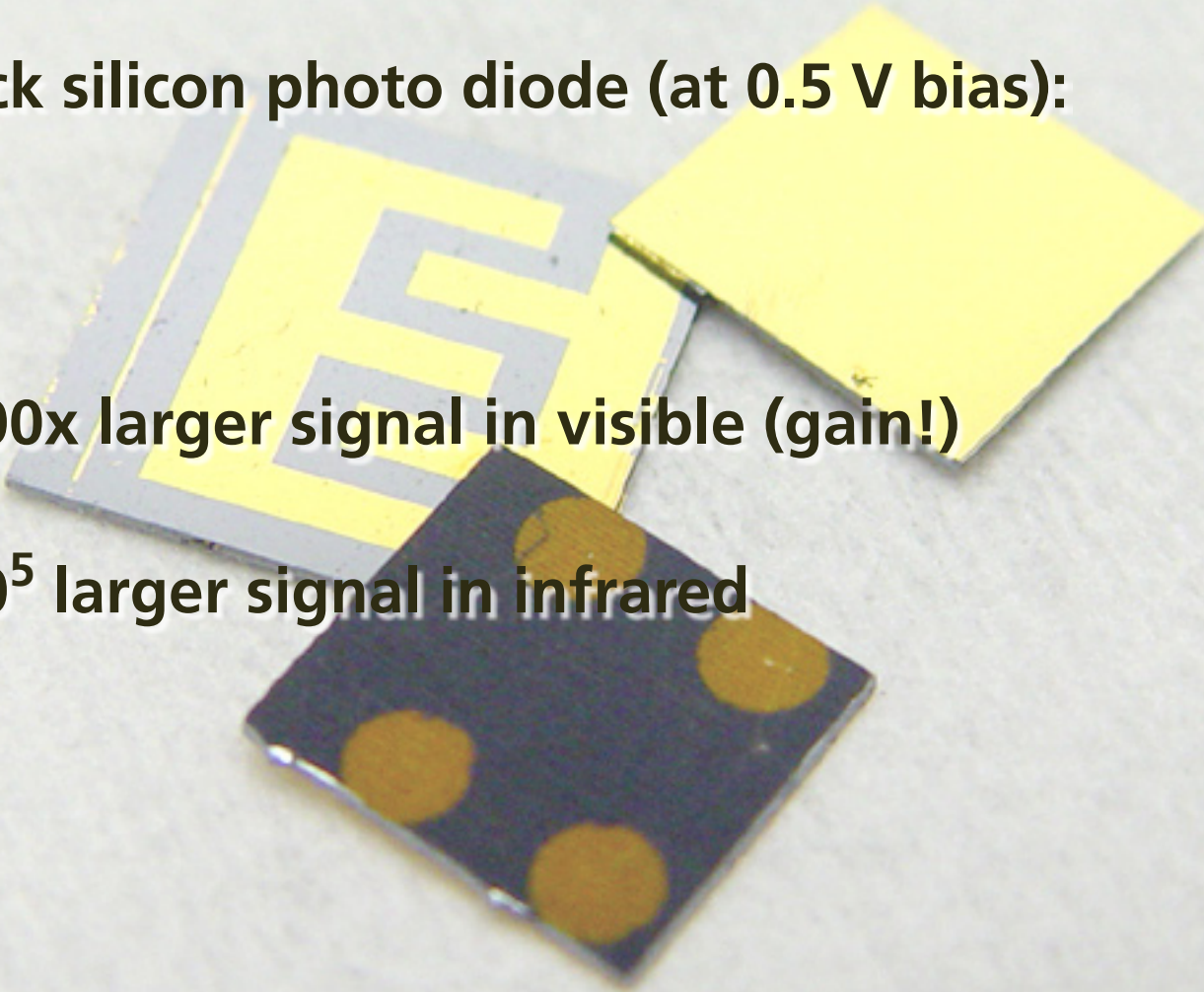
responsivity



Black silicon

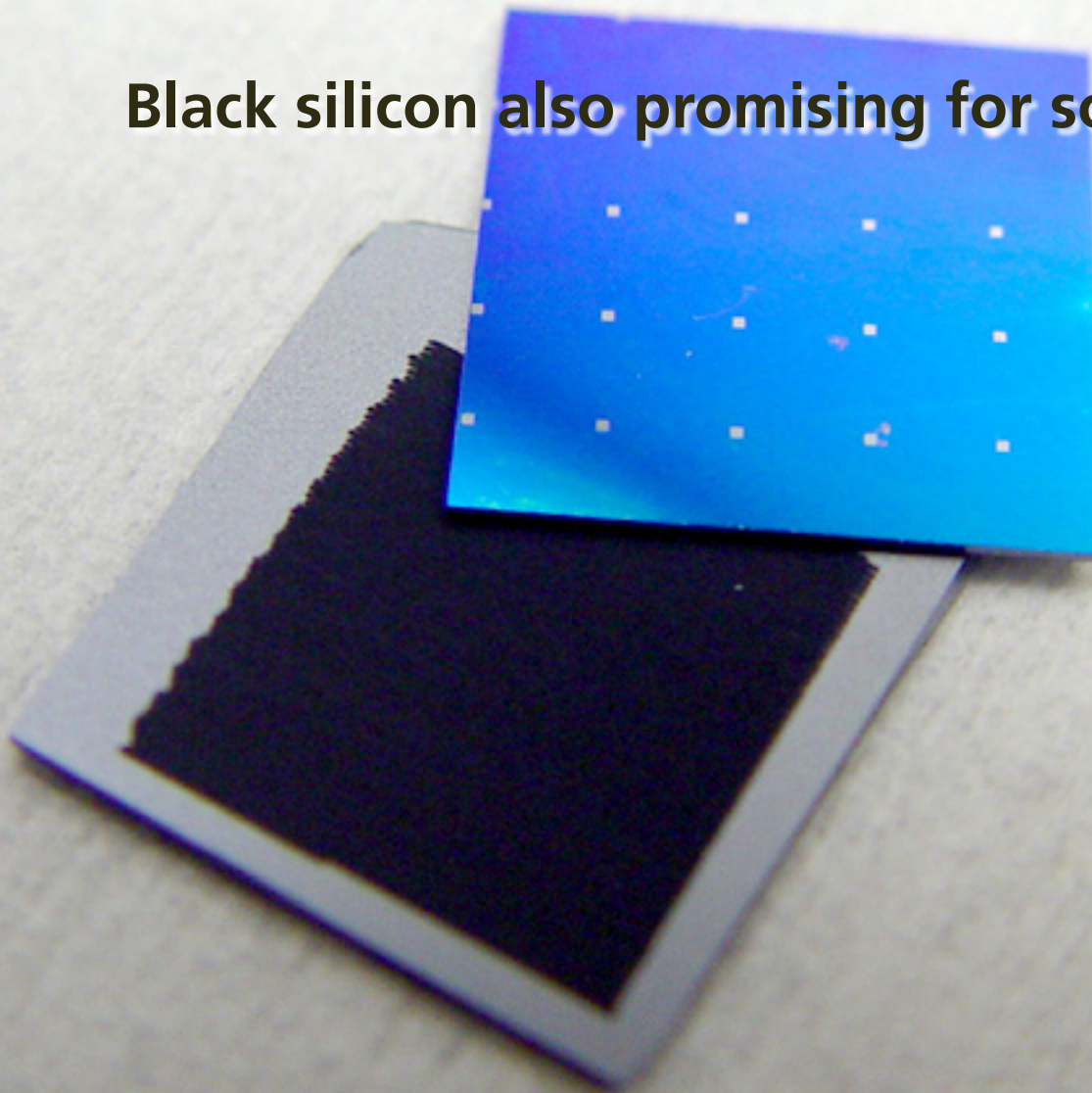
Black silicon photo diode (at 0.5 V bias):

- **100x larger signal in visible (gain!)**
- **10^5 larger signal in infrared**



Black silicon

Black silicon also promising for solar cells



Black silicon

A forest of silicon spikes could revolutionise solar cells and give you painless injections. **Bruce Schechter** peers into the mysterious world of black silicon

TALL, DARK AND STRANGER

WE ALL love stories of serendipity. They seem to hark back to a time when a fogged photographic plate or a filthy Petri dish could change the world. Even today, when financial constraints keep the role of chance to a minimum, science is still sometimes a spontaneous act, a freelance exploration of the unknown. It often starts in front of a blackboard when one scientist says, "I wonder what would happen if . . .", and the other one replies, "Let's give it a try."

The result of one such conversation two years ago in Eric Mazur's laboratory at Harvard University is a new form of silicon. It is a soot. What started life as a speck of silicon now has patents

semiconductors with a powerful laser. In the early 1990s, Mazur's was the first academic lab in the world to get its hands on a femtosecond laser. This device produces pulses of light that are hundreds of billions of times brighter than the Sun. Its immense power is delivered extremely quickly: each pulse lasts a mere fraction of a trillionth of a second.

These flashes of laser light have provided researchers with a new way to probe the characteristics of many materials (*New Scientist*, 19 February 2000, p 34). Mazur's group was using the powerful femtosecond pulses to study the surface chemistry of metals. But Her, who is now at the Lawrence Livermore Laboratory in California, had been wondering for years what could do to semiconductors like silicon. He tried it, so there

around the laboratory," he claims. Well, it was almost the only reason. A short laser pulse will break down SF_6 into sulphur and fluorine radicals, which will attack a silicon substrate. "Hydrogen fluoride is used to etch silicon. So we thought maybe the SF_6 would decompose and then the fluorine would somehow react with the silicon," Mazur explains. With no clearer idea than this, the researchers began firing 100-femtosecond pulses of laser light through the window of their chamber, through the SF_6 gas, about 100 pulses they cracked the seal of the chamber and removed the wafer. They saw a tiny black spot at the focal point of the laser beam. A burn, perhaps. That Mazur knew that silicon does not get black," he says. So what was going on? He tried it, so there



Funding:

Army Research Office

DARPA

Department of Energy

NDSEG

National Science Foundation

for more information and a copy of this presentation:

<http://mazur-www.harvard.edu>

Follow me!



eric_mazur

Google™

Google Search

I'm Feeling Lucky

Google™

mazur

Google Search

I'm Feeling Lucky

Google™

Google Search

I'm Feeling Lucky

Google™

Google Search

I'm Feeling Lucky

Funding:

Army Research Office

DARPA

Department of Energy

NDSEG

National Science Foundation

for more information and a copy of this presentation:

<http://mazur-www.harvard.edu>

Follow me!



eric_mazur